JAEGER ELEKTRONIK

SEMICON 1997

Original	Fabric.	Constr.	Info	Compl.	Fig.	JAEGER	Fig.	International
BUK 427-600A,B	Phi	MOS-N-FET-e	VFET, 600/30V, 45W, 80/275ns(2,8A) A: 4,3/17A, <1Ω(6,5A), B: 3,9/16A, <1,2Ω(6,5A)		16c	SOT-199		BUK 727-600, 2SK1463, 2SK1684, 2SK1859
BUK 428-500A,B	Phi	MOS-N-FET-e	VFET, 500/30V, 45W, 120/410ns(2,9A) A: 6,8/27A, <0,4Ω(8A), B: 6,1/24A, <0,5Ω(8A)		16c	SOT-199		2SK1206, 2SK1523, 2SK1696, 2SK1832
BUK 428-800A,B	Phi	MOS-N-FET-e	VFET, 800/30V, 45W, 160/450ns(2,6A) A: 3,4/14A, <1,5Ω(4A), B: 3/12A, <2Ω(4A)		16c	SOT-199		2SK809A, 2SK1463, 2SK1684, 2SK1859
BUK 428-1000A,B	Phi	MOS-N-FET-e	VFET, 1000/30V, 45W, 160/450ns(2,5A) A: 2,9/12A, <2Ω(3,5A), B: 2,6/10A, <2,6Ω(3,5A)		16c	SOT-199		BUK 426-1000, 2SK1770
BUK 436-50A,B	Phi	MOS-N-FET-e	=BUK 426-50A,B: A=50/200A, B=46/184A, 125W		18p	TO-3P		BUZ 346, 2SK1297, 2SK1379, 2SK1514
BUK 436-60A,B	Phi	MOS-N-FET-e	=BUK 426-60A,B: A=50/200A, B=46/184A, 125W		18p	TO-3P		2SK1297, 2SK1379, 2SK1514, 2SK2096
BUK 436-100A,B	Phi	MOS-N-FET-e	=BUK 426-100A,B: A=33/132A, B=31/124A, 125W		18p	TO-3P		BUZ 345, 2SK850, 2SK906, 2SK1429, ++

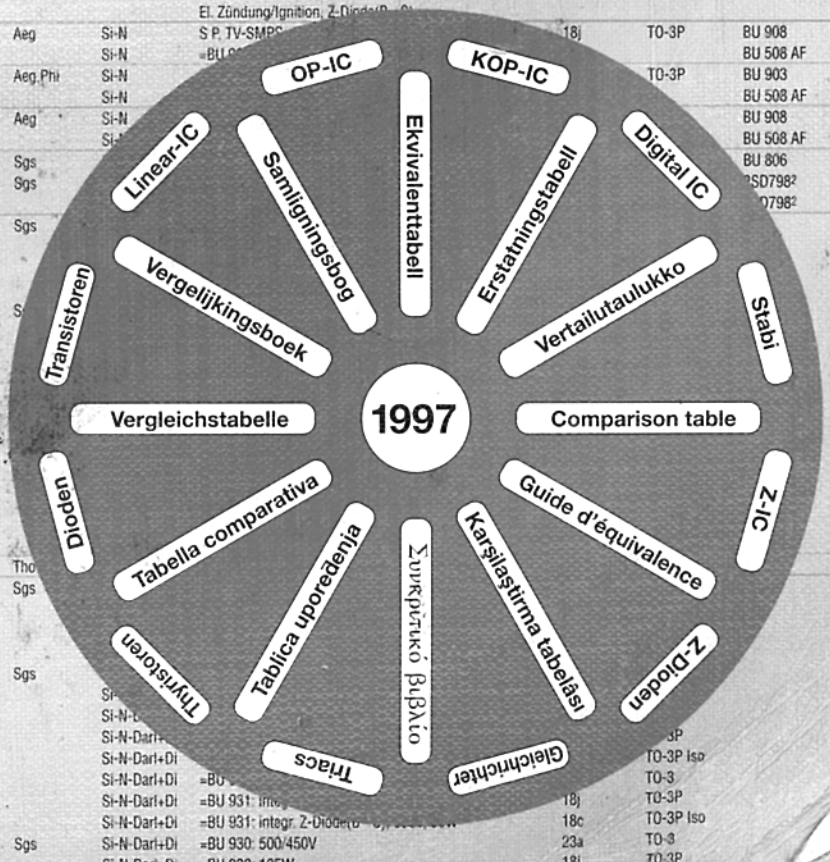
BUK 436-200
BUK 436-800
BUK 436-100
BUK 437-400
BUK 437-450
BUK 437-500
BUK 437-600
BUK 438-500
BUK 438-800
BUK 438-100
BUK 439-60A
BUK 441-60A
BUK 441-100
BUK 442-50A
BUK 442-60A
BUK 442-100
BUK 443-50A
BUK 443-60A
BUK 443-100
BUK 444-200
BUK 444-400
BUK 444-450
BUK 444-500
BUK 444-600
BUK 444-800
BUK 445-50A
BUK 445-60A
BUK 445-100
BUK 445-200
BUK 445-400
BUK 445-450
BUK 445-500
BUK 445-600
BUK 446-800
BUK 446-100
BUK 451-60A
BUK 451-100
BUK 452-50A
BUK 452-60A
BUK 452-100
BUK 45
BUK 45
BUK 45
BUK 45
BUK 454-200
BUK 454-400
BUK 454-450
BUK 454-500
BUK 454-600
BUK 454-800

Original	Fabric.	Constr.	Info	Compl.	Fig.	JAEGER	Fig.	International
KSV 3100 ACN-....	Sam	A/D-D/A-IC	8-Bit A/D- + 10-Bit D/A-Converter		40-DIP			-
KSV 3110(CN-....)	Sam	A/D-D/A-IC	8 Bit A/D- + 10 Bit D/A-Conv., Video, TTL In/Out		40-DIP			-
KSV 3208(CN)	Sam	A/D-IC	8 Bit, hi-speed, TV, Video, 20Msps, TTL In/Out		28-DIP			-
KSV 3310	Sam	D/A-IC	10 Bit, TV, Video, 20MHz		28-DIP			-
KSV 3404	Sam							
KSY 13	Sie							

KT

KT	
KT	
KT 208(A....V)	GUS
KT 209(A....V)	GUS
KT 814 A,B,G,V	GUS
KT 815 A,B,G,V	GUS
KT 816 A,B,G,V	GUS
KT 817 A,B,G,V	GUS
KT 818 A,B,G,V	GUS
KT 819 A,B,G,V	GUS
KT 3030	Sam
KT 3031	Sam
KT 3032	Sam
KT 3033	Sam
KT 3040 J	Sam
KT 3054 J	Sam
KT 3064 J	Sam
KT 3107(A....V)	GUS
KT 3170 J,N	Sam
KT 5116 J	Sam
KT 8518	Sam
KT 8520	Sam
KT 8521	Sam
KT 8554(J)	Sam
KT 8555(J)	Sam
KT 8557(J)	Sam
KT 8592(N)	Sam
KT 8593(N)	Sam
KTA 200	Kec
KTA 473	Kec
KTA 940	Kec
KTA 950	Kec
KTA 968(A)	Kec
KTA 1001	Kec
KTA 1015	Kec
KTA 1021	Kec
KTA 1023	Kec
KTA 1024	Kec
KTA 1070	Kec
KTA 1270	Kec
KTA 1271	Kec
KTA 1272	Kec
KTA 1273	Kec
KTA 1274	Kec
KTA 1275	Kec

Original	Fabric.	Constr.	Info	Compl.	Fig.	JAEGER	Fig.	Inter
BU 806	Phi,Sgs,Tfx	Si-N-Darl+Di	TV-HA, 400/200V, 8/15A, 60W, sat<1,5V(5A)		17j	TO-220	BU 806	17j
BU 806 AF		Si-N-Darl+Di	=BU 806: Iso		17c			
BU 806 FI	Tho	Si-N-Darl+Di	=BU 806: Iso, 30W		17c	TO-220Iso		
BU 807	Phi,Sgs,Tfx	Si-N-Darl+Di	=BU 806: 330/150V		17j	TO-220	BU 806	17j
BU 807 FI	Tho	Si-N-Darl+Di	=BU 807: Iso, 30W		17c	TO-220Iso		
BU 808 DFI [SGS]	Sgs	Si-N-Darl+Di	=BU 808FI: integr. Damper-Diode		18c	TO-3P Iso		
BU 808 FI [SGS]	Sgs	Si-N-Darl	CTV-HA, 1400/700V, 5/10A, 50W, hFE>25,sat<1,6V(5A)		18c	TO-3P Iso		
BU 808 [Philips]	Phi	Si-N	3Ph.-Motor Drv, 1500/700V, 12/20A, 160W,sat<1V(9V)		23a	TO-3		BUX 8
BU 810	Sgs	Si-N-Darl+Di	S P, 600/400V, 7/10A, 75W, <0,6/2µs, sat<3V(7A)		17j	TO-220	2SD798	17j
BU 824	Phi	Si-N-Darl+Di	S P, 650/375V, 0,5/1A, 12,5W, hFE>325, <1/2,5µs		13h	TO-202		
BU 826	Phi	Si-N-Darl+Di	S P, 800/375V, 6/8A, 125W, <1,3/2,2µs,sat<2,5V(4A)		18j	TO-3P	BU 826	18j
BU 826 A		Si-N-Darl+Di	=BU 826: 1000/400V		18j	TO-3P		
BU 900	Tho	Si-N-Darl	Tripleton, 650/400V, 8A, 70W, hFE>7000, sat<4V(3A) El. Zündung/Ignition, Z-Diode/D		17j	TO-220		
BU 902	Aeg	Si-N	S P, TV-SMPS		18j	TO-3P	BU 908	18j
BU 902 F		Si-N	=BU				BU 508 AF	16c
BU 903	Aeg,Phi	Si-N				TO-3P	BU 903	18j
BU 903 F		Si-N					BU 508 AF	16c
BU 908	Aeg	Si-N					BU 908	18j
BU 908 AF		Si-					BU 508 AF	16c
BU 910	Sgs						BU 806	17j
BU 911	Sgs						2SD798	17j
BU 912							2SD798	17j
BU 920	Sgs							
BU 920 P								
BU 920 PFI								
BU 920 T								
BU 921	S							
BU 921 P								
BU 921 PFI								
BU 921 T								
BU 921 ZP								
BU 921 ZPFI								
BU 921 ZT								
BU 921 ZTFI								
BU 922								
BU 922 P								
BU 922 PFI								
BU 922 T								
BU 926	Tho							18j
BU 930	Sgs							
BU 930 P								
BU 930 Z								
BU 930 ZP								
BU 931	Sgs	Si-						
BU 931 P		Si-						
BU 931 PFI		Si-N-Darl+Di						
BU 931 RPFI		Si-N-Darl+Di						
BU 931 Z		Si-N-Darl+Di	=BU					
BU 931 ZP		Si-N-Darl+Di	=BU 931: Inc					
BU 931 ZPFI		Si-N-Darl+Di	=BU 931: integr. Z-Diode/D					
BU 932	Sgs	Si-N-Darl+Di	=BU 930: 500/450V		23a	TO-3		
BU 932 P		Si-N-Darl+Di	=BU 932: 105W		18j	TO-3P		
BU 932 R		Si-N-Darl+Di	=BU 932: 175W			TO-3		



80.000 types

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
EX		Z-Di	=SM 6T 39A (SMD-Marking)		71a(6x4mm)	SOD-6			›SM 6T....
EX 0022 TA		Z-Di	11,5V		31a		Z-Diode 11V	31a	
EX 0048 CE		Z-Di	6,2V		31a		Z-Diode 6,2V	31a	
EX 0074 CE		Z-Di	115V		31a		Z-Diode 110V	31a	
EXB 919	Fjd	Hybrid-Z-IC	Z-IC, +100V, 0,2A						-
EY		Si-N	=2SC2882-Y (SMD-Marking)		39	SOT-89			›2SC2882
EY		Si-N	=2SC3265-Y (SMD-Marking)		35	SOT-23			›2SC3265
EY		Si-N	=2SC3398 (SMD-Marking)		35	SOT-23			›2SC3398
EY		Si-N	=2SC4398 (SMD-Marking)		35(2mm)	SOT-323			›2SC4398
EY		Si-N	=2SD2402-EY (SMD-Marking)		39	SOT-89			›2SD2402
EY		Si-N	=BCW 66RG (SMD-Marking)		35	SOT-23			›BCW 66RG
EY		Si-N	=KTC3265-Y (SMD-Marking)		35	SOT-23			›KTC 3265
EY		Si-N	=KTC4374-Y (SMD-Marking)		39	SOT-89			›KTC 4374
EYV-320(D)		Si-Di	=BA 127		31a		1N4148	31a	›BA 127
EZ		Si-N	=2SD2402-EZ (SMD-Marking)		39	SOT-89			›2SD2402
EZ		Si-N	=BCW 66RH (SMD-Marking)		35	SOT-23			›BCW 66RH
EZ-055....-372	Njr	Z-Di	5...37V, 0,4W		31a	DO-41	Z-Diode V	31a	BZX55/..., BZX83/..., ZPD..., 1N5231...58,++
F									
F		Si-N	=2SC4399 (SMD-Marking)		35(2mm)	SOT-323			›2SC3499
F 1		Si-N	=2SC1009-F1 (SMD-Marking)		35	SOT-23			›2SC1009
F 1(p)		Si-N	=BFS 18 (SMD-Marking)		35	SOT-23			›BFS 18
F 1 E23	Shi	MOS-N-FET-e	=2SK1195						
F 1 E50	Shi	MOS-N-FET-e	=2SK1672						
F 1 E90	Shi	MOS-N-FET-e	=2SK1533						
F10		Si-P	=KSA 1182-O (SMD-Marking)		35	SOT-23			›KSA 1182
F1Y		Si-P	=KSA 1182-Y (SMD-Marking)		35	SOT-23			›KSA 1182
F 2		Si-N	=2SC1009-F2 (SMD-Marking)		35	SOT-23			›2SC1009
F 2		Si-N	=2SC2814-F2 (SMD-Marking)		35	SOT-23			›2SC2814
F 2(p)		Si-N	=BFS 19 (SMD-Marking)		35	SOT-23			›BFS 19
F02		N-FET	=SO 4091 (SMD-Marking)		35	SOT-23			›SO 4091
F 3		Si-Di	=1SS193 (SMD-Marking)		35	SOT-23			›1SS193
F 3		Si-N	=2SC1009-F3 (SMD-Marking)		35	SOT-23			›2SC1009
F 3		Si-N	=2SC2814-F3 (SMD-Marking)		35	SOT-23			›2SC2814
F 3		Si-N	=BF 840 (SMD-Marking)		35	SOT-23			›BF 840
F03		N-FET	=SO 4391 (SMD-Marking)		35	SOT-23			›SO 4391
F 3 T		Si-Di	=1PS193 (SMD-Marking)		35	SOT-23			›1PS193
F 3 V50	Shi	MOS-N-FET-e	=2SK1244						
F 3 V90	Shi	MOS-N-FET-e	=2SK1534						
F 3 W90	Shi	MOS-N-FET-e	=2SK1536						
F 4		Si-N	=2SC1009-F4 (SMD-Marking)		35	SOT-23			›2SC1009
F 4		Si-N	=2SC2814-F4 (SMD-Marking)		35	SOT-23			›2SC2814
F 4		Si-N	=BFS 18R (SMD-Marking)		35	SOT-23			›BFS 18R
F 5		Si-Di	=1SS250 (SMD-Marking)		35	SOT-23			›1SS250
F 5		Si-Di	=1SS370 (SMD-Marking)		35(2mm)	SOT-323			›1SS370
F 5		Si-N	=2SC1009-F5 (SMD-Marking)		35	SOT-23			›2SC1009
F 5		Si-N	=2SC2814-F5 (SMD-Marking)		35	SOT-23			›2SC2814
F 5		Si-N	=BFS 19R (SMD-Marking)		35	SOT-23			›BFS 19R
F 05 E23	Shi	MOS-N-FET-e	=2SK1194						
F 5 V50	Shi	MOS-N-FET-e	=2SK1246						
F 5 W50	Shi	MOS-N-FET-e	=2SK1537						
F 6		Si-N	=2SC2223-F6 (SMD-Marking)		35	SOT-23			›2SC2223
F 6 V25	Shi	MOS-N-FET-e	=2SK1391						
F 7		Si-Di	=HSM 83 (SMD-Marking)		35	SOT-23			›HSM 83
F07		N-FET	=SO 4392 (SMD-Marking)		35	SOT-23			›SO 4392
F 7 W90	Shi	MOS-N-FET-e	=2SK1538						
F 8(p)		Si-P	=BF 824 (SMD-Marking)		35	SOT-23			›BF 824
F08		N-FET	=SO 4393 (SMD-Marking)		35	SOT-23			›SO 4393
F 9		Si-Di	=1SS321 (SMD-Marking)		35	SOT-23			›1SS321
F09		N-FET	=SO 3966 (SMD-Marking)		35	SOT-23			›SO 3966
F10		N-FET	=SO 4092 (SMD-Marking)		35	SOT-23			›SO 4092
F 10 V25	Shi	MOS-N-FET-e	=2SK1393						
F 10 W50	Shi	MOS-N-FET-e	=2SK1248						
F 10 W90	Shi	MOS-N-FET-e	=2SK1539						
F 11		N-FET	=SO 4093 (SMD-Marking)		35	SOT-23			›SO 4093
F 12		Si-N	=2SC2223-F12(SMD-Marking)		35	SOT-23			›2SC2223
F 12		Si-N	=2SC4178-F12 (SMD-Marking)		35(2mm)	SOT-323			›2SC4178
F 12		N-FET	=SO 245B (SMD-Marking)		35	SOT-23			›SO 245
F 13		Si-N	=2SC2223-F13(SMD-Marking)		35	SOT-23			›2SC2223
F 13		Si-N	=2SC4178-F13 (SMD-Marking)		35(2mm)	SOT-323			›2SC4178
F 13		N-FET	=BFR 30R (SMD-Marking)		35	SOT-23			›BFR 30R
F 14		N-FET	=BFR 31R (SMD-Marking)		35	SOT-23			›BFR 31R
F 14		Si-N	=2SC2223-F14(SMD-Marking)		35	SOT-23			›2SC2223
F 14		Si-N	=2SC4178-F14 (SMD-Marking)		35(2mm)	SOT-323			›2SC4178
F 14 A....J	Nec	Si-Di	Rr, Uni, 100...1000V, 1A, Uf<1V(1A), A=100, B=200V, C=300, D=400, E=500, F=600, H=800, J=1000V		31a	SOD-57	1N4007	31a	BY 126...127, BY 133...135, 1N4002...07, ++
F15		N-FET	=SO 5432 (SMD-Marking)		35	SOT-23			›SO 5432
F 15 W50	Shi	MOS-N-FET-e	=2SK1249						
F16		N-FET	=SO 5432R (SMD-Marking)		35	SOT-23			›SO 5432R
F17		N-FET	=SO 5433 (SMD-Marking)		35	SOT-23			›SO 5433
F18		N-FET	=SO 5433R (SMD-Marking)		35	SOT-23			›SO 5433R
F19		N-FET	=SO 5434 (SMD-Marking)		35	SOT-23			›SO 5433R
F20		N-FET	=SO 245BR (SMD-Marking)		35	SOT-23			›SO 245
F 20 W25	Shi	MOS-N-FET-e	=2SK1395						
F 20 W50	Shi	MOS-N-FET-e	=2SK1250						
F21		N-FET	=SO 245A (SMD-Marking)		35	SOT-23			›SO 245
F22		N-FET	=SO 4091R (SMD-Marking)		35	SOT-23			›SO 4091R
F23		N-FET	=SO 4391R (SMD-Marking)		35	SOT-23			›SO 4391R
F24		N-FET	=SO 245AR (SMD-Marking)		35	SOT-23			›SO 245AR
F25		N-FET	=SO 245C (SMD-Marking)		35	SOT-23			›SO 245C
F26		N-FET	=SO 245CR (SMD-Marking)		35	SOT-23			›SO 245CR
F27		N-FET	=SO 4392R (SMD-Marking)		35	SOT-23			›SO 4392R
F28		N-FET	=SO 4393R (SMD-Marking)		35	SOT-23			›SO 4393R

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
F29		N-FET	=SO 3966R (SMD-Marking)		35	SOT-23			›SO 3966R
F 30 S54(DC)	Fch	CMOS-IC	Telecom, µ-Law CODEC, Filter		16-DIC				-
F 30 S57(DC)	Fch	CMOS-IC	Telecom, A-Law CODEC, Filter		16-DIC				-
F 30 S64(DC)	Fch	CMOS-IC	Telecom, µ-Law CODEC, Filter		20-DIC				-
F 30 S67(DC)	Fch	CMOS-IC	Telecom, A-Law CODEC, Filter		20-DIC				-
F30		N-FET	=SO 4092R (SMD-Marking)		35	SOT-23			›SO 4092R
F 30 W25	Shi	MOS-N-FET-e	=2SK1396						
F 31		Si-N	=BF 841 (SMD-Marking)		35	SOT-23			›BF 841
F31		N-FET	=SO 4093R (SMD-Marking)		35	SOT-23			›SO 4093R
F32		N-FET	=SO 5434R (SMD-Marking)		35	SOT-23			›SO 5434R
F 40 W25	Shi	MOS-N-FET-e	=2SK1397						
F 099		Si-Di	≈BA 159		31a		BA 159	31a	›BA 159
F 100…117-L	Fer	µP-IC,MOS-IC	16-Bit µP System & Peripherie						
F 114 B….F	Nec	Si-Di	FRr, 200…600V, 0,8A, Uf<1,1V(0,8A), <200ns		31a	SOD-57	BYD 33 M	31a	BY 201/…, BYV 13…16, RGP 10D…M, ++
F 133		Si-Di	≈BY 133		31a		BY 133	31a	›BY 133
F 420		Si-N	≈BF 393		7c	TO-92	BF 420 A	7c	›BF 393
F 0810 BH	Tag	50Hz-Thy	200V, 5,1A(Tc=85°C), 8A≈, Igt/Ih<25/=75mA		17e	TO-220			TIC 116…, BStC10…M, CS6-…, TAG 660…
F 0810 DH		50Hz-Thy	=F 0810BH: 400V		17e	TO-220			TIC 116…, BStC10…M, CS6-…, TAG 660…
F 0810 MH		50Hz-Thy	=F 0810BH: 600V		17e	TO-220			TIC 116…, BStC10…M, CS6-…, TAG 660…
F 0810 NH		50Hz-Thy	=F 0810BH: 800V		17e	TO-220			TIC 116…, BStC10…M, CS6-…, TAG 660…
F 1612 BH	Tag	50Hz-Thy	200V, 10A(Tc=85°C), 16A≈, Igt/Ih=25/100mA		17e	TO-220			T 9,5N…, CS15-…, BStD10…M
F 1612 DH	Tag	50Hz-Thy	=F 1612BH: 400V		17e	TO-220			T 9,5N…, CS15-…, BStD10…M
F 1612 MH		50Hz-Thy	=F 1612BH: 600V		17e	TO-220			T 9,5N…, CS15-…, BStD10…M
F 1612 NH		50Hz-Thy	=F 1612BH: 800V		17e	TO-220			T 9,5N…, CS15-…, BStD10…M
F 2212 DC,PC	Fch	LIN-IC	Telecom, Full Duplex Modem, 2400/1200/600/300 Bps		28-DIC,DIP				-
F 2212 QC		LIN-IC	=F 2212DC,PC: SMD		28-MDIP				-
F 2224 DC,PC	Fch	LIN-IC	Telecom, Full Duplex Modem, 2400/1200/600/300 Bps		28-DIC,DIP				-
F 2224 QC		LIN-IC	=F 2224DC,PC: SMD		28-MDIP				-
F 3054(DC)	Fch	CMOS-IC	Telecom, µ-Law CODEC, Filter		16-DIC				-
F 3057(DC)	Fch	CMOS-IC	Telecom, A-Law CODEC, Filter		16-DIC				-
F 9010….9022		Si-N/P	›CS 9010…9022		7	TO-92	›CS 9010…22		
F 40098 BPC	Fch	CMOS-Logic	6x invert. Treiber/Driver, Tri-State		16-DIP				U 40098, V 40098BPC
FA		MOS-P/N-FETe	=µPA505T (SMD-Marking)		45	SOT-153			›µPA505T
FA		Si-N	=2SC2619-A (SMD-Marking)		35	SOT-23			›2SC2619
FA		Si-N	=BFP 81 (SMD-Marking)		44	SOT-143			›BFP 81
FA		Si-N	=BFQ 17 (SMD-Marking)		39	SOT-89			›BFQ 17
FA		Si-N	=BSV 65A (SMD-Marking)		35	SOT-23			›BSV 65A
FA		Si-P	=HQ 2A4A (SMD-Marking)		39	SOT-89			›HQ 2…
FA 1 A3Q	Nec	Si-N+R	=AA 1A3Q: SMD	{FN1A3Q	35a	SOT-23			DTC 113ZK, UN 2219
FA 1 A4M	Nec	Si-N+R	=AA 1A4M: SMD	{FN1A4M	35a	SOT-23			DTC 113EK, RN 1402, UN 2211, 2SC3398,++
FA 1 A4P	Nec	Si-N+R	=AA 1A4P: SMD	{FN1A4P	35a	SOT-23			DTC 114YK, RN 1407, UN 2214, 2SC4047,++
FA 1 A4Z	Nec	Si-N+R	=AA 1A4Z: SMD	{FN1A4P	35a	SOT-23			DTC 114TK, RN 1411, UN 2215, 2SC3859,++
FA 1 F4M	Nec	Si-N+R	=AA 1F4M: SMD	{FN1F4M	35a	SOT-23			DTC 124EK, RN 1403, UN 2212, 2SC3396,++
FA 1 F4N	Nec	Si-N+R	=AA 1F4N: SMD	{FN1F4N	35a	SOT-23			BCR 142, DTC 124XK, KSR 1107, RN 1408
FA 1 F4Z	Nec	Si-N+R	=AA 1F4Z: SMD	{FN1F4Z	35a	SOT-23			DTC 124TK, KSR 1111, UN 2217, 2SC4120
FA 1 L3M	Nec	Si-N+R	=AA 1L3M: SMD	{FN1L3M	35a	SOT-23			DTC 143EK, RN 1401, UN 221L, 2SC4362,++
FA 1 L3N	Nec	Si-N+R	=AA 1L3N: SMD	{FN1L3N	35a	SOT-23			DTC 143XK, KSR 1105, UN 221F, 2SC4360
FA 1 L3Z	Nec	Si-N+R	=AA 1L3Z: SMD	{FN1L3Z	35a	SOT-23			DTC 143TK, RN 1410, UN 2216, 2SC3900,++
FA 1 L4L	Nec	Si-N+R	=AA 1L4L: SMD	{FN1L4L	35a	SOT-23			DTC 144WK, RN 1409, UN 221E, 2SC3397,++
FA 1 L4M	Nec	Si-N+R	=AA 1L4M: SMD	{FN1L4M	35a	SOT-23			DTC 144EK, RN 1404, UN 2213, 2SC3395,++
FA 1 L4Z	Nec	Si-N+R	=AA 1L4Z: SMD	{FN1L4Z	35a	SOT-23			DTC 144TK, KSR 1112, UN 2210, 2SC3898
FA 3		Si-N	=2SC4179-FA3 (SMD-Marking)		35(2mm)	SOT-323			›2SC4179
FA 3 L4Z	Nec	Si-N+R	=BA 3L4Z: SMD	{FN3L4Z	35a	SOT-23			-
FA 4		Si-N	=2SC4179-FA4 (SMD-Marking)		35(2mm)	SOT-323			›2SC4179
FA 8025	Hit	Hybrid-Z-IC	Z-IC, +14,2…14,8V, 3,5A						-
FB		Si-N	=2SC2619-B (SMD-Marking)		35	SOT-23			›2SC2619
FB		Si-N	=2SC3053-B (SMD-Marking)		35	SOT-23			›2SC3053
FB		Si-N	=2SC4258-B (SMD-Marking)		35(2mm)	SOT-323			›2SC4258
FB		Si-N	=2SC5016 (SMD-Marking)		≈35	(T Mini)			›2SC5016
FB		Si-N	=BFP 17 (SMD-Marking)		44	SOT-143			›BFP 17
FB		Si-N	=BFQ 19 (SMD-Marking)		39	SOT-89			›BFQ 19
FB		Si-N	=BSV 65B (SMD-Marking)		35	SOT-23			›BSV 65B
FB 1 A3M…L3N	Nec	Si-N+R	=AB 1A3M…L3N: SMD	{FP1…	35a	SOT-23			-
FB 2060A,B	Fch	Si-N	=2N2060A,B:		TO-71	(EBC-EBC-)			›2N2060A,B
FB 3423	Fch	Si-N	=2N3423:		TO-71	(EBC-EBC-)			›2N3423
FB 3424	Fch	Si-N	=2N3424:		TO-71	(EBC-EBC-)			›2N3424
FB 3726	Fch	Si-P	=2N3726:		TO-71	(EBC-EBC-)			›2N3726
FB 3727	Fch	Si-P	=2N3727:		TO-71	(EBC-EBC-)			›2N3727
FB 3728	Fch	Si-N	=2N3728:		TO-71	(EBC-EBC-)			›2N3728
FB 3729	Fch	Si-N	=2N3729:		TO-71	(EBC-EBC-)			›2N3729
FB 4015	Fch	Si-P	=2N4015:		TO-71	(EBC-EBC-)			›2N4015
FB 4016	Fch	Si-P	=2N4016:		TO-71	(EBC-EBC-)			›2N4016
FBC 737		Si-N	≈BC 737				BC 337	7a	›BC 737
FBC 738		Si-N	≈BC 738				BC 337	7a	›BC 738
FC		Si-N	=2SC2619-C (SMD-Marking)		35	SOT-23			›2SC2619
FC		Si-N	=2SC3053-C (SMD-Marking)		35	SOT-23			›2SC3053
FC		Si-N	=2SC3438-C (SMD-Marking)		39	SOT-89			›2SC3438
FC		Si-N	=2SC4258-C (SMD-Marking)		35(2mm)	SOT-323			›2SC4258
FC		Si-N	=BFP 29 (SMD-Marking)		44	SOT-143			›BFP 29
FC		Si-N	=BFQ 64(SMD-Marking)		39	SOT-89			›BFQ 64
FC 11	Say	N-FET	SMD, Dual, =2x 2SK772, ΔUgs<30mV		45	SOT-153			-
FC 101	Say	Si-P	SMD, Dual, =2x 2SA1622		46	SOT-163			-
FC 102	Say	Si-N	SMD, Dual, =2x 2SC4211		46	SOT-163			-
FC 103	Say	Si-P	SMD, Dual, =2x 2SA1622		45	SOT-153			-
FC 104	Say	Si-N	SMD, Dual, =2x 2SC4211		45	SOT-153			-
FC 105	Say	Si-P	SMD, Dual, =2x 2SA1341		46	SOT-163			-
FC 106	Say	Si-N	SMD, Dual, =2x 2SC3395		46	SOT-163			-
FC 107	Say	Si-P	SMD, Dual, =2x 2SA1341		45	SOT-153			-
FC 108	Say	Si-N	SMD, Dual, =2x 2SC3395		45	SOT-153			-
FC 109	Say	Si-P	SMD, Dual, =2x 2SA1342		46	SOT-163			-
FC 110	Say	Si-N	SMD, Dual, =2x 2SC3396		46	SOT-163			-

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
FC 111	Say	Si-P	SMD, Dual, =2x 2SA1342		45	SOT-153			-
FC 112	Say	Si-N	SMD, Dual, =2x 2SC3396		45	SOT-153			-
FC 113	Say	Si-P	SMD, Dual, =2x 2SA1344		46	SOT-163			-
FC 114	Say	Si-N	SMD, Dual, =2x 2SC3398		46	SOT-163			-
FC 115	Say	Si-P	SMD, Dual, =2x 2SA1344		45	SOT-153			-
FC 116	Say	Si-N	SMD, Dual, =2x 2SC3398		45	SOT-153			-
FC 117	Say	Si-P	SMD, Dual, =2x 2SA1745		46	SOT-163			-
FC 118	Say	Si-N	SMD, Dual, =2x 2SC4555		46	SOT-163			-
FC 119	Say	Si-N	SMD, Dual, =2x 2SC2814		46	SOT-163			-
FC 120	Say	Si-N	SMD, Dual, =2x 2SC3142		46	SOT-163			-
FC 121	Say	Si-P	SMD, Dual, =2x 2SA1502		45	SOT-153			-
FCB 61 C65(L,LL)P	Phi	CMOS-sRAM-IC	8k x 8Bit, 55ns, 0…70°		28-DIP				-
FCB 61 C65(L,LL)T	Phi	CMOS-sRAM-IC	=FCB 61….P: SMD		28-MDIP				-
FCF 61 C65(L,LL)T	Phi	CMOS-sRAM-IC	=FCB 61…: SMD, -40…+85°		28-MDIP				-
FCM 7010		MOS-IC	Digital-Uhr/Digital Clock		40-DIL				-
FCS 6208….6209		Si-N/P	›CS 6208…6209		7	TO-92	›CS 6208…09		
FCS 9010….9022		Si-N/P	›CS 9010…9022		7	TO-92	›CS 9010…22		
FD		Si-N	=2SC3053-D (SMD-Marking)		35	SOT-23			›2SC3053
FD		Si-N	=2SC3438-D (SMD-Marking)		39	SOT-89			›2SC3438
FD		Si-N	=2SC4258-D (SMD-Marking)		35(2mm)	SOT-323			›2SC4258
FD		Si-P	=BCV 26 (SMD-Marking)		35	SOT-23			›BCV 26
FD		Si-N	=BFP 35A (SMD-Marking)		44	SOT-143			›BFP 35A
FD		Si-N	=BFQ 17P (SMD-Marking)		39	SOT-89			›BFQ 17P
FD 100	Fch	Si-Di	SS, 75V, Uf<1V(10mA), <4ns		31a	DO-7	1N4148	31a	BAW 62, BAW 76, BAX 95, 1N4148…49, ++
FD 111	Fch	Si-Di	SS, 75V, Uf<1V(10mA), <5ns		31a	DO-7	1N4148	31a	BAW 62, BAW 76, BAX 95, 1N4148…49, ++
FD 200	Fch	Si-Di	S, 200V, Uf<1V(0,1A), <50ns		31a	DO-7			BA 197…198, BAV 20…21, BAW 50
FD 222	Fch	Si-Di	S, 150V, Uf<1,05V(0,1A), <60ns		31a	DO-7			BA 196…198, BAV 16, BAV 20…21, BAW 50
FD 300	Fch	Si-Di	Uni, 150, Uf<1V(0,2A), Ir<1nA(125V)		31a	DO-7			BAS 45, FDH 300, FDH 333
FD 333	Fch	Si-Di	Uni, 150, Uf<1V(0,2A), Ir<3nA(125V)		31a	DO-7			BAS 45, FDH 300, FDH 333
FD 600	Fch	Si-Di	SS, 75V, Uf<1V(0,2A), <4ns		31a	DO-7			BAV 12, BAV 14, BAW 26…27, BAX 81
FD 700	Fch	Si-Di	SS, 20V, 0,05A, Uf=0,89…1,1V(0,05A), <0,7ns		31a	DO-7			FDH 700
FD 777	Fch	Si-Di	SS, 8V, 0,05A, Uf=0,89…1,35V(0,05A), <0,75ns		31a	DO-7			FDH 777
FD 6666	Fch	Si-Di	SS, 75V, Uf<1V(0,2A), <5ns		31a	DO-7			BAW 26…27, BAV 12, BAV 14, BAX 81
FDH 300	Fch, Nsc	Si-Di	Uni, 125V, 0,2A, Uf<1V(0,2A), Ir<1nA(125V)		31a	DO-35			BAS 45, BAY 135
FDH 333	Fch, Nsc	Si-Di	Uni, 125V, 0,2A, Uf<1,05V(0,2A), Ir<3nA(125V)		31a	DO-35			BAS 45, BAY 135
FDH 400	Fch, Nsc	Si-Di	Uni, S, 175V, 0,2A, Uf<1V(0,2A), <50ns		31a	DO-35	BA 159	31a	BA 197…198, BAV 20…21, BAW 50
FDH 444	Fch, Nsc	Si-Di	Uni, S, 125V, 0,2A, Uf<1V(0,2A), <60ns		31a	DO-35	BA 159	31a	BA 196…198, BAV 15…16, BAV 19…21
FDH 600	Fch, Nsc	Si-Di	SS, 50V, 0,2A, Uf<0,92V(0,1A), <4ns		31a	DO-35	1N4148	31a	BAW 62, BAW 76, BAX 95, 1N4148…49, ++
FDH 666	Fch, Nsc	Si-Di	SS, 25V, 0,2A, Uf<1V(0,1A), <4ns		31a	DO-35	1N4148	31a	BAW 62, BAW 76, BAX 95, 1N4148…49, ++
FDH 700	Fch	Si-Di	SS, 20V, 0,05A, Uf<1,10V(0,05A), <0,7ns		31a	DO-7			FD 700
FDH 777	Fch	Si-Di	SS, 8V, 0,05A, Uf<1,35V(0,05A), <0,75ns		31a	DO-7			FD 777
FDH 900	Fch, Nsc	Si-Di	SS, 40V, 0,2A, Uf<1V(0,1A), <4ns		31a	DO-35	1N4148	31a	BAV 10, BAW 24…27, BAX 81, 1N4150, ++
FDH 999	Fch, Nsc	Si-Di	SS, 25V, 0,2A, Uf<1V(0,01A), <5ns		31a	DO-35	1N4148	31a	BAV 10, BAW 24…27, BAX 81, 1N4150, ++
FDH 1000	Fch, Nsc	Si-Di	S, 50V, 0,2A, Uf<1V(0,5A)		31a	DO-35			BAW 24…27, BAX 82, BAY 95, 1N4151
FDN 600	Fch	Si-Di	=FDH 600:		31a	DO-34			›FDH 600
FDN 666	Fch	Si-Di	=FDH 666:		31a	DO-34			›FDH 666
FDR 300	Fch	Si-Di	S, RadH, 250V, Uf<0,85V(0,1A), <325ns		31a	DO-7			-
FDR 600	Fch	Si-Di	SS, RadH, 75V, Uf<1V(0,2A), <4ns		31a	DO-7			-
FDR 700	Fch	Si-Di	SS, RadH, 30V, Uf<1,1V(0,05A), <0,7ns		31a	DO-7			-
FE		Si-N	=2SC3438-E (SMD-Marking)		39	SOT-89			›2SC3438
FE(p,s)		Si-P	=BCV 46 (SMD-Marking)		35	SOT-23			›BCV 46
FE		Si-N	=BFP 93A (SMD-Marking)		44	SOT-143			›BFP 93A
FE		Si-N	=BFQ 19P (SMD-Marking)		39	SOT-89			›BFQ 19P
FE 1 A….H	Gie	Si-Di	FRr, 50…400V, 1A, Uf<0,95V(1A), <30ns A=50,B=100,C=150,D=200,E=250,F=300,G=350, H=400V		31a	SOD-57	BYV 27/200	31a	BYV 26B…E, EGP 10A…G
FE 2 A….H	Gie	Si-Di	FRr, 50…400V, 2A, Uf<0,95V(2A), <35ns		31a	SOD-57	BYV 27/200	31a	BYD 47A…G, BYV 27/…, EGP 20A…G
FE 3 A….H	Gie	Si-Di	FRr, 50…400V, 3A, Uf<0,95V(3A), <35ns		31a	SOD-64	BYV 28/200	31a	BYV 28/…, EGP 30A…G
FE 5 A….D	Gie	Si-Di	FRr, 50…200V, 5A, Uf<0,95(5A), <35ns		31a	SOD-64			BYV 61…63, EGP 50A…G
FE 6 A….H	Gie	Si-Di	FRr, 50…400V, 6A, Uf<0,95V(6A), <35ns		31a	SOD-64			BYV 61…63
FE 8 A….J	Gie,Tho	Si-Di	P FRr, 50…600V, 8A(Tc=100°), Uf<0,95V(8A), <35ns A=50,B=100,C=150,D=200,F=300,G=400,H=500,J=600V		17k	TO-220			BYT 79/…, BYV 29/…, BYR 29/…, ++
FE 16 A….J	Gie,Tho	Si-Di	Dual, 50…600V(Tc=100°), 16A, Uf<0,95V(8A), <35ns		17e	TO-220			BYV 34/…
FE 16 AD….JD		Si-Di	=FE 16A….J:		17r	TO-220			FED 16AT…JT
FE 16 AN….JN		Si-Di	=FE 16A….J:		17h	TO-220			FEN 16AT…JT
FE 30 A….J	Gie,Tho	Si-Di	Dual,50…600V, 30A(Tc100°),Uf<0,95V(30A),<35…50ns		23f	TO-3			BYV 72/…, BYV 74/…, MUR 3005…3060PT
FE 30 AD….JD		Si-Di	=FE 30A…J:		23s	TO-3			-
FE 30 AN….JN		Si-Di	=FE 30A…J:		23n	TO-3			-
FE 0654A….C	Fch,Tsc	N-FET	HF/S25V, Idss=1…40mA, Up<8V		8b	TO-106			BF 244A…C, BF 245A…C, 2N5163
FE 0655A….C	Fch,Tsc	N-FET	Uni, 30V, Idss>3mA, Up<10V		8b	TO-106			BFS 74…79, BSV 78…80, 2N4856…4861
FE 1718A….E	Fch	Si-P	SMD, Dual, 40V, >400MHz		10-MDIP	TO-89			-
FE 2060A,B	Fch	Si-N	=2N2060A,B: SMD		10-MDIP	TO-89			-
FE 2223(A)	Fch	Si-N	=2N2223(A): SMD		10-MDIP	TO-89			-
FE 2913….2920(A)	Fch	Si-N	=2N2913…2920(A): SMD		10-MDIP	TO-89			-
FE 3423	Fch	Si-N	=2N3423: SMD		10-MDIP	TO-89			-
FE 3424	Fch	Si-N	=2N3424: SMD		10-MDIP	TO-89			-
FE 3726	Fch	Si-P	=2N3726: SMD		10-MDIP	TO-89			-
FE 3727	Fch	Si-P	=2N3727: SMD		10-MDIP	TO-89			-
FE 3728	Fch	Si-N	=2N3728: SMD		10-MDIP	TO-89			-
FE 3729	Fch	Si-N	=2N3729: SMD		10-MDIP	TO-89			-
FE 3819	Fch,Tsc	N-FET	=2N3819: 0,3W		8b	TO-106			›2N3819
FE 4015….4025	Fch	Si-P	=2N4015…4025: SMD		10-MDIP	TO-89			-
FE 4302….4304	Fch,Tsc	N-FET	=2N4302…4304: 0,3W		8b	TO-106			›2N4302…4303
FE 5245….5247	Fch,Tsc	N-FET	=2N5245…5247: 0,36W		8f	TO-106			›2N5245…5247
FE 5257….5259	Fch,Tsc	N-FET	=2N5257…5259: 0,31W		8b	TO-106			›2N5257…5259
FE 5284….5286	Fch,Tsc	N-FET	=2N5284…5286: 0,31W		8f	TO-106			›2N5284…5286
FED 16 AT….JT	Gie	Si-Di	=FEP 16AT….JT:		17r	TO-220			FE 16AD…JD
FED 30 AP….JP	Gie	Si-Di	=FEP 30AP….JP:		18r	TO-247			-
FEN 16 AT….JT	Gie	Si-Di	=FEP 16AT….JT:		17h	TO-220			FE 16AN…JN
FEN 30 AP….JP	Gie	Si-Di	=FEP 30AP….JP:		18h	TO-247			-
FEP 16 AT….JT	Gie	Si-Di	Dual, 50…600V, 16ATc=100°), Uf<0,95V(8A), <50ns A=50,B=100,C=150,D=200,F=300,G=400,H=500,J=600V		17e	TO-220			BYV 34/…, FE 16A…J

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
FEP 30 AT....JT	Gie	Si-Di	Dual, 50...600V, 30A(Tc=100°), Uf<0,95V(15A), <50ns		18e	TO-247			BYV 74/..., MUR 3005PT...3060PT
FER 8 AT....JT	Gie	Si-Di	=FES 8AT....JT:		17m	TO-220			-
FER 16 AT....JT	Gie	Si-Di	=FES 16AT....JT:		17m	TO-220			-
FES 8 AT....JT	Gie	Si-Di	P FRr, 50...600V, 8A(Tc=100°), Uf<0,95V(8A), <35ns A=50,B=100,C=150,D=200,F=300,G=400,H=500,J=600V		17k	TO-220			BYR 29/..., BYT 86/..., FE 8A...J
FES 16 AT....JT	Gie	Si-Di	FRr, 50...600V, 16A(Tc=100°), Uf< 0,98V(16A), <35ns		17k	TO-220			BYR 79/..., BYT 87/..., FE 16A...J
FF(p,s)		Si-N	=BCV 27 (SMD-Marking)		35	SOT-23			›BCV 27
FF		Si-N	=BFQ 18A (SMD-Marking)		39	SOT-89			›BFQ 18A
FG(p,s)		Si-N	=BCV 47 (SMD-Marking)		35	SOT-23			›BCV 47
FG		Si-N	=BFQ 149 (SMD-Marking)		39	SOT-89			›BFQ 149
FG		Si-N	=BFQ 19S (SMD-Marking)		39	SOT-89			›BFQ 19S
FG 1		Ge-P	=2SB33				AC 151	2a	›2SB33
FG 2 N	Fdj	Si-Di	TV Damper-Di, 300V, 1A, Uf<1,1V(2A)		31a	(6x9mmØ)	BYD 33 M	31a	BY 201/3, BYX 55/350, MR 813, RGP 10G,++
FH(s)		Si-N	=BFN 24 (SMD-Marking)		35	SOT-23			›BFN 24
FHP		Si-N	=2SC5020-P (SMD-Marking)		35(2mm)	SOT-323			›2SC5020
FHQ		Si-N	=2SC5020-Q (SMD-Marking)		35(2mm)	SOT-323			›2SC5020
FHR		Si-N	=2SC5020-R (SMD-Marking)		35(2mm)	SOT-323			›2SC5020
FI		MOS-N-FET-d	=3SK186 (SMD-Marking)		44	SOT-143			›3SK186
FI		MOS-N-FET-d	=3SK217 (SMD-Marking)		44	SOT-143			›3SK217
FJ		N-FET	=2SK1069 (SMD-Marking)		35(2mm)	SOT-323			›2SK1069
FJ(s)		Si-N	=BFN 26 (SMD-Marking)		35	SOT-23			›BFN 26
FJ 3		N-FET	=2SK771-3 (SMD-Marking)		35	SOT-23			›2SK771
FJ 4		N-FET	=2SK771-4 (SMD-Marking)		35	SOT-23			›2SK771
FJ 5		N-FET	=2SK771-5 (SMD-Marking)		35	SOT-23			›2SK771
FJ 2501		Si-P-Darl	=BDX 34A		17j	TO-220	BD 902	17j	›BDX 34(A...D)
FJ 3001		Si-N-Darl	=BDX 33A		17j	TO-220	BD 901	17j	›BDX 33(A...D)
FK		Si-P	=2SB800-FK (SMD-Marking)		39	SOT-89			›2SB800
FK(s)		Si-P	=BFN 25 (SMD-Marking)		35	SOT-23			›BFN 25
FKE 4 F2/....	Skr	Si-Di	›SKE 4F2/...		33a		SKE 4F2/10	33a	
FL		Si-P	=2SA1434 (SMD-Marking)		35	SOT-23			›2SA1434
FL		Si-P	=2SB800-FL (SMD-Marking)		39	SOT-89			›2SB800
FL(s)		Si-P	=BFN 27 (SMD-Marking)		35	SOT-23			›BFN 27
FLV....		Opto							
FM		Si-P	=2SB800-FM (SMD-Marking)		39	SOT-89			›2SB800
FM		Si-Di	=BB 804 (SMD-Marking)		35	SOT-23			›BB 804
FMA 1	Rhm	Si-P+R	SMD, Dual, Rb=Rbe=22kΩ, 50V, 30mA		45	SOT-153			-
FMA 2	Rhm	Si-P+R	SMD, Dual, Rb=Rbe=47kΩ, 50V, 30mA		45	SOT-153			-
FMA 3	Rhm	Si-P+R	SMD, Dual, Rb=4,7kΩ, Rbe=-, 50/50V, 100mA		45	SOT-153			-
FMA 4	Rhm	Si-P+R	SMD, Dual, Rb=10kΩ, Rbe=-, 50/50V, 100mA		45	SOT-153			-
FMA 5	Rhm	Si-P+R	SMD, Dual, Rb=2,2k, Rbe=47kΩ, 50V, 100mA		45	SOT-153			-
FMA 6	Rhm	Si-P+R	SMD, Dual, Rb=47kΩ, Rbe=-, 50/50V, 100mA		45	SOT-153			-
FMC 1	Rhm	Si-N/P	SMD, NPN+PNP, Rb=4,7kΩ, Rbe=-, 50/50V, 100mA		45	SOT-153			-
FMC 2	Rhm	Si-N/P	SMD, NPN+PNP, Rb=Rbe=22kΩ, 50V, 100mA		45	SOT-153			-
FMC 3	Rhm	Si-N/P	SMD, NPN+PNP, Rb=Rbe=10kΩ, 50V, 50mA		45	SOT-153			-
FMG 1	Rhm	Si-N+R	SMD, Dual, Rb=Rbe=22kΩ, 50V, 30mA		45	SOT-153			-
FMG 2	Rhm	Si-N+R	SMD, Dual, Rb=Rbe=22kΩ, 50V, 30mA		45	SOT-153			-
FMG 3	Rhm	Si-N+R	SMD, Dual, Rb=4,7kΩ, Rbe=-, 50/50V, 100mA		45	SOT-153			-
FMG 4	Rhm	Si-N+R	SMD, Dual, Rb=10kΩ, Rbe=-, 50/50V, 100mA		45	SOT-153			-
FMG 5	Rhm	Si-N+R	SMD, Dual, Rb=10k, Rbe=47kΩ, 50V, 100mA		45	SOT-153			-
FMG 6	Rhm	Si-N+R	SMD, Dual, Rb=47kΩ, Rbe=-, 50/50V, 100mA		45	SOT-153			-
FMG 7	Rhm	Si-N+R	SMD, Dual, Rb=10kΩ, Rbe=-, 50/50V, 100mA		45	SOT-153			-
FMG 8	Rhm	Si-N+R	SMD, Dual, Rb=4,7k, Rbe=47kΩ, 50V, 100mA		45	SOT-153			-
FMMT 918	Fer	Si-N	=2N918: SMD		35a	SOT-23			BF 517, BFS 17, 2SC3016, 2SC3061, ++
FMMT 2222(A)	Fer	Si-N	=2N2222(A): SMD		35a	SOT-23			BSR14, BSS79, PMBT2222(A), SMBT2222(A)
FMMT 2222(A)R	Fer	Si-N	=2N2222(A): SMD		35d	SOT-23			-
FMMT 2369(A)	Fer	Si-N	=2N2369(A): SMD		35a	SOT-23			2SC4168, PMBT 2369(A)
FMMT 2484	Fer	Si-N	=2N2484: SMD		35a	SOT-23	BC 850	35a	BC 850, 2SC3323
FMMT 2907(A)	Fer	Si-P	=2N2907(A): SMD		35a	SOT-23			BSR15...16,BSS80,PMBT2907(A),SMBT2907(A)
FMMT 2907(A)R	Fer	Si-P	=2N2907(A): SMD		35d	SOT-23			-
FMMT 3903...3904	Fer	Si-N	=2N3903...3904: SMD		35a	SOT-23	BC 846	35a	BC846, BCV71...72, PMBT3903..., SMBT3904
FMMT 3905...3906	Fer	Si-P	=2N3905...3906: SMD		35a	SOT-23	BC 856	35a	BC856...857, BCX71, PMBT3905..., SMBT3906
FMMT 4124	Fer	Si-N	=2N4124: SMD		35a	SOT-23	BC 846	35a	BC 846...848, BSR 17, SMBT 4124, 2SC3392
FMMT 4125	Fer	Si-P	=2N4125: SMD		35a	SOT-23	BC 856	35a	BC 856...858, BSR 18, SMBT 2126, 2SA1607
FMMT 5087	Fer	Si-P	=2N5087: SMD		35a	SOT-23	BC 860	35a	BC 860, BCF 70, SMBT 5087, 2SA1311
FMMT 5087 R	Fer	Si-P	=2N5087: SMD		35a	SOT-23			-
FMMT-A05...06	Fer	Si-N	=MPS-A05...06: SMD		35a	SOT-23			BCW 65...66, PMBT-A05...06, SMBTA 05...06++
FMMT-A12...14	Fer	Si-N-Darl	=MPS-A12...14: SMD		35a	SOT-23			BCV 27, PMBT-A12...14, SMBTA 13...14++
FMMT-A20	Fer	Si-N	=MPS-A20: SMD		35a	SOT-23	BC 846	35a	BC 846...847, BCW 71...72, SMBTA 20, ++
FMMT-A42...43	Fer	Si-N	=MPS-A42...43: SMD		35a	SOT-23			PMBT-A42...43, SMBTA 42...43
FMMT-A42R...43R	Fer	Si-N	=MPS-A42...43: SMD		35d	SOT-23			-
FMMT-A55...56	Fer	Si-P	=MPS-A55...56: SMD		35a	SOT-23			BCW 68, BCX 42, PMBT-A55..., SMBTA 55...++
FMMT-A70	Fer	Si-P	=MPS-A50: SMD		35a	SOT-23	BC 856	35a	BC 856...857, BCW 69...70, 2SA1311, ++
FMMT-A92...93	Fer	Si-P	=MPS-A92...93: SMD		35a	SOT-23			PMBT-A92...93, SMBTA 92...93
FMMT-A92R...93R	Fer	Si-P	=MPS-A92...93: SMD		35d	SOT-23			-
FMP 18 N05	Fch	MOS-N-FET-e	VFET, 50/30V, 18/50A, 75W, on<0,1Ω(10A)		17p	TO-220			BUZ 21...22, IRF 540...43, 2SK674, 2SK1417
FMP 20 N05	Fch	MOS-N-FET-e	VFET, 50/30V, 20/60A, 75W, <85mΩ(10A), <140/135ns		17p	TO-220			BUZ 21...22, IRF 540...43, 2SK674, 2SK1417
FMP 30 N05	Fch	MOS-N-FET-e	VFET, 50/30V, 30A, 100W, on=0,05Ω		17p	TO-220			BUK 555/50, BUZ 11...12, PRFZ 42, 2SK856+
FMP 35 N05	Fch	MOS-N-FET-e	VFET, 50/30V, 35A, 100W, on=0,04Ω		17p	TO-220			BUK 555/50, BUZ 11...12, PRFZ 42, 2SK856+
FMPS-A 05	Fch	Si-N	=MPS-A05		7e	TO-92	›MPS-A05		›MPS-A05
FMPS-A 06	Fch	Si-N	=MPS-A06		7e	TO-92	›MPS-A06		›MPS-A06
FMPS-A 55	Fch	Si-P	=MPS-A55		7e	TO-92	›MPS-A55		›MPS-A55
FMPS-A 56	Fch	Si-P	=MPS-A56		7e	TO-92	›MPS-A56		›MPS-A56
FMS 1	Rhm	Si-P	SMD, Dual, Uni, 50/40V, 100mA		45	SOT-153			-
FMS 2	Rhm	Si-P	SMD, Dual, Uni, 50/40V, 100mA		45	SOT-153			-
FMS 3	Rhm	Si-P	SMD, Dual, Uni, 120/120V, 50mA		45	SOT-153			-
FMS 4	Rhm	Si-P	SMD, Dual, Uni, 120/120V, 50mA		45	SOT-153			-
FMW 1	Rhm	Si-N	SMD, Dual, Uni, 50/40V, 100mA		45	SOT-153			-
FMW 2	Rhm	Si-N	SMD, Dual, Uni, 50/40V, 100mA		45	SOT-153			-
FMW 3	Rhm	Si-N	SMD, Dual, Uni, 120/120V, 50mA		45	SOT-153			-
FMW 4	Rhm	Si-N	SMD, Dual, Uni, 120/120V, 50mA		45	SOT-153			-
FMW 5	Rhm	Si-N	SMD, Dual, Uni, 50/40V, 100mA		45	SOT-153			-
FMW 6	Rhm	Si-N	SMD, Dual, HF, 30/18V, 50mA, >600MHz		45	SOT-153			-

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
FMW 7	Rhm	Si-N	SMD, Dual, HF, 20/11V, 50mA, >1400MHz		45	SOT-153			-
FMW 8	Rhm	Si-N	SMD, Dual, HF, 20/11V, 50mA, >1400MHz		45	SOT-153			-
FMW 9	Rhm	Si-N	SMD, Dual, HF, 20/11V, 50mA, >1400MHz		45	SOT-153			-
FMW 10	Rhm	Si-N	SMD, Dual, HF, 30/18V, 50mA, >600MHz		45	SOT-153			-
FMY 1	Rhm	Si-P/N	SMD, PNP+NPN, 50/40V, 100mA, 140MHz		45	SOT-153			-
FMY 3	Rhm	Si-P/N	SMD, PNP+NPN, 50/40V, 100mA, 140MHz		45	SOT-153			-
FMY 4	Rhm	Si-P/N	SMD, PNP+NPN, 50/40V, 100mA, 140MHz		45	SOT-153			-
FMY 5	Rhm	Si-P/N	SMD, PNP+NPN, 120/120V, 50mA, 140MHz		45	SOT-153			-
FN....FS									
FN 1 A3Q	Nec	Si-P+R	=AN 1A3Q: SMD	{FA1A3Q	35a	SOT-23			DTA 113ZK, UN 2119
FN 1 A4M	Nec	Si-P+R	=AN 1A4M: SMD	{FA1A4M	35a	SOT-23			DTA 114EK, RN 2402, UN 2111, 2SA1344,++
FN 1 A4P	Nec	Si-P+R	=AN 1A4P: SMD	{FA1A4P	35a	SOT-23			DTA 114YK, RN 2407, UN 2114, 2SA1563,++
FN 1 A4Z	Nec	Si-P+R	=AN 1A4Z: SMD	{FA1A4Z	35a	SOT-23			DTA 114TK, RN 2411, UN 2115, 2SA1496,++
FN 1 F4M	Nec	Si-P+R	=AN 1F4M: SMD	{FA1F4M	35a	SOT-23			DTA 124EK, RN 2403, UN 2112, 2SA1342,++
FN 1 F4N	Nec	Si-P+R	=AN 1F4N: SMD	{FA1F4N	35a	SOT-23			BCR 192, DTA 124XK, KSR 2107, RN 2408
FN 1 F4Z	Nec	Si-P+R	=AN 1F4Z: SMD	{FA1F4Z	35a	SOT-23			DTA 124TK, KSR 2111, UN 2117, 2SA1589
FN 1 L3M	Nec	Si-P+R	=AN 1L3M: SMD	{FA1L3M	35a	SOT-23			DTA 143EK, RN 2401, UN 211L, 2SA1655,++
FN 1 L3N	Nec	Si-P+R	=AN 1L3N: SMD	{FA1L3N	35a	SOT-23			DTA 143XK, KSR 2105, UN 211F, 2SA1653
FN 1 L3Z	Nec	Si-P+R	=AN 1L3Z: SMD	{FA1L3Z	35a	SOT-23			DTA 143TK, RN 2410, UN 2116, 2SA1510,++
FN 1 L4L	Nec	Si-P+R	=AN 1L4L: SMD	{FA1L4L	35a	SOT-23			DTA 144WK, RN 2409, UN 211E, 2SA1343,++
FN 1 L4M	Nec	Si-P+R	=AN 1L4M: SMD	{FA1L4M	35a	SOT-23			DTA 144EK, RN 2404, UN 2113, 2SA1341,++
FN 1 L4Z	Nec	Si-P+R	=AN 1L4Z: SMD	{FA1L4Z	35a	SOT-23			DTA 144TK, KSR 2112, UN 2110, 2SA1508
FND 500		Opto							
FO		Si-P	=2SA1202-O (SMD-Marking)		39	SOT-89			›2SA1202
FO		Si-N	=2SC2716-O (SMD-Marking)		35	SOT-23			›2SC2716
FO		Si-P	=KTA1662-O (SMD-Marking)		39	SOT-89			›KTA 1662
FO		Si-N	=KTC3878-O (SMD-Marking)		35	SOT-23			›KTC 3878
FOI		N-FET	=SO 4416 (SMD-Marking)		35	SOT-23			›SO 4416
FP		Z-Di	=SM 6T 68 (SMD-Marking)		71a(6x4mm)	SOD-6			›SM 6T....
FP 1 A3M...L3N	Nec	Si-P+R	=AP 1A3M...L3N: SMD	{FB1...	35a	SOT-23			-
FP 3 V50	Shi	MOS-N-FET-e	=2SK1245						
FP 3 V90	Shi	MOS-N-FET-e	=2SK1535						
FP 5 V50	Shi	MOS-N-FET-e	=2SK1247						
FP 08 C	Hit	Triac	200V, 30A=(Tc=90°C), Igt/Ih=50/30mA		21b	TO-48			T 6417..., T 6410..., 2N5444...5446
FP 08 D		Triac	=FP 08C: 300V		21b	TO-48			T 6417..., T 6410..., 2N5445...5446
FP 08 E		Triac	=FP 08C: 400V		21b	TO-48			T 6417..., T 6410..., 2N5445...5446
FP 08 F		Triac	=FP 08C: 500V		21b	TO-48			T 6417..., T 6410..., 2N5446
FP 08 G		Triac	=FP 08C: 600V		21b	TO-48			T 6417..., T 6410..., 2N5446
FP 10 V25	Shi	MOS-N-FET-e	=2SK1394						
FP 10 W50	Shi	MOS-N-FET-e	=2SK1523						
FP 15 W50	Shi	MOS-N-FET-e	=2SK1524						
FPQ 3467	Fch	Si-P	4x PNP Trans., 40V, 1A, >175MHz, <40/-ns		14-DIP	TO-116			-
FPQ 3468	Fch	Si-P	4x PNP Trans., 50V, 1A, >150MHz, <40/-ns		14-DIP	TO-116			-
FPQ 3724	Fch	Si-N	4x NPN Trans., 40V, 1A, >300MHz, <35/-ns		14-DIP	TO-116			CA 1724, DH 3724, MPQ 3724, SP 3724
FPQ 3725	Fch, Rca	Si-N	4x NPN Trans., 50V, 1A, >300MHz, <35/-ns		14-DIP	TO-116			CA 1725, DH 3725, FPQ 3725, SP 3725
FPT 6004		Si-P-Darl	=BD 902		17j	TO-220	BD 902	17j	›BD 902
FPT 6005		Si-N-Darl	=BD 901		17j	TO-220	BD 901	17j	›BD 901
FQ		Si-P	=2SA1037-FQ (SMD-Marking)		≈35	(MMT)			›2SA1037
FQ		Si-P	=2SA1037K-Q (SMD-Marking)		35	SOT-23			›2SA1037K
FQ		Si-P	=2SA1576-Q (SMD-Marking)		35(2mm)	SOT-323			›2SA1576
FQ		Si-P	=2SA1774-FQ (SMD-Marking)		35(1,6mm)	SS Mini			›2SA1774
FQ		Si-P	=2SB1610 (SMD-Marking)		≈35	(T Mini)			›2SB1610
FQ		Si-P	=2SB1618 (SMD-Marking)		35(2mm)	SOT-323			›2SB1618
FQ		Z-Di	=SM 6T 68A (SMD-Marking)		71a(6x4mm)	SOD-6			›SM 6T....
FQ 08 C	Hit	Triac	200V, 20A=(Tc=100°C), Igt/Ih=50/30mA		21b	TO-48			TXE 99..., SC 260..., T 6411..., T 6410...
FQ 08 D		Triac	=FQ 08C: 300V		21b	TO-48			TXE 99..., SC 260..., T 6411..., T 6410...
FQ 08 E		Triac	=FQ 08C: 400V		21b	TO-48			TXE 99..., SC 260..., T 6411..., T 6410...
FQ 08 F		Triac	=FQ 08C: 500V		21b	TO-48			TXE 99..., SC 260..., T 6411..., T 6410...
FQ 08 G		Triac	=FQ 08C: 600V		21b	TO-48			TXE 99..., SC 260..., T 6411..., T 6410...
FQ 3467	Fch	Si-P	=FPQ 3467: SMD		14-MDIP	TO-86			-
FQ 3468	Fch	Si-P	=FPQ 3468: SMD		14-MDIP	TO-86			-
FQ 3724	Fch	Si-N	=FPQ 3724: SMD		14-MDIP	TO-86			-
FQ 3725	Fch	Si-N	=FPQ 3725: SMD		14-MDIP	TO-86			-
FR		Si-P	=2SA1034-R (SMD-Marking)		35	SOT-23			›2SA1034
FR		Si-P	=2SA1037-FR (SMD-Marking)		≈35	(MMT)			›2SA1037
FR		Si-P	=2SA1037K-R (SMD-Marking)		35	SOT-23			›2SA1037K
FR		Si-P	=2SA1531-R (SMD-Marking)		35(2mm)	SOT-323			›2SA1531
FR		Si-P	=2SA1576-R (SMD-Marking)		35(2mm)	SOT-323			›2SA1576
FR		Si-P	=2SA1774-FR (SMD-Marking)		35(1,6mm)	SS Mini			›2SA1774
FR		Si-N	=2SC2716-R (SMD-Marking)		35	SOT-23			›2SC2716
FR		Si-N	=2SC4988 (SMD-Marking)		39	SOT-89			›2SC4988
FR		Si-N	=2SD2472 (SMD-Marking)		≈35	(T Mini)			›2SD2472
FR		Si-N	=2SD2482 (SMD-Marking)		35(2mm)	SOT-323			›2SD2482
FR		Si-N	=KTC3878-R (SMD-Marking)		35	SOT-23			›KTC 3878
FR 1/....		Si-Di	Rr				1N4007	31a	BY 126...127, BY 133...135, 1N4002...07, ++
FR 2/-02....-12	Fjd	Si-Di	Rr, Uni, 200...1200V, 1,1A, Uf<1,1V(2A)		31a	(6x9mmØ)	1N4007	31a	BY 126...127, BY 133...135, 1N4003...07, ++
FR 34	Ssc	Si-Di	Rr, Uni, 100V, 0.2A, Uf<1V(0.2A)		31a	DO-7	BA 159	31a	BAW 52, BAY 19...21, BAY 45
FR 3205 CC	Fch	Si-Di	Dual, 50V, 32A(Tc=130°), Uf<0,95V(16A, <50ns		16	TO-247			BYT 30P/200, BYV 72/50, BYW 99P/50
FR 3210 CC	Fch	Si-Di	=FR 3205: 100V		16	TO-247			BYT 30P/200, BYV 72/100, BYW 99P/100
FR 3215 CC	Fch	Si-Di	=FR 3205: 150V		16	TO-247			BYT 30P/200, BYV 72/150, BYW 99P/150
FR 3220 CC	Fch	Si-Di	=FR 3205: 180V		16	TO-247			BYT 30P/200, BYV 72/200, BYW 99P/200
FR 4001		Ge-Di	=AY 103K		3				›AY 103K
FR 4001 [Thomson]	Tho	Si-Di	=BYX 58/400				›BYX 58/...		›BYX 58/...
FRH 101		Si-Di	≈1N4001				1N4007	31a	›1N4001
FRM 3205 CC	Fch	Si-Di	Dual, 50V, 32A(Tc=107°), Uf<0,95V(16A), <50ns		23	TO-3			BYT 30P/200, BYV 72/50, BYW 99P/50
FRM 3210 CC	Fch	Si-Di	=FRM 3205: 100V		23	TO-3			BYT 30P/200, BYV 72/100, BYW 99P/100
FRM 3215 CC	Fch	Si-Di	=FRM 3205: 150V		16	TO-3			BYT 30P/200, BYV 72/150, BYW 99P/150
FRM 3220 CC	Fch	Si-Di	=FRM 3205: 180V		16	TO-3			BYT 30P/200, BYV 72/200, BYW 99P/200
FRP 805	Fch	Si-Di	P FRr, 50V, 8A(Tc=130°), Uf<0,95V(8A), <50ns		17k	TO-220			BYP 21-50, BYT 79/300, BYW 29/50, FE 8A
FRP 810	Fch	Si-Di	=FRP 805: 100V		17k	TO-220			BYP 21-100, BYT 79/300, BYW 29/100, FE8B
FRP 815	Fch	Si-Di	=FRP 805: 150V		17k	TO-220			BYP 21-150, BYT 79/300, BYW 29/150, FE8C
FRP 820	Fch	Si-Di	=FRP 805: 180V		17k	TO-220			BYP 21-200, BYT 79/300, BYW 29/200, FE8D

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
FRP 840	Fch	Si-Di	P FRr, 400V, 8A(Tc=130°), Uf<1,5V(8A), <75ns		17k	TO-220			BYT 79/400, BYV 29/400, FE 8G
FRP 850	Fch	Si-Di	=FRP 840: 500V		17k	TO-220			BYT 79/500, BYV 29/500, FE 8H
FRP 860	Fch	Si-Di	=FRP 840: 600V		17k	TO-220			BYT 12P/600, FE 8J
FRP 1005	Fch	Si-Di	P FRr, 50V, 10A(117°), Uf<1V(10A), <50ns		17k	TO-220			BYT 79/300, BYV 79/50
FRP 1010	Fch	Si-Di	=FRP 1005: 100V		17k	TO-2200			BYT 79/300, BYV 79/100
FRP 1015	Fch	Si-Di	=FRP 1005: 150V		17k	TO-220			BYT 79/300, BYV 79/150
FRP 1020	Fch	Si-Di	=FRP 1005: 180V		17k	TO-220			BYT 79/300, BYV 79/200
FRP 1605	Fch	Si-Di	P FRr, 50V, 16A(Tc=118°), Uf<0,95V(16A), <50ns		17k	TO-220			BYV 79/50, MUR 1505
FRP 1610	Fch	Si-Di	=FRP 1605: 100V		17k	TO-220			BYV 79/100, MUR 1510
FRP 1615	Fch	Si-Di	=FRP 1605: 150V		17k	TO-220			BYV 79/150, MUR 1515
FRP 1620	Fch	Si-Di	=FRP 1605: 180V		17k	TO-220			BYV 79/200, MUR 1520
FRP 1605...1620 CC		Si-Di	=FRP 1605...1620: Dual		17e	TO-220			BYV 32/..., BYP 22/..., FE 16A...D
FRP 2005 CC	Fch	Si-Di	Dual, 50V, 20A(Tc=117°), Uf<1V(10A), <50ns		17e	TO-220			BYW 51/50, BYP 22-50, BYV 44/300
FRP 2010 CC	Fch	Si-Di	=FRP 2005CC: 100V		17e	TO-220			BYW 51/100, BYP 22-100, BYV 44/300
FRP 2015 CC	Fch	Si-Di	=FRP 2005CC: 150V		17e	TO-220			BYW 51/150, BYP 22-150, BYV 44/300
FRP 2020 CC	Fch	Si-Di	=FRP 2005CC: 180V		17e	TO-220			BYP 22-200, BYV 44/300
FS		Si-P	=2SA1034-S (SMD-Marking)		35	SOT-23			›2SA1034
FS		Si-P	=2SA1037-FS (SMD-Marking)		=35	(MMT)			›2SA1037
FS		Si-P	=2SA1037K-S (SMD-Marking)		35	SOT-23			›2SA1037K
FS		Si-P	=2SA1531-S (SMD-Marking)		35(2mm)	SOT-323			›2SA1531
FS		Si-P	=2SA1576-S (SMD-Marking)		35(2mm)	SOT-323			›2SA1576
FS		Si-P	=2SA1763 (SMD-Marking)		35(2mm)	SOT-323			›2SA1763
FS		Si-P	=2SA1764 (SMD-Marking)		35	SOT-23			›2SA1764
FS		Si-P	=2SA1774-FS (SMD-Marking)		35(1,6mm)	SS Mini			›2SA1774
FS		Si-P	=2SB1611 (SMD-Marking)		=35	(T Mini)			›2SB1611
FS		Si-P	=2SB1619 (SMD-Marking)		35(2mm)	SOT-323			›2SB1619
FS 1/....		Si-Di	=RGP 10G...M				BYD 33 M	31a	›RGP 10G...M
FSM 3 B2	Hit	Triac	200V, 3A=(Tc=67°C), Igt/Ih=40/20mA		13e	TO-202			TAG 136..., ZO 410...
FSM 3 B4		Triac	=FSM 3B2: 400V		13e	TO-202			TAG 136..., ZO 410...
FSM 6 B2	Hit	Triac	200V, 6A=(Tc=103°C), Igt/Ih=30/20mA		17b	TO-220			T 2856..., TAG 426-..., TAG 452-...
FSM 6 B4		Triac	=FSM 6B2: 400V		17b	TO-220			T 2856..., TAG 426-..., TAG 452-...
FSM 10 B4	Hit	Triac	400V, 10A=(Tc=100°C), Igt/Ih=30/20mA		17b	TO-220			TAG 457-..., (BT 162/..., TAG 257-...)[3]
FSM 16 C2	Hit	Triac	200V, 16A=(Tc=76°C), Igt/Ih=50/30mA		65e	=TO-238			MAC 515-..., MAC 525-..., MAC 515A-...
FSM 16 C4		Triac	=FSM 16C2: 400V		65e	=TO-238			MAC 515-..., MAC 525-..., MAC 515A-...
FSM 16 C6		Triac	=FSM 16C2: 600V		65e	=TO-238			MAC 515-..., MAC 525-..., MAC 515A-...
FSM 20 C2	Hit	Triac	=FSM 16C2: 20A(Tc=74°C)		65e	=TO-238			MAC 525-..., MAC 525A-...
FSM 20 C4		Triac	=FSM 16C4: 20A(Tc=74°C)		65e	=TO-238			MAC 525-..., MAC 525A-...
FSM 30 C2		Triac	=FSM 16C2: 30A(Tc=63°C)		65e	=TO-238			(MAC 50-..., MAC 50A-..., TAG 740-...)[4]
FSM 30 C4		Triac	=FSM 16C4: 30A(Tc=63°C)		65e	=TO-238			(MAC 50-..., MAC 50A-..., TAG 740-...)[4]
FSP 100 DC	Fch	CMOS-IC	Progr. Digital Filter		40-DIP				-
FSP 100 LC		CMOS-IC	=FSP 100DC:		44-LCC				-
FT									
FT		Si-P	=2SA1034-T (SMD-Marking)		35	SOT-23			›2SA1034
FT		Si-P	=2SA1531-T (SMD-Marking)		35(2mm)	SOT-323			›2SA1531
FT		Si-N	=2SC4146 (SMD-Marking)		35	SOT-23			›2SC4146
FT		Si-N	=2SD2473 (SMD-Marking)		=35	(T Mini)			›2SD2473
FT		Si-N	=2SD2483 (SMD-Marking)		35(2mm)	SOT-323			›2SD2483
FT 1 M,N,P	Fjd	Si-Di	FRr, 140...600V, 0,3A, Uf<1,5V(1A), <3µs M=600V, N=300V, P=140V		31a	(6x9mmØ)	BA 159	31a	BA 157...159, BY 204/..., BY 208/..., ++
FT 06 B	Hit	Triac	100V, 6A=(Tc=88°C), Igt<75mA		22a	TO-66			TAG 260-..., TAG 265-..., T 4700...
FT 06 C		Triac	=FT 06B: 200V		22a	TO-66			TAG 260-..., TAG 265-..., T 4700...
FT 06 D		Triac	=FT 06B: 300V		22a	TO-66			TAG 260-..., TAG 265-..., T 4700...
FT 06 E		Triac	=FT 06B: 400V		22a	TO-66			TAG 260-..., TAG 265-..., T 4700...
FT 07 C	Hit	Triac	200V, 6A=(Tc=90°C), Igt/Ih=50/20mA		22a	TO-66			TAG 260-..., TAG 265-..., T 4700...
FT 07 D		Triac	=FT 07C: 300V		22a	TO-66			TAG 260-..., TAG 265-..., T 4700...
FT 07 E		Triac	=FT 07C: 400V		22a	TO-66			TAG 260-..., TAG 265-..., T 4700...
FT 07 F		Triac	=FT 07C: 500V		22a	TO-66			TAG 260-..., TAG 265-..., T 4700...
FT 07 G		Triac	=FT 07C: 600V		22a	TO-66			TAG 260-..., TAG 265-..., T 4700...
FT 08 C	Hit	Triac	200V, 6A=(Tc=110°C), Igt/Ih=50/20mA		21b	TO-48			BS6-...A, TW6N...C, BS8-...A, TW8N...C, ++
FT 08 D		Triac	=FT 08C: 300V		21b	TO-48			BS6-...A, TW6N...C, BS8-...A, TW8N...C, ++
FT 08 E		Triac	=FT 08C: 400V		21b	TO-48			BS6-...A, TW6N...C, BS8-...A, TW8N...C, ++
FT 08 F		Triac	=FT 08C: 500V		21b	TO-48			BS6-...A, TW6N...C, BS8-...A, TW8N...C, ++
FT 08 G		Triac	=FT 08C: 600V		21b	TO-48			BS6-...A, TW6N...C, BS8-...A, TW8N...C, ++
FT 12 C	Hit	Triac	200V, 6A=, Igt/Ih=75/20mA		17j	TO-220			MAC 216-..., T 2801..., SC 141..., BS7-...
FT 12 E		Triac	=FT 12C: 400V		17j	TO-220			MAC 216-..., T 2801..., SC 141..., BS7-...
FT 17	Fch	Si-N	UHF, -/15V, >1GHz, PQ>35mW(1GHz)		2a	TO-46			BF 357, BF 378...379, BFW 30, BFX 59, ++
FT 034 A	Fch	Si-N	S P, 150/80V, 10A, 15W(Tc=100°), >80MHz, <0,5/1µs		49m	TO-59			2N5542
FT 034 B	Fch	Si-N	=FT 34A: 120/60V		49m	TO-59			2N5542
FT 034 C	Fch	Si-N	S, 150/80V, 5A, 0,8W, >80MHz, <0,5/1µs		2a	TO-5			BU 125, BUY 48...49, BUY 80...81, ++
FT 034 D	Fch	Si-N	=FT 34C: 120/60V		2a	TO-5			BU 125, BUY 48...49, BUY 80...81, ++
FT 40	Sgs	Si-N	UHF, 15/10V, 0,3W, 1,4GHz, RadH		2a	TO-46			-
FT 45	Sgs	Si-N	VHF, 30/30V 0,2W, >425MHz		5g	TO-72			BF 173, BF 199, BF 224, BF 311, BF 373++
FT 107 A	Fch	Si-N	LF, In, 30/30V, 0,05A, 0,26W, hFE>1200, F<3dB		2a	TO-18			2SC3112...13, 2SD1010...11, 2SD1512
FT 107 B	Fch	Si-N	=FT 107A: 45/45V, hFE=600...1550		2a	TO-18			2SC3112...13, 2SD1010...11, 2SD1512
FT 107 C	Fch	Si-N	=FT 107A: 60/60V, hFE=150...950		2a	TO-18			2N2483...2484, 2N3117, 2SD1011, 2SD1512++
FT 109	Fch	Si-N	HF,S, 15/6V, 0,2A, 0,3W, >600MHz		2a	TO-18			BSS 10...12, BSY 17...18, 2N2369(A), ++
FT 118	Fch	Si-N	VHF, 20/20V, 0,175W, 500MHz		5k	TO-72			BF 173, BF 199, BF 224, BF 311, BF 373++
FT 123	Fch	Si-N	Vid, -/300V, 0,1A, 1W, >60MHz		2a	TO-39			BF 259, BF 659, BFS 89, 2N5058
FT 317(A)		Si-N	=BD 237				BD 237	14h	›BD 237
FT 400A,B	Fch	Si-P	LF P, 80/80V, 8A, 30W(Tc=100°), 120MHz		49a	TO-59			2N6186...6189
FT 401	Fch	Si-N	S P, -/400V, 2A, 100W, >2MHz		23a	TO-3			BUX 46, 2SC3091, 2SC3099, 2SC3155, ++
FT 402	Fch	Si-N	=FT 401: 3,5A		23a	TO-3			BUX 46, 2SC3091, 2SC3099, 2SC3155, ++
FT 410	Fch	Si-N	S P, -/200V, 7,5A, 100W, 5MHz		23a	TO-3			BUX 47, 2SC3090, 2SC3092, 2SD811, ++
FT 411	Fch	Si-N	=FT 410: -/300V		23a	TO-3			BUX 47, 2SC3090, 2SC3092, 2SD811, ++
FT 413	Fch	Si-N	S P, -/400V, 7,5A, 100W, 5MHz		23a	TO-3			BUX 47, 2SC3090, 2SC3092, 2SD811, ++
FT 417(A)		Si-P	=BD 238				BD 238	14h	›BD 238
FT 423	Fch	Si-N	S P, -/400V, 7,5A, 100W, 5MHz		23a	TO-3			BUX 47, 2SC3090, 2SC3092, 2SD811, ++
FT 430	Fch	Si-N	S P, -/400V, 10A, 100W, hFE=15...45		23a	TO-3			BUS 12, BUW 26, BUW 12, BUW 35...36, ++
FT 431	Fch	Si-N	=FT 430: hFE=15...35		23a	TO-3			BUS 12, BUW 26, BUW 12, BUW 35...36, ++
FT 0654(A....C)	Fch	N-FET	=FE 0654(A...C):		2b	TO-18			›FE 0654(A...C)
FT 0655(A....C)	Fch	N-FET	=FE 0655(A...C):		2b	TO-18			›FE 0655(A...C)
FT 701	Fch	MOS-P-FET-e	Dual, 30V, 0,2A, Up<0,6V, 30/-ns		TO-77	(D-GbG-DS)			-

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
FT 703	Fch	MOS-P-FET-e	S, 40V, 0,5A, Up<0,6V, 66/-ns		5(DGSubS)	TO-72			-
FT 704	Fch	MOS-P-FET-e	S, 25V, 20mA, Up<0,6V, 150/-ns		5(DGSubS)	TO-72			-
FT 709	Fch	Si-N	≈2N709		2a	TO-18			›2N709
FT 1210	Fch	Si-N	≈2N917		5k	TO-72			›2N917
FT 1310	Fch	Si-N	SS, 5V, 0,3W, <15/-ns		2a	TO-18			BSS 10…12, BSY 17…18, 2N2368…69, ++
FT 1315	Fch	Si-N	SS, 30V, 0,2A, 0,36W, >500MHz, 12/18ns		2a	TO-18			BSS 10…12, BSY 17…18, 2N2368…69, ++
FT 1324(B,C)	Fch	Si-N	VHF, 25/10V, 0,5A, 0,36W, B: >800MHz, C: >640MHz		2a	TO-18			BFX 55, 2SC2852
FT 1341	Fch	Si-N	S, 25/10V, 0,1A, 0,36W, >480MHz, <65/-ns		2a	TO-18			BSW 41, BSY 62…63, 2N706A, 2N708, ++
FT 1702	Fui	Si-P	HF,S, 12/12V, 0,1A, 0,3W, 700MHz, <60/75ns		2a	TO-18			BSV 21, BSW 25, BSW 37, BSX 36, ++
FT 1718(A….E)	Fch	Si-P	Dual, -/40V, 0,1A, >400MHz, F<6dB(1kHz)		TO-78	(CBE-EBC-)			BFX 11, 2N3726…3727, 2N4015…4016
FT 1724	Fch	Si-N	=2N1724		49a	TO-61			›2N1724
FT 1725	Fch	Si-N	=2N1725		49a	TO-61			›2N1725
FT 1746	Fui	Si-P	Uni, 35/30V, 0,36W, 150MHz		2a	TO-18			BC 213, BC 258, BC 308, BC 558, 2SA1295+
FT 1869….1874	Fch	50Hz-Thy	=2N1869…1874		2a	TO-5			›2N1869…1874
FT 1881….1885	Fch	50Hz-Thy	=2N1881…1885		2a	TO-5			›2N1881…1885
FT 2009….2013	Fch	50Hz-Thy	=2N2009…2013		2a	TO-5			›2N2009…2013
FT 2368	Fch	Si-N	›2N2368		2a	TO-18			
FT 2369	Fch	Si-N	›2N2369		2a	TO-18			
FT 2383	Fch	Si-N	›2N2383		2a	TO-18			
FT 2384	Fch	Si-N	›2N2384		2a	TO-18			
FT 2955		Si-P	≈BD 204		17j	TO-220	BD 244 C	17j	›BD 204
FT 2974	Fch	Si-N	=2N2974: ΔUbe<1,5mV		TO-71	(EBC-EBC-)			›2N2974
FT 2975	Fch	Si-N	=2N2975: ΔUbe<1,5mV		TO-71	(EBC-EBC-)			›2N2975
FT 2978	Fch	Si-N	=2N2978: ΔUbe<1,5mV		TO-71	(EBC-EBC-)			›2N2978
FT 2979	Fch	Si-N	=2N2979: ΔUbe<1,5mV		TO-71	(EBC-EBC-)			›2N2979
FT 3055		Si-N	≈BD 203		17j	TO-220	BD 243 C	17j	›BD 203
FT 3567	Fch	Si-N	=2N3567: 0,5W		8a	TO-105			›2N3567
FT 3568	Fch	Si-N	=2N3568: 0,5W		8a	TO-105			›2N3568
FT 3569	Fch	Si-N	=2N3569: 0,5W		8a	TO-105			›2N3569
FT 3641	Fch	Si-N	=2N3641: 0,45W		8a	TO-105			›2N3641
FT 3642	Fch	Si-N	=2N3642: 0,45W		8a	TO-105			›2N3642
FT 3643	Fch	Si-N	=2N3643: 0,45W		8a	TO-105			›2N3643
FT 3644	Fch	Si-P	=2N3644: 0,45W		8a	TO-105			›2N3644
FT 3645	Fch	Si-P	=2N3645: 0,45W		8a	TO-105			›2N3645
FT 3722	Fch	Si-N	=2N3722: 0,5W		8a	TO-105			›2N3722
FT 3723	Fch	Si-N	=2N3723		2a	TO-5			›2N3723
FT 3820	Fch	P-FET	=2N3820: 0,2W		8b	TO-106			›2N3820
FT 4017….4025	Fch	Si-P	=2N4017…4025: 0,5W		TO-71	(EBC-EBC-)			›(2N4017…4025)[5]
FT 4354….4356	Fch	Si-P	=2N4354…4356: 0,5W		8a	TO-105			›2N4354…4356
FT 5040….5041	Fch	Si-P	=2N5040…5041: 0,5W		8a	TO-105			›2N5040…5041
FT 5415	Fch	Si-P	=2N5415: 0,5W		8a	TO-105	MPS-U60[6]	13m	›2N5415
FT 7207 A	Fch	Si-N	LF,S P, 120/80V, 5A, 30W(Tc=100°), >70MHz		49a	TO-59			2N5284…5285
FT 7207 B	Fch	Si-N	=FT 7207A: 100/60V		49a	TO-59			2N5002, 2N5004, 2N5284…5285
FU…FZ									
FU 1 M,N,P	Fjd	Si-Di	FRr, 140…600V, 0,2A, Uf<2,5V(0,5A), <400ns M=600V, N=300V, P=140V		31a	(6x9mmØ)	BA 159	31a	BA 157…159, BY 204/…, BY 208/…, ++
FU 12 B	Hit	Triac	100V, 3A≈, Igt/Ih=30/20mA		17j	TO-220	TAG 232-600	17j	TAG 230-…, TAG 231-…, TAG 220-…, ++
FU 12 C		Triac	=FU 12B: 200V		17j	TO-220	TAG 232-600	17j	TAG 230-…, TAG 231-…, TAG 220-…, ++
FU 12 D		Triac	=FU 12B: 300V		17j	TO-220	TAG 232-600	17j	TAG 230-…, TAG 231-…, TAG 220-…, ++
FU 12 E		Triac	=FU 12B: 400V		17j	TO-220	TAG 232-600	17j	TAG 230-…, TAG 231-…, TAG 220-…, ++
FV		PIN-Di	=1SV248 (SMD-Marking)		35 (2mm)	SOT-323			›1SV248
FV		PIN-Di	=1SV250 (SMD-Marking)		35	SOT-23			›1SV250
FV 1043		C-Di	≈BB 103						›BB 103
FX		Si-P	=2SB1571-FX (SMD-Marking)		39	SOT-89			›2SB1571
FX		Z-Di	=SM 6T 100 (SMD-Marking)		71a(6x4mm)	SOD-6			›SM 6T….
FX 107(A….C)	Fch	Si-N	=FT 107(A…C):		≈24	TO-120			›(FT 107(A…C))[6]
FX 914	Fch	Si-N	=2N914: 0,25W		≈24	TO-120			›(2N914)[6]
FX 918	Fch	Si-N	=2N918: 0,25W		≈24	TO-120			›(2N918)[6]
FX 2368….2369(A)	Fch	Si-N	=2N2368…2369(A): 0,25W		≈24	TO-120			›(2N2368…2369(A))[6]
FX 2483….2484	Fch	Si-N	=2N2483…2484: 0,25W		≈24	TO-120			›(2N2483…2484)[6]
FX 2894(A)	Fch	Si-P	=2N2894(A): 0,25W		≈24	TO-120			›(2N2894(A))[6]
FX 3299….3300	Fch	Si-N	=2N3299…3300: 0,25W		≈24	TO-120			›(2N3299…3300)[6]
FX 3502….3503	Fch	Si-P	=2N3502…3503: 0,25W		≈24	TO-120			›(2N3502…3503)[6]
FX 3724….3725	Fch	Si-N	=2N3724…3725: 0,25W		≈24	TO-120			›(2N3724…3725)[6]
FX 3962….3965	Fch	Si-P	=2N3962…3965: 0,25W		≈24	TO-120			›(2N3962…3965)[6]
FX 4046….4047	Fch	Si-N	=2N4046…4047: 0,25W		≈24	TO-120			›(2N4046…4047)[6]
FX 4207	Fch	Si-P	=2N4207: 0,25W		≈24	TO-120			›(2N4207)[6]
FX 4960	Fch	Si-N	=2N4960: 0,25W		≈24	TO-120			›(2N4960)[6]
FY		Si-P	=2SA1202-Y (SMD-Marking)		39	SOT-89			›2SA1202
FY		Si-P	=2SB1571-FY (SMD-Marking)		39	SOT-89			›2SB1571
FY		Si-N	=2SC2761-Y (SMD-Marking)		35	SOT-23			›2SC2761
FY		Si-N	=2SC3661 (SMD-Marking)		35	SOT-23			›2SC3661
FY		Si-N	=BSV 65RA (SMD-Marking)		35	SOT-23			›BSV 65RA
FY		Si-P	=KTA1662-Y (SMD-Marking)		39	SOT-89			›KTA 1662
FY		Si-N	=KTC3878-Y (SMD-Marking)		35	SOT-23			›KTC 3878
FY		Z-Di	=SM 6T 100A (SMD-Marking)		71a(6x4mm)	SOD-6			›SM 6T….
FZ		Si-P	=2SB1571-FZ (SMD-Marking)		39	SOT-89			›2SB1571
FZ		Si-N	=BSV 65RB (SMD-Marking)		35	SOT-23			›BSV 65RB
FZH 211 S	Sie	LIN-IC	Pegelwandler/Level Shift, 0…+70°		16-DIP				-
FZH 215 S	Sie	LIN-IC	=FZH 211S: -25…+85°		16-DIP				-
FZL 135 S		LIN-IC	Leistungstreiber/Power Driver						E 435E
FZL 4141 D	Sie	LIN-IC	4x Treiber/Driver, Ucc=4,5…35V, 0…+70°		18-DIP				-
FZL 4145 D	Sie	LIN-IC	=FZL 4141D: -25…+85°		18-DIP				-
FZL 4146 G	Sie	LIN-IC	4x Treiber/Driver, Ucc=4,5…40V, -25…+125°		20-MDIP				-
G									
G 1(p)		Si-N	=BFS 20 (SMD-Marking)		35	SOT-23			›BFS 20
G 1 A….M	Gie	Si-Di	Rr, Uni, 50…1000V, 1A, Uf<1,2V(1A), 2µs A=50, B=100, D=200, G=400, J=600, K=800, M=1000V		31a	SOD-57	BY 133	31a	BY 126…127, BY 133…135, 1N4001…07, ++
G 1		Si-N	=D70Y1.5T1 (SMD-Marking)		39	SOT-89			›D70Y1.5T1
G 2		Si-P	=BF 550 (SMD-Marking)		35	SOT-23			›BF 550

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
G 2		Si-N	=BF 599 (SMD-Marking)		35	SOT-23			›BF 599
G 2 A....M	Gie	Si-Di	Rr, Uni, 50...1000V, 2A, Uf<1,2V(2A), 2µ A=50, B=100, D=200, G=400, J=600, K=800, M=1000V		31a	SOD-57	BY 255	31a	BY 251...255, BY 259/..., GP 20A...M, ++
G 2 N 2955		Si-P	≈BD 318		23a	TO-3	BD 318	23a	›BD 318
G 2 N 3055		Si-N	≈BD 317		23a	TO-3	BD 317	23a	›BD 317
G 3		Si-P	=BF 536 (SMD-Marking)		35	SOT-23			›BF 536
G 3		Si-Di	=1SS196 (SMD-Marking)		35	SOT-23			›1SS196
G 3		Si-P	=2SA1257-3 (SMD-Marking)		35	SOT-23			›2SA1257
G 3		Si-N	=2SC2107-G3 (SMD-Marking)		35	SOT-23			›2SC2107
G 3 A....M	Gie	Si-Di	Rr, Uni, 50...1000V, 3A, Uf<1,1V(3A), 3µ A=50, B=100, D=200, G=400, J=600, K=800, M=1000V		31a	SOD-64	BY 255	31a	BY 251...255, GP 30A...M, 1N5400...08, ++
G 4		Si-N	=BFS 20R (SMD-Marking)		35	SOT-23			›BFS 20R
G 4		Si-P	=2SA1257-4 (SMD-Marking)		35	SOT-23			›2SA1257
G 4		Si-N	=2SC2107-G4 (SMD-Marking)		35	SOT-23			›2SC2107
G 4 A....M	Gie	Si-Di	Rr, Uni, 50...1000V, 3A, Uf<1,1V(3A), 3µs A=50, B=100, D=200, G=400, J=600, K=800, M=1000V		31a	SOD-64	BY 255	31a	BY 251...255, GP 30A...M, 1N5400...08, ++
G 5		Si-P	=2SA1257-5 (SMD-Marking)		35	SOT-23			›2SA1257
G 5		Si-N	=2SC2107-G5 (SMD-Marking)		35	SOT-23			›2SC2107
G 5		Si-P	=BF 550R (SMD-Marking)		35	SOT-23			›BF 550R
G 5/2		Ge-Di	≈OA 70		31a		AA 138	31a	›OA 70
G 5/61		Ge-Di	≈AA 119		31a		AA 119	31a	›AA 119
G 6		Si-N	=2SC2107-G6 (SMD-Marking)		35	SOT-23			›2SC2107
G 6		Si-P	=BF 569 (SMD-Marking)		35	SOT-23			›BF 569
G 7		Si-P	=BF 579 (SMD-Marking)		35	SOT-23			›BF 579
G 8		Si-P	=BF 660 (SMD-Marking)		35	SOT-23			›BF 660
G 9		Si-P	=BF 767 (SMD-Marking)		35	SOT-23			›BF 767
G 11		MOS-N-FET-e	=2SK1133 (SMD-Marking)		35	SOT-23			›2SK1133
G 13		MOS-N-FET-e	=2SK1580 (SMD-Marking)		35(2mm)	SOT-323			›2SK1580
G 14		MOS-N-FET-e	=2SK1581 (SMD-Marking)		35	SOT-23			›2SK1581
G 16		MOS-N-FET-e	=2SK1590 (SMD-Marking)		35	SOT-23			›2SK1590
G 17		MOS-N-FET-e	=2SK1589 (SMD-Marking)		35	SOT-23			›2SK1589
G 18		MOS-N-FET-e	=2SK1582 (SMD-Marking)		35	SOT-23			›2SK1582
G 18		MOS-N-FET-e	=2SK1591 (SMD-Marking)		35	SOT-23			›2SK1591
G 19		MOS-N-FET-e	=2SK1657 (SMD-Marking)		35	SOT-23			›2SK1657
G 20		MOS-N-FET-e	=2SK1658 (SMD-Marking)		35(2mm)	SOT-323			›2SK1658
G 21		MOS-N-FET-e	=2SK1958 (SMD-Marking)		35(2mm)	SOT-323			›2SK1958
G 22		MOS-N-FET-e	=2SK2090 (SMD-Marking)		35(2mm)	SOT-323			›2SK2090
G 23		MOS-N-FET-e	=2SK2158 (SMD-Marking)		35	SOT-23			›2SK2158
G 61		Si-P	=BF 569R (SMD-Marking)		35	SOT-23			›BF 569R
G 81		Si-P	=BF 660R (SMD-Marking)		35	SOT-23			›BF 660R
G 088		Si-St	≈BZ 102/0V7		31a		(1N4148)	31a	›BZ 102/0V7
G 150	Sie	LIN-IC	Telecom, Teilnehmerschaltung (SLIC)		28-DIP				-
G 580	Itt	Ge-Di	Uni, 20V, 0,2A, Uf<0,5V(10mA)		31a	DO-7	(AA 138)	31a	AA 139, 1N270
G 6004		Si-P-Darl	≈BD 700		15j		BD 902	17j	›BD 700
G 6005		Si-N-Darl	≈BD 699		15j		BD 901	17j	›BD 699
G 8870		LIN-IC	›KT 3170						KT 3170, MT 8870
GA									
GA		Si-N	=µPA600T (SMD-Marking)		46	SOT-163			›µPA600T
GA		Si-N	=2SD1463-GA (SMD-Marking)		39	SOT-89			›2SD1463
GA		Si-Di	=BAW 78A (SMD-Marking)		39	SOT-89			›BAW 78A
GA		Si-N	=BFR 35 (SMD-Marking)		35	SOT-23			›BFR 35
GA		Si-P	=S 416 T (SMD-Marking)		35	SOT-23			›S 416 T
GA 1		Si-P	=2SB1871-GA1 (SMD-Marking)		39	SOT-89			›2SA1871
GA 1 A3Q	Nec	Si-N+R	=AA 1A3Q: SMD	{GN1A3Q	35a(2mm)	SOT-323			DTC 113ZU
GA 1 A4M	Nec	Si-N+R	=AA 1A4M: SMD	{GN1A4M	35a(2mm)	SOT-323			DTC 114EU, 2SC4398
GA 1 A4P	Nec	Si-N+R	=AA 1A4P: SMD	{GN1A4P	35a(2mm)	SOT-323			DTC 114YU
GA 1 A4Z	Nec	Si-N+R	=AA 1A4Z: SMD	{GN1A4Z	35a(2mm)	SOT-323			DTC 114TU
GA 1 F4M	Nec	Si-N+R	=AA 1F4M: SMD	{GN1F4M	35a(2mm)	SOT-323			DTC 124EU, 2SC4397
GA 1 F4N	Nec	Si-N+R	=AA 1F4N: SMD	{GN1F4N	35a(2mm)	SOT-323			DTC 124XU
GA 1 F4Z	Nec	Si-N+R	=AA 1F4Z: SMD	{GN1F4Z	35a(2mm)	SOT-323			DTC 124TU
GA 1 L3M	Nec	Si-N+R	=AA 1L3M: SMD	{GN1L3M	35a(2mm)	SOT-323			DTC 143EU
GA 1 L3N	Nec	Si-N+R	=AA 1L3N: SMD	{GN1L3N	35a(2mm)	SOT-323			DTC 143XU
GA 1 L3Z	Nec	Si-N+R	=AA 1L3Z: SMD	{GN1L3Z	35a(2mm)	SOT-323			DTC 143TU
GA 1 L4L	Nec	Si-N+R	=AA 1L4L: SMD	{GN1L4L	35a(2mm)	SOT-323			DTC 144WU
GA 1 L4M	Nec	Si-N+R	=AA 1L4M: SMD	{GN1L4M	35a(2mm)	SOT-323			DTC 144EU, 2SC4396
GA 1 L4Z	Nec	Si-N+R	=AA 1L4Z: SMD	{GN1L4Z	35a(2mm)	SOT-323			DTC 144TU
GA 2		Si-P	=2SB1871-GA2 (SMD-Marking)		39	SOT-89			›2SA1871
GA 3		Si-P	=2SB1871-GA3 (SMD-Marking)		39	SOT-89			›2SA1871
GA 100	Hfo	Ge-Di	Uni, 26V, 0,02A		31a		AA 133	31a	AA 132...134, 1N34, 1N54, 1N60
GA 101	Hfo	Ge-Di	Uni, 50V, 0,015A		31a		AA 133	31a	AA 132...134, 1N34, 1N54, 1N60
GA 102	Hfo	Ge-Di	Uni, 60V, 0,012A		31a		AA 133	31a	AA 132...134, 1N34, 1N54, 1N60
GA 103	Hfo	Ge-Di	Uni, 90V, 0,01A		31a		AA 133	31a	AA 117...118, AA 132...133
GA 104	Hfo	Ge-Di	Uni, 115V, 0,01A		31a		AA 133	31a	AA 117...118, AA 132...133
GA 105	Hfo	Ge-Di	Uni, 26V, 0,02A		31a		AA 133	31a	AA 132...134, 1N34, 1N54, 1N60
GA 106	Hfo	Ge-Di	S, 35V, 0,03A(ss), 500ns		31a		AA 133	31a	AAY 49, AAZ 15, AAZ 17, 1N276
GA 107	Hfo	Ge-Di	S, 90V, 0,15A(ss), 500ns		31a		AA 133	31a	AAZ 15
GA 108	Hfo	Ge-Di	Uni, 90V, 0,02A		31a		AA 133	31a	AA 117...118, AA 132...133
(2)GA 109	Hfo	Ge-Di	FM Dem, 50V, 0,015A		31a		AA 138	31a	AA 113, 1N34, 1N54, 1N60
(2)GA 113	Hfo	Ge-Di	Dem, Diskr, 35V, 0,03A(ss)		31a		AA 138	31a	AA 113, AA 119, 1N34, 1N54, 1N60
(4)GA 114	Hfo	Ge-Di	4x Ge-Di, Ring-Dem, 35V, 0,03A(ss)		31a				›4x GA 113
GA 5005(A....T)	Gie,Tho	Si-Di	TV-Booster-Di, 6...7kV, 0,3...0,44/3A, Uf<10V(0,5A)						-
GAY 60	Hfo	Ge-Di	Uni, S, 20V, 0,075A		31a				AA 132...134, 1N34, 1N54, 1N60
GAY 61	Hfo	Ge-Di	Uni, S, 20V, 0,1A		31a				AA 135...136, AA 139
GAY 62	Hfo	Ge-Di	Uni, S, 20V, 0,1A		31a				AA 135...136, AA 139
GAY 63	Hfo	Ge-Di	Uni, S, 40V, 0,1A		31a				AA 136, 1N270
GAY 64	Hfo	Ge-Di	Uni, S, 80V, 0,075A		31a				1N270
GAZ 14	Hfo	Ge-Di	S, 25V, 0,02A, 500ns		31a				AAY 49, AAZ 15, AAZ 17, 1N276
GAZ 15	Hfo	Ge-Di	Uni, S, 25V, 0,02A		31a				AA 132...134, 1N34, 1N54, 1N60
GAZ 16	Hfo	Ge-Di	=GAZ 14		31a				›GAZ 14
GAZ 17	Hfo	Ge-Di	=GAZ 15		31a				›GAZ 15

Original	Fabric.	Constr.	Info	{Compl.	Fig.	JAEGER	Fig.	International
GB								
GB		Si-N	=2SD1463-GB (SMD-Marking)		39	SOT-89		›2SD1463
GB		Si-Di	=BAW 78B (SMD-Marking)		39	SOT-89		›BAW 78B
GB		Si-N	=BFR 35A (SMD-Marking)		35	SOT-23		›BFR 35A
GB 1		Si-P	=2SB1578-GB1 (SMD-Marking)		39	SOT-89		›2SA1578
GB 2		Si-P	=2SB1578-GB2 (SMD-Marking)		39	SOT-89		›2SA1578
GB 3		Si-P	=2SB1578-GB3 (SMD-Marking)		39	SOT-89		›2SA1578
GBC 107		Si-N	=BC 237		7a	TO-92	BC 546	7a ›BC 237
GBC 108		Si-N	=BC 238		7a	TO-92	BC 546	7a ›BC 238
GBC 109		Si-N	=BC 239		7a	TO-92	BC 550	7a ›BC 239
GBD 179		Si-N	=BD 179		14h	TO-126	BD 237	14h ›BD 179
GBD 189		Si-N	=BD 189		14h	TO-126	BD 189	14h ›BD 189
GBD 190		Si-P	=BD 190		14h	TO-126	BD 190	14h ›BD 190
GBD 266		Si-P-Darl	=BD 700		15j		BD 902	17j ›BD 700
GBD 267		Si-N-Darl	=BD 699		15j		BD 901	17j ›BD 699
GBD 645		Si-N-Darl	=BD 699		15j		BD 901	17j ›BD 699
GBD 646		Si-P-Darl	=BD 700		15j		BD 902	17j ›BD 700
GC								
GC		Si-N	=2SC2734 (SMD-Marking)		35	SOT-23		›2SC2734
GC		Si-N	=2SC4264 (SMD-Marking)		35(2mm)	SOT-323		›2SC4264
GC		Si-Di	=BAW 78C (SMD-Marking)		39	SOT-89		›BAW 78C
GC 100	Hfo	Ge-P	LF Inp 15V, 15mA, 0,03W		2a		AC 151	2a AC 122, AC 125…126, AC 151
GC 101	Hfo	Ge-P	LF Inp, 15V, 15mA, 0,03W		2a		AC 151	2a AC 122, AC 125…126, AC 151
GC 102	Hfo	Ge-P	LF Inp,Drv, 15V, 50mA		2a		AC 151	2a AC 122, AC 125…126, AC 151
GC 103	Hfo	Ge-P	LF Inp, 15V, 15mA		2a		AC 151	2a AC 122, AC 125…126, AC 151
GC 104	Hfo	Ge-P	=GC 103: In		2a		AC 151	2a AC 151r, ACY 32
GC 111	Hfo	Ge-P	LF, 80V, 0,125A, 0,07W		2a			ACY 39, 2N2042…2043
GC 112	Hfo	Ge-P	LF, 80V, 0,125A, 0,07W		2a			ACY 39, 2N2042…2043
GC 115	Hfo	Ge-P	LF Inp,Drv, 20V, 0,15A, 0,07W		2a		AC 151	2a AC 122, AC 125…126, AC 151
GC 116	Hfo	Ge-P	LF Inp,Drv, 20V, 0,15A, 0,07W		2a		AC 151	2a AC 122, AC 125…126, AC 151
GC 117	Hfo	Ge-P	=GC 116: In		2a		AC 151	2a AC 151r, ACY 32
GC 118	Hfo	Ge-P	=GC 116: In		2a		AC 151	2a AC 151r, ACY 32
GC 120	Hfo	Ge-P	LF Drv,Out, 20V, 0,15A, 0,07W		2a		AC 188 K	3a AC 128, AC 152…153, AC 188
GC 121	Hfo	Ge-P	LF Drv,Out, 20V, 0,15A, 0,07W		2a		AC 188 K	3a AC 128, AC 152…153, AC 188
GC 122	Hfo	Ge-P	LF,S, 30V, 0,15A, 0,07W		2a		AC 188 K	3a AC 128, AC 152…153, AC 188
GC 123	Hfo	Ge-P	=GC 122: 60V		2a			ACY 24, ASY 48, ASY 77
GC 181(A)[Grundig]		Si-P	=BC 181		7e		BC 556	7a ›BC 181
GC 189 [Grundig]		Si-N	=BC 238		7e		BC 546	7a ›BC 238
GC 195 [Grundig]		Si-N-Darl	=BC 517		7a, 7e		(BC 879)	7c ›BC 517
GC 196 [Grundig]		Si-N	=BC 337		7e		BC 337	7a ›BC 337
GC 197 [Grundig]		Si-P	=BC 327		7e		BC 327	7a ›BC 327
GC 198 [Grundig]		Si-P	=BC 161				BC 161	2a ›BC 161
GC 214 [Grundig]		Si-P	=BC 214		7a		BC 560	7a ›BC 214
GC 216	Hfo	Ge-P	LF Drv,Out, 20V, 0,1A, 0,075W		2a		AC 151	2a AC 122, AC 125…126, AC 151
GC 217	Hfo	Ge-P	LF Drv,Out, 20V, 0,1A, 0,075W		2a		AC 151	2a AC 122, AC 125…126, AC 151
GC 221	Hfo	Ge-P	LF Drv,Out, 20V, 0,1A, 0,075W		2a		AC 151	2a AC 122, AC 125…126, AC 151
GC 223	Hfo	Ge-P	=GC 221: 60V		2a			ACY 24, ASY 48, ASY 77
GC 223(A,B)[Grun.]		Si-N	=BC 337		7a		BC 337	7a ›BC 337
GC 237 [Grundig]		Si-N	=BC 237		7a		BC 546	7a ›BC 237
GC 238 [Grundig]		Si-N	=BC 238		7a		BC 546	7a ›BC 238
GC 239 [Grundig]		Si-N	=BC 239		7a		BC 550	7a ›BC 239
GC 269 [Grundig]		Si-P	=BC 328		7a		BC 327	7a ›BC 328
GC 300	Hfo	Ge-P	LF Out, 20V, 0,5A, 0,6W		2a		AC 188 K	3a AC 128, AC 152…153, AC 188
GC 301	Hfo	Ge-P	LF Drv,Out, 32V, 0,5A		2a		AC 188 K	3a AC 128, AC 153, AC 188
GC 307 [Grundig]		Si-P	=BC 307		7a		BC 556	7a ›BC 307
GC 308 [Grundig]		Si-P	=BC 308		7a		BC 556	7a ›BC 308
GC 309 [Grundig]		Si-P	=BC 309		7a		BC 560	7a ›BC 309
GC 371 [Grundig]		Si-N	=BC 338		7a		BC 337	7a ›BC 338
GC 372 [Grundig]		Si-P	=BC 328		7a		BC 327	7a ›BC 328
GC 373 [Fairch.]		Si-N	=BC 368		7a		BC 337	7a ›BC 368
GC 373 [Valvo]		Si-N	=BC 368		7c		BC 639	7c ›BC 368
GC 374 [Fairch.]		Si-P	=BC 369		7a		BC 327	7a ›BC 369
GC 374 [Valvo]		Si-P	=BC 369		7c		BC 640	7c ›BC 369
GC 500	Hfo	Ge-P	LF Drv,Out, 24V, 0,3A, 0,55W		1a		AC 188 K	3a AC 128, AC 152…153, AC 188
GC 501	Hfo	Ge-P	LF Drv,Out, 24V, 0,3A, 0,55W		1a		AC 188 K	3a AC 128, AC 152…153, AC 188
GC 502	Hfo	Ge-P	LF Drv,Out, 32V, 0,3A, 0,55W		1a		AC 188 K	3a AC 128, AC 152…153, AC 188
GC 503	Hfo	Ge-P	Min, LF, 7V, 5mA, 0,01W		37d			OC 57…60
GC 504	Hfo	Ge-P	Min, LF, 7V, 5mA, 0,01W		37d			OC 57…60
GC 505	Hfo	Ge-P	Min, LF, 7V, 5mA, 0,01W		37d			OC 57…60
GC 506	Hfo	Ge-P	Min, LF, 7V, 5mA, 0,01W		37d			OC 57…60
GC 507	Hfo	Ge-P	LF Drv 32V, 0,125A, 0,125W		1a		AC 151	2a AC 122, AC 125…126, AC 151
GC 508	Hfo	Ge-P	LF Drv 32V, 0,125A, 0,125W		1a		AC 151	2a AC 122, AC 125…126, AC 151
GC 509	Hfo	Ge-P	LF Drv 60V, 0,125A, 0,125W		1a			ACY 24, ASY 48, ASY 77
GC 510	Hfo	Ge-P	LF Out, 32V, 1A, 0,2W		1a		AC 188 K	3a AC 128, AC 153, AC 188
GC 510 K	Hfo	Ge-P	=GC 510: 0,3W		3a		AC 188 K	3a AC 128K, AC 153K, AC 188K
GC 511	Hfo	Ge-P	LF Out, 25V, 1A, 0,2W		1a		AC 188 K	3a AC 128, AC 153, AC 188
GC 511 K		Ge-P	=GC 511: 0,3W		3a		AC 188 K	3a AC 128K, AC 153K, AC 188K
GC 512	Hfo	Ge-P	LF Out, 25V, 1A, 0,2W		1a		AC 188 K	3a AC 128, AC 153, AC 188
GC 512 K		Ge-P	=GC 512: 0,3W		3a		AC 188 K	3a AC 128K, AC 153K, AC 188K
GC 515	Hfo	Ge-P	LF Drv,Out, 32V, 0,125A, 0,125W		1a		AC 151	2a AC 122, AC 125…126, AC 151
GC 516	Hfo	Ge-P	LF Drv,Out, 32V, 0,125A, 0,125W		1a		AC 151	2a AC 122, AC 125…126, AC 151
GC 517	Hfo	Ge-P	LF Drv,Out, 32V, 0,125A, 0,125W		1a		AC 151	2a AC 122, AC 125…126, AC 151
GC 518	Hfo	Ge-P	LF Drv,Out, 32V, 0,125A, 0,125W		1a		AC 151	2a AC 122, AC 125…126, AC 151
GC 519	Hfo	Ge-P	LF Drv,Out, 32V, 0,125A, 0,125W		1a		AC 151	2a AC 122, AC 125…126, AC 151
GC 520	Hfo	Ge-N	LF Out, 32V, 1A, 0,2W		1a		AC 187 K	3a AC 176, AC 187
GC 520 K		Ge-N	=GC 520: 0,3W		3a		AC 187 K	3a AC 176K, AC 187K
GC 521	Hfo	Ge-N	LF Out, 25V, 1A, 0,2W		1a		AC 187 K	3a AC 176, AC 187
GC 521 K		Ge-N	=GC 521: 0,3W		3a		AC 187 K	3a AC 176K, AC 187K
GC 522	Hfo	Ge-N	LF Out, 20V, 1A, 0,2W		1a		AC 187 K	3a AC 176, AC 187
GC 522 K		Ge-N	=GC 522: 0,3W		3a		AC 187 K	3a AC 176K, AC 187K
GC 525	Hfo	Ge-N	LF Drv,Out, 15V, 0,125A, 0,125W		1a		AC 187 K	3a AC 127, AC 176, AC 187

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
GC 526	Hfo	Ge-N	LF Drv,Out, 32V, 0,125A, 0,125W		1a		AC 187 K	3a	AC 127, AC 176, AC 187
GC 527	Hfo	Ge-N	LF Drv,Out, 32V, 0,125A, 0,125W		1a		AC 187 K	3a	AC 127, AC 176, AC 187
GCN 53	Hfo	Ge-N	LF Drv,Out, 30V, 0,25A, 0,125W		1a		AC 187 K	3a	AC 127, AC 176, AC 187
GCN 54	Hfo	Ge-N	LF Drv,Out, 48V, 0,25A, 0,125W		1a				-
GCN 55	Hfo	Ge-P	LF Drv,Out, 32V, 0,125A, 0,125W		1a		AC 188 K	3a	AC 128, AC 152…153, AC 188
GCN 56	Hfo	Ge-P	LF Drv,Out, 60V, 0,125A, 0,125W		1a				ACY 24, ASY 48, ASY 77
GD									
GD		Si-Di	=BAW 78D (SMD-Marking)		39	SOT-89			›BAW 78D
GD 100	Hfo	Ge-P	LF P, 20V, 1,3A, 2W(Tc=45°)		22a	TO-66	AD 162	22a	AD 162
GD 110	Hfo	Ge-P	LF P, 20V, 1,3A, 2W(Tc=45°)		22a	TO-66	AD 162	22a	AD 162
GD 114 [Grundig]		Si-P	≈BD 246B		16h		(BD 246 C)[5]	18j	›BD 246B
GD 115 [Grundig]		Si-N	≈BD 245B		16h		(BD 245 C)[5]	18j	›BD 245B
GD 120	Hfo	Ge-P	LF P, 33V, 1,3A, 2W(Tc=45°)		22a	TO-66	AD 162	22a	AD 162
GD 125	Hfo	Ge-P	LF P, 66V, 1,3A, 2W(Tc=45°)		22a	TO-66			-
GD 130	Hfo	Ge-P	LF P, 66V, 1,3A, 2W(Tc=45°)		22a	TO-66			-
GD 133 [Grundig]		Si-P	≈BD 140		14h	TO-126	BD 238	14h	›BD 140
GD 134 [Grundig]		Si-P	≈BD 246B				BD 246 C	18j	›BD 246B
GD 135 [Grundig]		Si-N	≈BD 245B				BD 245 C	18j	›BD 245B
GD 142 [Grundig]		Si-N	≈2N3055		23a	TO-3	2N3055	23a	›2N3055
GD 150	Hfo	Ge-P	LF P, 20V, 3A, 5,3W		22a	TO-66	(AD 162)[7]	22a	(AD 162, 2SB474)[7]
GD 151 [Grundig]		Si-N	≈BD 433		14h	TO-126	BD 189	14h	›BD 433
GD 152 [Grundig]		Si-P	≈BD 434		14h	TO-126	BD 190	14h	›BD 434
GD 160(A….C)	Hfo	Ge-P	LF P, 20V, 3A, 5,3W		22a	TO-66	(AD 162)[7]	22a	(AD 162, 2SB474)[7]
GD 170(A….C)	Hfo	Ge-P	=GD 160: 33V		22a	TO-66	(AD 162)[7]	22a	(AD 162, 2SB474)[7]
GD 175(A….C)	Hfo	Ge-P	=GD 160: 50V		22a	TO-66			-
GD 180(A….C)	Hfo	Ge-P	=GD 160: 66V		22a	TO-66			-
GD 183 [Grundig]		Si-P	≈BD 136		14h	TO-126	BD 140	14h	›BD 136
GD 190	Hfo	Ge-P	LF P, 30V, 1,5A		22a	TO-66	AD 162	22a	AD 162
GD 191	Hfo	Ge-P	LF P, 40V, 1,5A		22a	TO-66	AD 162	22a	AD 162
GD 192	Hfo	Ge-P	LF P, 50V, 1,5A		22a	TO-66			-
GD 200	Hfo	Ge-P	LF P, 30V, 6A, 12W(Tc=50°)		23a	TO-3	AL 102	23a	AL 102…103, AUY 22(A), AUY 28
GD 203 [Grundig]		Si-N	≈BD 243B		17j	TO-220	BD 243 C	17j	›BD 243B
GD 204 [Grundig]		Si-P	≈BD 244B		17j	TO-220	BD 244 C	17j	›BD 244B
GD 207 [Grundig]		Si-N	≈BD 243B		17j	TO-220	BD 243 C	17j	›BD 243B
GD 210	Hfo	Ge-P	LF P, 60V, 6A, 12W(Tc=50°)		23a	TO-3	AL 102	23a	AL 102…103, AUY 22(A), AUY 28
GD 220	Hfo	Ge-P	LF P, 80V, 6A, 12W(Tc=50°)		23a	TO-3	AL 102	23a	AL 102…103, AUY 22(A), AUY 28
GD 240	Hfo	Ge-P	LF,S P, 30V, 3A, 10W		22a	TO-66	(AD 162)[7]	22a	(AD 162, 2SB474)[7]
GD 241	Hfo	Ge-P	LF,S P, 40V, 3A, 10W		22a	TO-66	(AD 162)[7]	22a	(AD 162, 2SB474)[7]
GD 241(A,B)[Grun.]		Si-N	≈BD 241A,B		17j	TO-220	BD 243 C	17j	›BD 241A,B
GD 242	Hfo	Ge-P	LF,S P, 50V, 3A, 10W		22a	TO-66			-
GD 243	Hfo	Ge-P	LF,S P, 65V, 3A, 10W		22a	TO-66			-
GD 243 [Grundig]		Si-N	≈BD 243		17j	TO-220	BD 243 C	17j	›BD 243
GD 244	Hfo	Ge-P	LF,S P, 75V, 3A, 10W		22a	TO-66			-
GD 340 [Grundig]		Si-P	≈BD 438		14h	TO-126	BD 190	14h	›BD 438
GD 341 [Grundig]		Si-N	≈BD 437		14h	TO-126	BD 189	14h	›BD 437
GD 361 [Grundig]		Si-N	≈BD 433		14h	TO-126	BD 189	14h	›BD 433
GD 362 [Grundig]		Si-P	≈BD 434		14h	TO-126	BD 190	14h	›BD 434
GD 363 [Grundig]		Si-N	≈BD 433		14h	TO-126	BD 189	14h	›BD 433
GD 364 [Grundig]		Si-P	≈BD 434		14h	TO-126	BD 190	14h	›BD 434
GD 384 [Grundig]		Si-N	≈BD 525		13j		(2SC4135)[4]	30j	›BD 525
GD 607	Hfo	Ge-N	LF P, 32V, 1A, 4W(Tc=60°)		22a	TO-66	AD 161	22a	AD 161
GD 608	Hfo	Ge-N	LF P, 25V, 1A, 4W(Tc=60°)		22a	TO-66	AD 161	22a	AD 161
GD 609	Hfo	Ge-N	LF P, 20V, 1A, 4W(Tc=60°)		22a	TO-66	AD 161	22a	AD 161
GD 617	Hfo	Ge-P	LF P, 32V, 1A, 4W(Tc=60°)		22a	TO-66	AD 162	22a	AD 162
GD 618	Hfo	Ge-P	LF P, 25V, 1A, 4W(Tc=60°)		22a	TO-66	AD 162	22a	AD 162
GD 619	Hfo	Ge-P	LF P, 20V, 1A, 4W(Tc=60°)		22a	TO-66	AD 162	22a	AD 162
GE									
GE		Si-P	=2SA1455K-E (SMD-Marking)		35	SOT-23			›2SA1455K
GE		Si-Di	=BAW 79A (SMD-Marking)		39	SOT-89			›BAW 79A
GE		Si-N	=BFR 35AP (SMD-Marking)		35	SOT-23			›BFR 35AP
GE 1001	Gen,Rca	Si-Di	FRr, 50V, 1A, Uf<0,95V(1A), <35ns		31a	SOD-57	BYV 27/200	31a	BYV 26B, EGP 10A, FE 1A
GE 1002	Gen,Rca	Si-Di	=GE 1001: 100V		31a	SOD-57	BYV 27/200	31a	BYV 26B, EGP 10B, FE 1B
GE 1003	Gen,Rca	Si-Di	=GE 1001: 150V		31a	SOD-57	BYV 27/200	31a	BYV 26B, EGP 10C, FE 1C
GE 1004	Gen,Rca	Si-Di	=GE 1001: 200V		31a	SOD-57	BYV 27/200	31a	BYV 26B, EGP 10D, FE 1D
GE 1101	Gen,Rca	Si-Di	FRr, 50V, 2,5A, 0,95V(2A), <35ns		31a	SOD-57	BYV 28/200	31a	BYV 28/50,EGP 30A, FE 3A
GE 1102	Gen,Rca	Si-Di	=GE 1101: 100V		31a	SOD-57	BYV 28/200	31a	BYV 28/100,EGP 30B, FE 3B
GE 1103	Gen,Rca	Si-Di	=GE 1101: 150V		31a	SOD-57	BYV 28/200	31a	BYV 28/150,EGP 30C, FE 3C
GE 1104	Ge,Rca	Si-Di	=GE 1101: 200V		31a	SOD-57	BYV 28/200	31a	BYV 28/200,EGP 30D, FE 3D
GE 1301	Gen,Rca	Si-Di	FRr, 50V, 6A, 0,975V(2A), <35ns		31a	SOD-64			BYV 61, FE 6A
GE 1302	Gen,Rca	Si-Di	=GE1301: 100V		31a	SOD-64			BYV 62, FE 6B
GE 1303	Gen,Rca	Si-Di	=GE1301: 150V		31a	SOD-64			BYV 63, FE 6C
GE 1304	Gen,Rca	Si-Di	=GE1301: 200V		31a	SOD-64			FE 6D
GE 3055 P	Gen	Si-N	LF,S P, 80/80V, 10A, 70W		18j	TO-3P	BD 245 C	18j	BD 245B…F, BD 545B…D, 2SD1187, ++
GE 5060	Gen	Si-N-Darl+Di	S P, 400/350V, 20/25A, 125W, hFE=160>100		23a	TO-3			BUT 13, MJ 10000…01, MJ 10004…05
GE 5061	Gen	Si-N-Darl+Di	=GE 5060: 450/400V		23a	TO-3			BUT 13, MJ 10000…01, MJ 10004…05
GE 5062	Gen	Si-N-Darl+Di	=GE 5060: 500/450V		23a	TO-3			BUT 13, MJ 10001, MJ 10005, MJ 10008…09
GE 6060	Gen	Si-N-Darl+Di	≈GE 5060: integr. Speedup-Diode(E ›B), hFE=160>40		23a	TO-3			MJ 10004…5, MJ 10008…09
GE 6061	Gen	Si-N-Darl+Di	≈GE 5061: integr. Speedup-Diode(E ›B), hFE=160>40		23a	TO-3			MJ 10004…5, MJ 10008…09
GE 6062	Gen	Si-N-Darl+Di	≈GE 5062: integr. Speedup-Diode(E ›B), hFE=160>40		23a	TO-3			MJ 10005, MJ 10008…09
GE 6251	Gen	Si-N-Darl+Di	S P, Speedup-Di., 450/400V, 10/15A, 125W, hFE>60		23a	TO-3			MJ 10006…07, MJ 10013…14
GE 6252	Gen	Si-N-Darl+Di	=GE 6251: 500/450V		23a	TO-3			MJ 10007, MJ 10013…14
GE 6253	Gen	Si-N-Darl+Di	=GE 6251: 550/500V		23a	TO-3			MJ 10013…14
GE 10000…10009	Gen	Si-N-Darl+Di	=MJ 10000…10009		23a	TO-3			›MJ 10000…10009
GE 10015…10016	Gen	Si-N-Darl+Di	=MJ 10015…10016		23a	TO-3			›MJ 10015…10016
GE 10020…10023	Gen	Si-N-Darl+Di	=MJ 10020…10023		23a	TO-3			›MJ 10020…10023
GE 13070P…13071P	Gen	Si-N	=MJ 13070…13071: 100W		18j	TO-3P	BUW 11 A	18j	BUW 11(A), BU 131(A), BUV 82…83, ++
GE 13080P…13081P	Gen	Si-N	=MJ 13080…13081: 110W		18j	TO-3P	BUW 13 A	18j	BUW 12(A), BU 132(A), BUP 22B…C, ++
GE 13080T…13081T	Gen	Si-N	=MJ 13080…13081: 90W		17j	TO-220	BUT 12 A	17j	BUT 12(A), BUT 54(A), BUT 56(A), ++
GE 13100P…13101P	Gen	Si-N	=MJ 13100…13101: 125W		18j	TO-3P			BUX 98(A)P, 2SC3988
GER 4001…4007	Gen	Si-Di	=1N4001…4007		31a	SOD-57	1N4007	31a	›1N4001…4007
GES 92	Gen	Si-N	Uni, 40/40V, 0,4A, 0,625W, 100MHz		7e	TO-92	BC 337	7a	BC 337, BC 635, 2SC3377, 2SC3939, ++

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
GES 93	Gen	Si-P	Uni, 40/40V, 0,4A, 0,625W, 100MHz		7e	TO-92	BC 327	7a	BC 327, BC 636, 2SB910, 2SD1116, ++
GES 97	Gen	Si-N	Uni, 60/40V, 0,1A, 0,36W, 100MHz		7e	TO-92	BC 546	7a	BC 174, BC 546, 2SC2240, 2SC2459, ++
GES 98	Gen	Si-N	Uni, 80/60V, 0,1A, 0,36W, 100MHz		7e	TO-92	BC 546	7a	BC 546, 2SC2240, 2SC2459, 2SC3378, ++
GES 929…930	Gen	Si-N	=2N929…930: 0,36W		7e	TO-92	›2N929…930		›2N929…930
GES 2218…2219(A)	Gen	Si-N	=2N2218…2219(A): 0,625W		7e	TO-92	›2N2218…19		›2N2218…2219(A)
GES 2221…2222(A)	Gen	Si-N	=2N2221…2222(A): 0,36W		7e	TO-92	›2N2221…22		›2N2221…2222(A)
GES 2483	Gen	Si-N	=2N2483: 0,36W		7e	TO-92	›2N2483		›2N2483
GES 2646	Gen	UJT-P	=2N2646		7b	TO-29			›2N2646
GES 2647	Gen	UJT-P	=2N2647		7b	TO-92			›2N2647
GES 2904…2905(A)	Gen	Si-P	=2N2904…2905(A): 0,6W		7e	TO-92	›2N2904…05		›2N2904…2905(A)
GES 2906…2907(A)	Gen	Si-P	=2N2906…2907(A): 0,36W		7e	TO-92	›2N2906…07		›2N2906…2907(A)
GES 3053	Gen	Si-N	=2N3053: 0,625W		7e	TO-92	›BC 639	7c	BC 337A, BC 637, BC 639, 2SD1616, ++
GES 3414…3417	Gen	Si-N	=2N3414…3417: 0,625W		7e	TO-92	›2N3414…17		›2N3414…3417
GES 3565…3569	Gen	Si-N	=2N3565…3569: 0,625W		7e	TO-92	›2N3565…69		›2N3565…3569
GES 4121…4122	Gen	Si-P	=2N4121…4122: 0,2W		7e	TO-92	›2N4121…22		›2N4121…4122
GES 4248	Gen	Si-P	=2N4248: 0,4W		7e	TO-92			›2N4248
GES 4891…4894	Gen	UJT-P	=2N4891…4894		7b	TO-92			›2N4891…4894
GES 5305…5308(A)	Gen	Si-N	=2N5305…5308(A): 0,9W		7e	TO-92			›2N5305…5308(A)
GES 5368…5375	Gen	Si-N/P	=2N5368…5375: 0,36W		7e	TO-92			›2N5368…5375
GES 5401	Gen	Si-P	=2N5401		7e	TO-92			›2N5401
GES 5447…5451	Gen	Si-N/P	=2N5447…5451: 0,36W		7e	TO-92	›2N5447…51		›2N5447…5451
GES 5551	Gen	Si-N	=2N5551		7e	TO-92	›2N5551		›2N5551
GES 5810…5823	Gen	Si-N/P	=2N5810…5823: 0,5W		7c	TO-92			›2N5810…5823
GES 5824…5828(A)	Gen	Si-N	=2N5824…5828(A): 0,36W		7c	TO-92			›2N5824…5828(A)
GES 6000…6007	Gen	Si-N/P	=2N6000…6007: 0,4W		7e	TO-92			›2N6000…6007
GES 6010…6017	Gen	Si-N/P	=2N6010…6017: 0,5W		7e	TO-92			›2N6010…6017
GES 6027	Gen	PUT	=2N6027		7n	TO-92			›2N6027
GES 6028	Gen	PUT	=2N6028		7n	TO-92			›2N6028
GES 6218…6221	Gen	Si-N	=2N6218…6221: 0,5W		7e	TO-92			›2N6218…6221
GES 6222	Gen	Si-N	=2N6222: 0,36W		7e	TO-92			›2N6222
GES 6224	Gen	Si-N	=2N6224: 0,36W		7e	TO-92			›2N6224
GES 6426…6427	Gen	Si-N	=2N6426…6427: 0,625W		7e	TO-92			›2N6426…6427
GES 6560…6563	Gen	Si-N/P	=2N6560…6563: 0,625W		7e	TO-92			›2N6560…6563
GET 706	Gen	Si-N	=2N706: 0,36W		7a	SOT-30			›2N706
GET 708	Gen	Si-N	=2N708: 0,36W		7a	SOT-30			›2N708
GET 914	Gen	Si-N	=2N914: 0,36W		7a	SOT-30			›2N914
GET 929	Gen	Si-N	=2N929: 0,36W		7a	SOT-30			›2N929
GET 930	Gen	Si-N	=2N930: 0,36W		7a	SOT-30			›2N930
GET 2221(A)	Gen	Si-N	=2N2221(A): 0,36W		7a	SOT-30			›2N2221(A)
GET 2222(A)	Gen	Si-N	=2N2222(A): 0,36W		7a	SOT-30			›2N2222(A)
GET 2369	Gen	Si-N	=2N2369: 0,36W		7a	SOT-30			›2N2369
GET 2483	Gen	Si-N	=2N2483: 0,36W		7a	SOT-30			›2N2483
GET 2484	Gen	Si-N	=2N2484: 0,36W		7a	SOT-30			›2N2484
GET 2904….2907	Gen	Si-P	=2N2904…2907: 0,36W		7a	SOT-30			›2N2904…2907
GET 3013….3014	Gen	Si-N	=2N3013…3014: 0,36W		7a	SOT-30			›2N3013…3014
GET 3562….3563	Gen	Si-N	=2N3562…3563: 0,25W		7a	SOT-30			›2N3562…3563
GET 3638(A)	Gen	Si-P	=2N3638(A): 0,25W		7a	SOT-30			›2N3638(A)
GET 3646	Gen	Si-N	=2N3646: 0,36W		7a	SOT-30			›2N3646
GET 3903….3906	Gen	Si-N/P	=2N3903…3906: 0,31W		7a	SOT-30			›2N3903…3906
GET 4870	Gen	UJT-P	=2N4870:		7b	SOT-30			›2N4870
GET 4871	Gen	UJT-P	=2N4871:		7b	SOT-30			›2N4871
GET 5305….5308(A)	Gen	Si-N	=2N5305…5308(A): 0,4W		7a	SOT-30			›2N5305…5308(A)
GF									
GF		Si-Di	=BAW 79B (SMD-Marking)		39	SOT-89			›BAW 79B
GF		Si-N	=BFN 22 (SMD-Marking)		35	SOT-23			›BFN 22
GF		Si-N	=BFR 92P (SMD-Marking)		35	SOT-23			›BFR 92P
GF 100	Hfo	Ge-P	AM IF		2a		AF 239 S	5g	AF 127, AF 200, AF 139, AF 239(S)
GF 105	Hfo	Ge-P	AM Inp,Mx,Os		2a		AF 239 S	5g	AF 126, AF 200, AF 139, AF 239(S)
GF 108	Hfo	Ge-P	AM Inp,Mx,Os		2a		AF 239 S	5g	AF 126, AF 200, AF 139, AF 239(S)
GF 120	Hfo	Ge-P	AM Inp,Mx,IF, 30MHz		5k		AF 239 S	5g	AF 126, AF 200, AF 139, AF 239(S)
GF 121	Hfo	Ge-P	AM Inp,Mx, 50MHz		5k		AF 239 S	5g	AF 126, AF 200, AF 139, AF 239(S)
GF 122	Hfo	Ge-P	AM Inp,Mx,Os, 50MHz		5k		AF 239 S	5g	AF 126, AF 200, AF 139, AF 239(S)
GF 125	Hfo	Ge-P	FM IF, 60MHz		5k		AF 239 S	5g	AF 125…126, AF 200, AF 139, AF 239(S)
GF 126	Hfo	Ge-P	AM IF		5k		AF 239 S	5g	AF 125…126, AF 200, AF 139, AF 239(S)
GF 127	Hfo	Ge-P	AM Inp, 75MHz		5k		AF 239 S	5g	AF 125, AF 200, AF 139, AF 239(S)
GF 128	Hfo	Ge-P	AM/FM, 100MHz		5k		AF 239 S	5g	AF 124…125, AF 200, AF 139, AF 239(S)
GF 129	Hfo	Ge-P	AM Inp,Mx,Os, 75MHz		5k		AF 239 S	5g	AF 124…125, AF 200, AF 139, AF 239(S)
GF 130	Hfo	Ge-P	FM IF		5k		AF 239 S	5g	AF 125…126, AF 200, AF 139, AF 239(S)
GF 131	Hfo	Ge-P	FM Mx, 85MHz		5k		AF 239 S	5g	AF 124…125, AF 200, AF 139, AF 239(S)
GF 132	Hfo	Ge-P	FM Inp 85MHz		5k		AF 239 S	5g	AF 124, AF 200, AF 139, AF 239(S)
GF 134	Hfo	Ge-P	VHF, 180MHz		5k		AF 239 S	5g	AF 106, AF 109R, AF 239(S), AF 306
GF 135	Hfo	Ge-P	VHF, 150MHz		5g		AF 239 S	5g	AF 106, AF 109R, AF 239(S), AF 306
GF 136	Hfo	Ge-P	VHF, 150MHz		5g		AF 239 S	5g	AF 106, AF 109R, AF 239(S), AF 306
GF 137	Hfo	Ge-P	VHF, 180MHz		5g		AF 239 S	5g	AF 106, AF 109R, AF 239(S), AF 306
GF 138	Hfo	Ge-P	VHF, 180MHz		5g		AF 239 S	5g	AF 106, AF 109R, AF 239(S), AF 306
GF 139	Hfo	Ge-P	AM Inp,Mx, FM IF		5k		AF 239 S	5g	AF 106, AF 109R, AF 200, AF 239(S)
GF 140	Hfo	Ge-P	VHF Inp,Mx,Os, 300MHz		2a		AF 239 S	5g	AF 139, AF 239(S)
GF 141	Hfo	Ge-P	VHF Inp,Mx,Os, 300MHz		2a		AF 239 S	5g	AF 139, AF 239(S)
GF 142	Hfo	Ge-P	VHF Inp,Mx,Os, 300MHz		2a		AF 239 S	5g	AF 139, AF 239(S)
GF 143	Hfo	Ge-P	VHF Inp,Mx,Os, 300MHz		2a		AF 239 S	5g	AF 139, AF 239(S)
GF 145	Hfo	Ge-P	UHF Inp,Mx,Os, >250MHz		5g		AF 239 S	5g	AF 139, AF 239(S)
GF 146	Hfo	Ge-P	UHF Inp,Mx,Os, >600MHz		5g		AF 239 S	5g	AF 139, AF 239(S)
GF 147	Hfo	Ge-P	UHF, >600MHz		5g		AF 239 S	5g	AF 139, AF 239(S)
GF 180	Hfo	Ge-P	HF		5k		AF 239 S	5g	AF 106, AF 109R, AF 200, AF 306
GF 181	Hfo	Ge-P	HF, 100MHz		5k		AF 239 S	5g	AF 106, AF 109R, AF 200, AF 306
GF 268		N-FET	=BF 245		7f		BF 245	7f	›BF 245
GF 501	Hfo	Ge-P	HF, 300MHz		2a		AF 239 S	5g	AF 139, AF 239(S)
GF 502	Hfo	Ge-P	HF, 300MHz		2a		AF 239 S	5g	AF 139, AF 239(S)
GF 503	Hfo	Ge-P	HF, 300MHz		2a		AF 239 S	5g	AF 139, AF 239(S)
GF 504	Hfo	Ge-P	HF, 300MHz		2a		AF 239 S	5g	AF 139, AF 239(S)
GF 505	Hfo	Ge-P	HF, 170MHz		5g		AF 239 S	5g	AF 106, AF 109R, AF 239(S), AF 306
GF 506	Hfo	Ge-P	HF, 170MHz		5g		AF 239 S	5g	AF 106, AF 109R, AF 239(S), AF 306

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
GF 507	Hfo	Ge-P	HF, 250MHz		5g		AF 239 S	5g	AF 106, AF 109R, AF 239(S), AF 306
GF 515	Hfo	Ge-P	HF, 60MHz		5k		AF 239 S	5g	AF 124…127, AF 200, AF 139, AF 239(S)
GF 516	Hfo	Ge-P	HF, 60MHz		5k		AF 239 S	5g	AF 124…127, AF 200, AF 139, AF 239(S)
GF 517	Hfo	Ge-P	HF, 50MHz		5k		AF 239 S	5g	AF 124…127, AF 200, AF 139, AF 239(S)
GF 522		N-FET	=BF 245		7f		BF 245	7f	›BF 245
GF 757		Si-N	=BF 757				BF 759	13h	›BF 757
GF 758		Si-N	=BF 758				BF 759	13h	›BF 758
GF 759		Si-N	=BF 759				BF 759	13h	›BF 759
GF 760		Si-P	=BF 760				BF 762	13h	›BF 760
GF 761		Si-P	=BF 761				BF 762	13h	›BF 761
GF 762		Si-P	=BF 762				BF 762	13h	›BF 762
GFT 20 A6	Hit	GTO-Thy	600V, 10A=(Tc=60°C), Igt/Ih=100/200mA, tgq=7µs		22a	TO-66			-
GFT 20 B12	Hit	GTO-Thy	=GFT 20A6: 1200V, 7A=(Tc=60°C), tgq=6µs		22a	TO-66			-
GFT 50 A6	Hit	GTO-Thy	600V, 20A=(Tc=60°C), Igt/Ih=300/600mA, tgq=7µs		23a	TO-3			-
GFT 50 B12	Hit	GTO-Thy	=GFT 50A6: 1200V, 18A=(Tc=60°C), tgq=6µs		23a	TO-3			-
GG….GL									
GG		Si-P	=2SA1369-G (SMD-Marking)		39	SOT-89			›2SA1369
GG		Si-Di	=BAW 79C (SMD-Marking)		39	SOT-89			›BAW 79C
GG		Si-P	=BF 579R (SMD-Marking)		35	SOT-23			›BF 579R
GG		Si-N	=BFR 93P (SMD-Marking)		35	SOT-23			›BFR 93P
GH		Si-P	=2SA1369-H (SMD-Marking)		39	SOT-89			›2SA1369
GH		Si-Di	=BAW 79D (SMD-Marking)		39	SOT-89			›BAW 79D
GH 1 E,F	Sak	Si-Di	Rr, 1300…1500V, 1A, Uf<1,05V(1A), <6µs E=1300V, F=1500V		31a	SOD-57	BY 228	31a	BY 228, BY 448, DM 513, EM 516, GP 10W
GH 3 E,F	Sak	Si-Di	Rr, 1300…1500V, 1,5A, Uf<1,2V(4A), <10µs E=1300V, F=1500V		31a	SOD-64	BY 228	31a	BY 228, BY 448, BY 350/…
GI 1-1200	Gie	Si-Di	Rr, 1200V, 1A, Uf<1,1V(1A), <1µs		31a	SOD-57	BY 133	31a	BY133, BY350/1300, CH 3E, EM 513, GP 10Q
GI 1-1400		Si-Di	=GI 1-1200: 1400V		31a	SOD-57	BY 228	31a	BY 350/1500, CH 3E, EM 516, GP 10Y
GI 1-1600		Si-Di	=GI 1-1200: 1600V		31a	SOD-57			DM 513, DM 516, EM 516, GP 10Y
GI 250-1	Gie	Si-Di	kV-Rr, 1000V, 0,25A, Uf<3,5V(0,25A), 2µs		31a	DO-41	BA 159	31a	BA 159, BY 203/12, BY 204/10, MR 250-1
GI 250-2		Si-Di	=GI 250-1: 2000V		31a	DO-41	BY 203/20	31a	BY 203/20, GP 02-20, MR 250-2
GI 250-3		Si-Di	=GI 250-1: 3000V		31a	DO-41			GP 02-30, MR 250-3
GI 250-4		Si-Di	=GI 250-1: 4000V		31a	DO-41			GP 02-40, MR 250-4
GI 500	Gie	Si-Di	Rr, 50V, 3A, Uf<1,1V(9,4A), 2,5µs		31a	DO-27A	BY 255	31a	BY 251, G3A, GP 30A, MR 500, 1N5400, ++
GI 501	Gie	Si-Di	=GI 500: 100V		31a	DO-27A	BY 255	31a	BY 251, G3B, GP 30B, MR 501, 1N5401, ++
GI 502	Gie	Si-Di	=GI 500: 200V		31a	DO-27A	BY 255	31a	BY 251, G3D, GP 30D, MR 502, 1N5402, ++
GI 504	Gie	Si-Di	=GI 500: 400V		31a	DO-27A	BY 255	31a	BY 252, G3G, GP 30G, MR 504, 1N5404, ++
GI 506	Gie	Si-Di	=GI 500: 600V		31a	DO-27A	BY 255	31a	BY 253, G3J, GP 30J, MR 506, 1N5406, ++
GI 508	Gie	Si-Di	=GI 500: 800V		31a	DO-27A	BY 255	31a	BY 254, G3K, GP 30K, MR 508, 1N5407, ++
GI 510	Gie	Si-Di	=GI 500: 1000V		31a	DO-27A	BY 255	31a	BY 255, G3M, GP 30M, MR 510, 1N5408, ++
GI 750	Gie	Si-Di	Rr, 50V, 6A, Uf<0,9V(6A)		31a	(9x9mmØ)	BY 500/800	31a	BY 214/50, BY 500/100, MR 750
GI 751	Gie	Si-Di	=MR 750: 100V		31a	(9x9mmØ)	BY 500/800	31a	BY 214/100, BY 500/100, MR 751
GI 752	Gie	Si-Di	=MR 750: 200V		31a	(9x9mmØ)	BY 500/800	31a	BY 214/200, BY 500/200, MR 752
GI 754	Gie	Si-Di	=MR 750: 400V		31a	(9x9mmØ)	BY 500/800	31a	BY 214/400, BY 500/400, MR 754
GI 756	Gie	Si-Di	=MR 750: 600V		31a	(9x9mmØ)	BY 500/800	31a	BY 214/600, BY 500/600, MR 756
GI 758	Gie	Si-Di	=MR 750: 800V		31a	(9x9mmØ)	BY 500/800	31a	BY 214/800, BY 500/800, MR 758
GI 810	Gie	Si-Di	FRr, 50V, 1A, Uf<1,1V(1A), <750ns		31a	DO-15	BYD 33 M	31a	BYD 33D, BYT 52A, RGP 10A, MR 810, ++
GI 811	Gie	Si-Di	=GI 810: 100V		31a	DO-15	BYD 33 M	31a	BYD 33D, BYT 52B, RGP 10B, MR 811, ++
GI 812	Gie	Si-Di	=GI 810: 200V		31a	DO-15	BYD 33 M	31a	BYD 33D, BYT 52D, RGP 10D, MR 812, ++
GI 814	Gie	Si-Di	=GI 810: 400V		31a	DO-15	BYD 33 M	31a	BYD 33G, BYT 52G, RGP 10G, MR 814, ++
GI 816	Gie	Si-Di	=GI 810: 600V		31a	DO-15	BYD 33 M	31a	BYD 33J, BYT 52J, RGP 10J, MR 816, ++
GI 817	Gie	Si-Di	=GI 810: 800V		31a	DO-15	BYD 33 M	31a	BYD 33K, BYT 52K, RGP 10K, MR 817, ++
GI 818	Gie	Si-Di	=GI 810: 1000V		31a	DO-15	BYD 33 M	31a	BYD 33M, BYT 52M, RGP 10M, MR 818, ++
GI 820	Gie	Si-Di	FFr, TV, 50V, 5A, Uf<1V(5A), <200ns		31a	(9x9mmØ)	BY 500/800	31a	BY 500/100, EGP 50A, MR 820
GI 821	Gie	Si-Di	=GI 820: 100V		31a	(9x9mmØ)	BY 500/800	31a	BY 500/100, EGP 50B, MR 821
GI 822	Gie	Si-Di	=GI 820: 200V		31a	(9x9mmØ)	BY 500/800	31a	BY 500/200, EGP 50D, MR 822
GI 824	Gie	Si-Di	=GI 820: 400V		31a	(9x9mmØ)	BY 500/800	31a	BY 500/400, EGP 50G, MR 824[4]
GI 826	Gie	Si-Di	=GI 820: 600V		31a	(9x9mmØ)	BY 500/800	31a	BY 500/600, MR 826, (BY 229/600,++)[4]
GI 850	Gie	Si-Di	FRr, 50V, 3A, Uf=1,25V(3A), <200ns		31a	DO-27A	BYW 95 C	31a	BYW 95A, BYW 72, RGP 30A, MR 850
GI 851	Gie	Si-Di	=GI 850: 100V		31a	DO-27A	BYW 95 C	31a	BYW 95A, BYW 72, RGP 30B, MR 851
GI 852	Gie	Si-Di	=GI 850: 200V		31a	DO-27A	BYW 95 C	31a	BYW 95A, BYW 72, RGP 30D, MR 852
GI 854	Gie	Si-Di	=GI 850: 400V		31a	DO-27A	BYW 95 C	31a	BYW 95B, BYW 74, RGP 30G, MR 854
GI 856	Gie	Si-Di	=GI 850: 600V		31a	DO-27A	BYW 95 C	31a	BYW 95C, BYW 76, RGP 30J, MR 856
GI 910	Gie	Si-Di	FRr, 50V, 3A, Uf=1,25V(3A), <750ns		31a	DO-27A	BYW 95 C	31a	BYW 95A, BYW 72, RGP 30A, MR 850
GI 911	Gie	Si-Di	=GI 910: 100V		31a	DO-27A	BYW 95 C	31a	BYW 95A, BYW 72, RGP 30B, MR 851
GI 912	Gie	Si-Di	=GI 910: 200V		31a	DO-27	BYW 95 C	31a	BYW 95A, BYW 72, RGP 30D, MR 852
GI 914	Gie	Si-Di	=GI 910: 400V		31a	DO-27A	BYW 95 C	31a	BYW 95B, BYW 74, RGP 30G, MR 854
GI 916	Gie	Si-Di	=GI 910: 600V		31a	DO-27A	BYW 95 C	31a	BYW 95C, BYW 76, RGP 30J, MR 856
GI 917	Gie	Si-Di	=GI 910: 800V		31a	DO-27A	BYW 96 E	31a	BY 399, BYW 96D, BYT 77, RGP 30K
GI 1001	Gie	Si-Di	FRr, 50V, 1A, Uf<0,975V(1A), <25ns		31a	SOD-57	BYV 27/200	31a	BYV 26B, EGP 10A, FE 1A
GI 1002	Gie	Si-Di	=GI 1001: 100V		31a	SOD-57	BYV 27/200	31a	BYV 26B, EGP 10B, FE 1B
GI 1003	Gie	Si-Di	=GI 1001: 150V		31a	SOD-57	BYV 27/200	31a	BYV 26B, EGP 10C, FE 1C
GI 1004	Gie	Si-Di	=GI 1001: 200V, <40ns		31a	SOD-57	BYV 27/200	31a	BYV 26B, EGP 10D, FE 1D
GI 1101	Gie	Si-Di	FRr, 50V, 2,4A, 0,975V(2A), <25ns		31a	SOD-57	BYV 28/200	31a	BYV 28/50, EGP 30A, FE 3A
GI 1102	Gie	Si-Di	FRr, 100V, 2,4A, Uf<0,975V(2A), <25ns		31a	SOD-57	BYV 28/200	31a	BYV 28/100, EGP 30B, FE 3B
GI 1103	Gie	Si-Di	FRr, 150V, 2,4A, Uf<0,975V(2A), <25ns		31a	SOD-57	BYV 28/200	31a	BYV 28/150, EGP 30C, FE 3C
GI 1104	Gie	Si-Di	FRr, 200V, 2A, Uf<1,25V(2A), <50ns		31a	SOD-57	BYV 28/200	31a	BYV 28/200, EGP 30D, FE 3D
GI 1301	Gie	Si-Di	FRr, 50V, 6A, 0,925V(6A), <30ns		31a	SOD-64			BYV 61, FE 6A, (BYT 08/200, RGP 80A,++)[4]
GI 1302	Gie	Si-Di	FRr, 100V, 6A, Uf<0,925V(6A), <30ns		31a	SOD-64			BYV 62, FE 6B, (BYT 08/200, RGP 80B,++)[4]
GI 1303	Gie	Si-Di	FRr, 150V, 6A, Uf<0,925V(6A), <30ns		31a	SOD-64			BYV 63, FE 6C, (BYT 08/200, RGP 80C,++)[4]
GI 1304	Gie	Si-Di	FRr, 200V, 5A, Uf<1,25V(6A), <50ns		31a	SOD-64			FE 6D, (BYT 08/200, RGP 80D,++)[4]
GI 1401	Gie	Si-Di	P FRr, 50V, 8A(Tc=125°), Uf<0,975V(8A), <35ns		17k	TO-220			BYP 51-50, BYW 29/50, BYW 80/50, FE 8A
GI 1402	Gie	Si-Di	=GI 1401: 100A		17k	TO-220			BYP 51-100, BYW 29/100, BYW80/100, FE 8B
GI 1403	Gie	Si-Di	=GI 1401: 150A		17k	TO-220			BYP 51-150, BYW 29/150, BYW80/150, FE 8C
GI 1404	Gie	Si-Di	=GI 1401: 200A		17k	TO-220			BYP 51-200, BYW 29/200, BYW80/200, FE 8D
GI 1401R…1404R		Si-Di	=GI 1401…1404:		17m	TO-220			-
GI 2401	Gie	Si-Di	Dual, FRr, 50V, 16A(Tc=125°), Uf<0,975V(8A), <35ns		17e	TO-220			BYV 32/50, BYV 79/50, FE 16A, MUR 1605CT
GI 2402	Gie	Si-Di	=GI 2401: 100V		17e	TO-220			BYV32/100, BYV79/100, FE 16B, MUR 1610CT
GI 2403	Gie	Si-Di	=GI 2401: 150V		17e	TO-220			BYV32/150, BYV79/150, FE 16C, MUR 1615CT
GI 2404	Gie	Si-Di	=GI 2401: 200V		17e	TO-220			BYV32/200, BYV79/200, FE 16D, MUR 1620CT
GI 2401R…2404R		Si-Di	=GI 2401…2404:		17h	TO-220			BYV 32N/…, FE 16…N
GI 5823	Gie	Si-Di	Schottky, 20V, 5A, Uf<0,45V(5A), (=1N5823)		31a	DO-27A			SB 520, =1N5823

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
GI 5824	Gie	Si-Di	=GI 5823: 30V, (=1N5824)		31a	DO-27A			SB 530, =1N5824
GI 5825	Gie	Si-Di	=GI 5823: 40V, (=1N5825)		31a	DO-27A			SB 540, 1N5825
GIA		Si-N-Darl	=2SC3957-GIA (SMD-Marking)		44	SOT-143			›2SC3957
GIB		Si-N-Darl	=2SC3957-GIB (SMD-Marking)		44	SOT-143			›2SC3957
GJ 2		N-FET	=2SK968-2 (SMD-Marking)		35	SOT-23			›2SK968
GJ 3		N-FET	=2SK968-3 (SMD-Marking)		35	SOT-23			›2SK968
GJ 4		N-FET	=2SK968-4 (SMD-Marking)		35	SOT-23			›2SK968
GJ 5		N-FET	=2SK968-5 (SMD-Marking)		35	SOT-23			›2SK968
GK		Si-N	=2SD1615-GK (SMD-Marking)		39	SOT-89			›2SD1615
GK		Z-Di	=SM 6T 150 (SMD-Marking)		71a(6x4mm)	SOD-6			›SM 6T....
GL		Si-P	=2SA1496 (SMD-Marking)		35	SOT-23			›2SA1496
GL		Si-N	=2SD1615-GL (SMD-Marking)		39	SOT-89			›2SD1615
GL		Z-Di	=SM 6T 150A (SMD-Marking)		71a(6x4mm)	SOD-6			›SM 6T....
GL 27 A...M	Gie	Si-Di	=BYM 30/....						›BYM 30/...
GL 34 A...M	Gie	Si-Di	=BYM 05/....						›BYM 05/...
GL 41 A...M	Gie	Si-Di	=BYM 10/....						›BYM 10/...
GL 317		Z-IC	+1,7...37V, 0,01...1,5A, 20W, -20...+100°		17l	TO-220	LM 317 T	17l	... 117..., ... 217..., ... 317...
GL 7805		Z-IC	=LM 7805		17b	TO-220	›LM 7805		›LM 7805
GL 7812		Z-IC	=LM 7812		17b	TO-220	›LM 7812		›LM 7812
GLC 555		LIN-IC	=NE 555CH,CM: SMD		8-MDIP				›NE 555...
GLC 556		LIN-IC	=NE 556CH,CM: SMD		8-MDIP				›NE 556...
GLC 4558		OP-IC	SMD, Dual, Serie 158, ±18V, 0...+70°		8-MDIP				... 258..., ... 358..., ... 1458..., ... 4558...
GLC 4559		OP-IC	=GLC 4558: lo-noise		8-MDIP				... 258..., ... 358..., ... 1458..., ... 4559...
GLL 4735...4763	Gie	Si-Di	=1N4735...4763: SMD		72a(5mm)	(MELF)			-
GLT 12	Tho	Z-Di	=BZW 25/12:		32	DO-4			›BZW 25/12
GLT 24	Tho	Z-Di	=BZW 25/24:		32	DO-4			›BZW 25/24
GLT 47	Tho	Z-Di	=BZW 25/47:		32	DO-4			›BZW 25/47
GLT 120	Tho	Z-Di	=BZW 25/120:		32	DO-4			›BZW 25/120
GM....GO									
GM		Si-N	=2SD1615-GM (SMD-Marking)		39	SOT-89			›2SD1615
GM-1 A....Z	Sak	Si-Di	Rr, Uni, 200...1000V, 1,3A, Uf<1,2V(1A) A=600V, B=800V, C=1000V, Z=200V		31a	SOD-57	BY 255	31a	BY 226...227, BY 251...255, 1N5391...99, ++
GM 3 A....Z	Sak	Si-Di	Rr, Uni, 100...1000V, 2,7A, Uf<1,2V(3A) A=600V, B=800V, C=1000V, Y=100V, Z=200V		31a	SOD-64	BY 255	31a	BY 251...255, GP 30B...M, 1N5401...08, ++
GM 30 A....M	Gie	Si-Di	Dual, 50...1000V, 30A(Tc=100°), Uf<1,1V(15A), 5µs A=50, B=100, D=200, G=400, J=600, K=800, M=1000V		23f	TO-3			BYV 72/..., BYW 99P/..., RP 30AP...MP
GM 30 AD....MD		Si-Di	=GM 30A...M:		23s	TO-3			-
GM 30 AN....MN		Si-Di	=GM 30A...M:		23n	TO-3			-
GM 0290(A)	Tix	Ge-P	UHF Inp,Mx,Os, 750MHz		5g		AF 239 S	5g	AF 139, AF 239(S)
GM 0378(A)	Tix	Ge-P	VHF, 600MHz		5g		AF 239 S	5g	AF 139, AF 239(S)
GM 0656(A)	Tix	Ge-P	UHF Os		5g		AF 239 S	5g	AF 139, AF 239(S)
GM 0760	Tix	Ge-P	VHF Inp		5g		AF 239 S	5g	AF 106, AF 109R, AF 239(S), AF 306
GM 0761	Tix	Ge-P	VHF Mx		5g		AF 239 S	5g	AF 106, AF 109R, AF 239(S), AF 306
GM 62093		CMOS-IC	›KS 093						KS 093, M 093, MT 8812
GMA 01	Say	Si-Di	SS, 55/60V, 0,12/0,36V, Uf<0,65V(1,5mA), <4ns		31a	DO-35	1N4148	31a	BAW 62, BAW 76, BAX 95, 1N4148...49, ++
GMA 01 U	Say	Si-Di	=GMA 01: 100/105V		31a	DO-35	(1N4148)	31a	BAV 14
GMB 01(U)	Say	Si-Di	=GMA 01: 100/105V		31a	DO-34	›GMA 01(U)		›GMA 01(U)
GMJ 2955		Si-P	=BD 208		14h	TO-126	›BD 208		›BD 208
GMJ 3055		Si-N	=BD 207		14h	TO-126	›BD 207		›BD 207
GN 1 A3Q	Nec	Si-P+R	=AN 1A3Q: SMD	{GA1A3Q	35a(2mm)	SOT-323			DTA 113ZU
GN 1 A4M	Nec	Si-P+R	=AN 1A4M: SMD	{GA1A4M	35a(2mm)	SOT-323			DTA 114EU, 2SA1678
GN 1 A4P	Nec	Si-P+R	=AN 1A4P: SMD	{GA1A4P	35a(2mm)	SOT-323			DTA 114YU
GN 1 A4Z	Nec	Si-P+R	=AN 1A4Z: SMD	{GA1A4Z	35a(2mm)	SOT-323			DTA 114TU
GN 1 F4M	Nec	Si-P+R	=AN 1F4M: SMD	{GA1F4M	35a(2mm)	SOT-323			DTA 124EU, 2SA1677
GN 1 F4N	Nec	Si-P+R	=AN 1F4N: SMD	{GA1F4N	35a(2mm)	SOT-323			DTA 124XU
GN 1 F4Z	Nec	Si-P+R	=AN 1F4Z: SMD	{GA1F4Z	35a(2mm)	SOT-323			DTA 124TU
GN 1 L3M	Nec	Si-P+R	=AN 1L3M: SMD	{GA1L3M	35a(2mm)	SOT-323			DTA 143EU
GN 1 L3N	Nec	Si-P+R	=AN 1L3N: SMD	{GA1L3N	35a(2mm)	SOT-323			DTA 143XU
GN 1 L3Z	Nec	Si-P+R	=AN 1L3Z: SMD	{GA1L3Z	35a(2mm)	SOT-323			DTA 143TU
GN 1 L4L	Nec	Si-P+R	=AN 1L4L: SMD	{GA1L4L	35a(2mm)	SOT-323			DTA 143WU
GN 1 L4M	Nec	Si-P+R	=AN 1L4M: SMD	{GA1L4M	35a(2mm)	SOT-323			DTA 144EU, 2SA1676
GN 1 L4Z	Nec	Si-P+R	=AN 1L4Z: SMD	{GA1L4Z	35a(2mm)	SOT-323			DTA 144TU
GN 1010...8062	Mat	GaAs-FET	MMIC, UHF MES-FET Arrays						-
GO		Si-P	=2SA2883-O (SMD-Marking)		39	SOT-89			›2SA2883
GO		Si-N	=2SC2996-O (SMD-Marking)		35	SOT-23			›2SC2996
GO		Si-N	=KTC4375-O (SMD-Marking)		39	SOT-89			›KTC 4375
GP....GR									
GP		Si-N	=2SD1615A-GP (SMD-Marking)		39	SOT-89			›2SD1615A
GP 02-20....-40	Gie	Si-Di	kV-Rr, 2...4kV, 0,25A, Uf<3V(1A), 2µs		31a	DO-41			MR 250-2...-5, 1N1732A...1734A
GP 08 A....J	Gie	Si-Di	Rr, 50...600V, 0,8A, Uf<1,3V(0,8A), 1µs		31a	DO-41	1N4007	31a	BY 126...127, BY 133...135, 1N4001...07, ++
GP 10 A....M	Gie	Si-Di	Rr, 50...1000V, 1A, Uf<1,1V(1A), 2µs A=50, B=100, D=200, G=400, J=600, K=800, M=1000V		31a	DO-41	1N4007	31a	BY 126...127, BY 133...135, 1N4001...07, ++
GP 10 N...Y		Si-Di	=GP 10A...M: 1100...1600V, Uf<1,3V(1A) N=1100, Q=1200, T=1300, V=1400, W=1500, Y=1600V		31a	DO-41	BY 228	31a	BY 350/1500, GH 3F, DM 513, EM 516, ++
GP 15 A....M	Gie	Si-Di	Rr, 50...1000V, 1,5A, Uf<1,1V(1,5A), 2µs A=50, B=100, D=200, G=400, J=600, K=800, M=1000V		31a	DO-15	BYD 33 M	31a	BY 226...227, BY 251...255, 1N5391...99, ++
GP 20 A....M	Gie	Si-Di	Rr, 50...1000V, 2A, Uf<1,2V(2A), 2,5µs		31a	DO-27	BY 255	31a	BY 251...255, MR 500...510, 1N5400...08, ++
GP 30 A....M	Gie	Si-Di	Rr, 50...1000V, 3A, Uf<1,2V(3A), 3µs		31a	DO-27A	BY 255	31a	BY 251...255, MR 500...510, 1N5400...08, ++
GP 80 A....M	Gie	Si-Di	P Rr, 50...1000V, 8A(Tc=100°), Uf<1V(8A), 5µs		17k	TO-220	BY 359/1500	17k	BY 239/..., BY 359/..., RGP 80...
GP 140		Si-N-Darl	=BDW 83C		18j	TO-3P	BDW 83 C	18j	›BDW 83C
GP 145		Si-P-Darl	=BDW 84C		18j	TO-3P	BDW 84 C	18j	›BDW 84C
GPP 10 A....M	Sym	Si-Di	=GP 10A...M		31a	DO-41	›GP 10A...M		›GP 10A...M
GPP 15 A....M	Sym	Si-Di	=GP 15A...M		31a	DO-15	›GP 15A...M		›GP 15A...M
GPP 20 A....M	Sym	Si-Di	=GP 20A...M		31a	DO-15	›GP 20A...M		›GP 20A...M
GPP 30 A....M	Sym	Si-Di	=GP 30A...M		31a	DO-27A	›GP 30A...M		›GP 30A...M
GPP 60 A....M	Sym	Si-Di	Rr, 50...1000V, 6A, Uf<1,1V(6A) A=50, B=100, D=200, G=400, J=600, K=800, M=1000V		31a	(9x9mmØ)			BY 214/..., MR 750...760
GPS-....		Si-N/P	=MPS-....				›MPS-....		›MPS-....
GPU 2243	Itt	NMOS-IC	CTV, Digital SECAM Chroma Processor		40-DIP				-
GQ		Si-N	=2SD1615A-GQ (SMD-Marking)		39	SOT-89			›2SD1615A
GR		Si-P	=2SA1455K-R (SMD-Marking)		35	SOT-23			›2SA1455K

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
GR		Si-N	=2SC2996-R (SMD-Marking)		35	SOT-23			›2SC2996
GS									
GS		Si-P	=2SA1455K-S (SMD-Marking)		35	SOT-23			›2SA1455K
GS 100(B....D)	Hfo	Ge-P	S, 25V, 0,05A, 0,03W, <1500/-ns		2a		AC 151	2a	AC 122, AC 125...126, AC 151, ASY 26...27
GS 109(B....D)	Hfo	Ge-P	S, 20V, 0,05A, 0,083W, <1500/-ns		2a		AC 151	2a	AC 122, AC 125...126, AC 151, ASY 26...27
GS 110	Hfo	Ge-P	S, 20V, 0,3A, 0,083W, <1500/-ns		2a		AC 188 K	3a	AC 128, AC 152...153, AC 188, ASY 76...77
GS 111(B....E)	Hfo	Ge-P	S, 20V, 0,2A, 0,083W, <1200/1500ns		2a		AC 188 K	3a	AC 128, AC 152...153, AC 188, ASY 76...77
GS 112(B....E)	Hfo	Ge-P	=GS 111: <900/1500ns		2a		AC 188 K	3a	AC 128, AC 152...153, AC 188, ASY 76...77
GS 121(B....D)	Hfo	Ge-P	S, 20V, 0,1A, 0,15W, <10µs		2a		AC 188 K	3a	AC 128, AC 152...153, AC 188, ASY 76...77
GS 122	Hfo	Ge-P	=GS 121: 30V		2a		AC 188 K	3a	AC 128, AC 152...153, AC 188, ASY 76...77
GS 9010....9022		Si-N/P	›CS 9010...9022				›CS 9010-9022		
GSA 15 B...G	Say	Si-Di	Rr, Uni, 100...600V, 1,5A, Uf<1V(1,5A)		31a	SOD-57	BYD 33 M	31a	BY 226...227, BY 251...255, 1N5391...99, ++
GSA 17 B...E	Say	Si-Di	Rr, Uni, 100...400V, 1,7A, Uf<1,05V(1,7A)		31a	DO-15	BY 255	31a	BY 251...255, MR 500...510, 1N5400...08, ++
GSA 26 B...E	Say	Si-Di	Rr, Uni, 100...400V, 2,6A, Uf<1,05V(2,6A)		31a	DO-15	BY 255	31a	BY 251...255, MR 500...510, 1N5400...08, ++
GSA 30 B...J	Say	Si-Di	Rr, Uni, 100...800V, 3A, Uf<1V(3A)		31a	SOD-64	BY 255	31a	BY 251...255, MR 500...510, 1N5400...08, ++
GS-H9012		Si-P	=SS 9012				›SS 9012		›SS 9012
GS-H9032		Si-P	›CS 9012				BC 327	7a	
GS-H9033		Si-N	›CS 9013				BC 337	7a	
GT....GZ									
GT		Si-N	=2SC4168 (SMD-Marking)		35	SOT-23			›2SC4168
GT		Si-N	=2SC4443 (SMD-Marking)		35(2mm)	SOT-323			›2SC4443
GT		Z-Di	=SM 6T 200 (SMD-Marking)		71a(6x4mm)	SOD-6			›SM 6T....
GT 8 J101	Tos	MOS-N-IGBT-e	Iso-Gate bipolar Trans., 600/20V, 8/16A, 30W		17(GCE)	TO-220 Iso			-
GT 8 J102	Tos	MOS-N-IGBT-e	=GT 8J101: 50W		30(GCE)	(TO-220MF)			-
GT 8 N101	Tos	MOS-N-IGBT-e	Iso-Gate bipolar Trans., 1000/20V, 8/16A, 100W		18(GCEC)	TO-3P			BUP 302
GT 8 Q101	Tos	MOS-N-IGBT-e	Iso-Gate bipolar Trans., 1200/20V, 8/16A, 100W		18(GCEC)	TO-3P			-
GT 10 G101	Tos	MOS-N-IGBT-e	Iso-Gate bipolar Trans., 400/25V, 10/130A, 30W		17(GCE)	TO-220 Iso			-
GT 10 G102	Tos	MOS-N-IGBT-e	Iso-Gate bipolar Trans., 400/20V, 10/130A, 30W		17(GCE)	TO-220 Iso			-
GT 15 G101	Tos	MOS-N-IGBT-e	Iso-Gate bipolar Trans., 400/25V, 15/170A, 40W		17(GCE)	TO-220 Iso			-
GT 15 J101	Tos	MOS-N-IGBT-e	Iso-Gate bipolar Trans., 600/20V, 15/30A, 100W		18(GCEC)	TO-3P			-
GT 15 J102	Tos	MOS-N-IGBT-e	=GT 15J101: 35W		17(GCE)	TO-220 Iso			-
GT 15 J103	Tos	MOS-N-IGBT-e	=GT 15J101: 70W		30(GCE)	(TO-220MF)			-
GT 15 N101	Tos	MOS-N-IGBT-e	Iso-Gate bipolar Trans., 1000/20V, 15/30A, 150W		18(GCEC)	TO-3P			BUP 303
GT 15 Q101	Tos	MOS-N-IGBT-e	Iso-Gate bipolar Trans., 1200/20V, 15/30A, 150W		18(GCEC)	TO-3P			-
GT 20 D101	Tos	MOS-N-IGBT-e	Iso-Gate bipolar Trans., 250/20V, 20/60A, 180W		77(GCEC)	TOP-3L			-
GT 20 D201	Tos	MOS-N-IGBT-e	Iso-Gate bipolar Trans., 250/20V, 20/60A, 180W		77(GCEC)	TOP-3L			-
GT 20 G101	Tos	MOS-N-IGBT-e	Iso-Gate bipolar Trans., 400/25V, 20/130A, 60W		30(GCEC)	(TO-220MF)			-
GT 20 G102	Tos	MOS-N-IGBT-e	Iso-Gate bipolar Trans., 400/25V, 20/130A, 60W		30(GCEC)	(TO-220MF)			-
GT 25 G101	Tos	MOS-N-IGBT-e	Iso-Gate bipolar Trans., 400/25V, 25/130A, 75W		30(GCEC)	(TO-220MF)			-
GT 25 G102	Tos	MOS-N-IGBT-e	Iso-Gate bipolar Trans., 400/25V, 25/150A, 75W		30(GCEC)	(TO-220MF)			-
GT 25 J101	Tos	MOS-N-IGBT-e	Iso-Gate bipolar Trans., 600/20V, 25/50A, 150W		18(GCEC)	TO-3P			-
GT 25 Q101	Tos	MOS-N-IGBT-e	Iso-Gate bipolar Trans., 1200/20V, 25/50A, 200W		77(GCEC)	TOP-3L			-
GT 50 J101	Tos	MOS-N-IGBT-e	Iso-Gate bipolar Trans., 600/20V, 50/100A, 200W		77(GCEC)	TOP-3L			-
GT 50 M101	Tos	MOS-N-IGBT-e	Iso-Gate bipolar Trans., 900/25V, 50/100A, 180W		77(GCEC)	TOP-3L			-
GT 60 J101	Tos	MOS-N-IGBT-e	Iso-Gate bipolar Trans., 600/20V, 60/120A, 200W		77(GCEC)	TOP-3L			-
GT 60 M102	Tos	MOS-N-IGBT-e	Iso-Gate bipolar Trans., 900/25V, 60/120A, 200W		77(GCEC)	TOP-3L			-
GT 60 M103	Tos	MOS-N-IGBT-e	Iso-Gate bipolar Trans., 900/25V, 60/120A, 200W		77(GCEC)	TOP-3L			-
GT 60 M104	Tos	MOS-N-IGBT-e	Iso-Gate bipolar Trans., 900/25V, 60/120A, 200W		77(GCEC)	TOP-3L			-
GT 322	Gdc,Usr	Ge-P	HF, >80MHz		5k		AF 239 S	5g	AF 139, AF 200, AF 239(S)
GT 328(A,B)	Gdc,Usr	Ge-P	VHF, >400MHz		5g		AF 239 S	5g	AF 139, AF 239(S)
GT 346(A,B)	Gdc,Usr	Ge-P	VHF/UHF, 600...700MHz		5g		AF 239 S	5g	AF 139, AF 239(S)
GU		Z-Di	=SM 6T 200A (SMD-Marking)		71a(6x4mm)	SOD-6			›SM 6T....
GU-1(A,B,Z)	Sak	Si-Di	Rr, 200...800V, 0,8A, Uf<1,4V(1A), <1µs GU-1: 400V, A=600V, B=800V, Z=200V		31a	SOD-57	BA 159	31a	BA157...159, BY204/..., BY208/..., BY268,++
GU-1 E	Sak	Si-Di	Rr, 1300V, 0,3A, Uf<3V(1A), <2µs		31a	SOD-57	BY 228	31a	BY 228, BY 231/1400, DM 513, GP 10V...Y
GU-1 F		Si-Di	=GU-1E: 1500V		31a	SOD-57	BY 228	31a	BY 228, BY 231/1500, DM 516, GP 10Y
GU-3(A,B,Z)	Sak	Si-Di	FRr, 200...800V, 1A, Uf<1,3V(1A), <500ns GU-3: 400V, A=600V, B=800V, Z=200V		31a	SOD-64	BYD 33 M	31a	BYT 52A...M, BYV 12...16, RG 1A...M, ++
GU-3 SY...SZ	Sak	Si-Di	FRr, SY=100, SZ=200V, 3A, Uf<1,2V(1A), <500ns		31a	SOD-64	BYW 95 C	31a	BYW 95A...C, BYW 96D...E, RG 3A...M, ++
GV		PIN-Di	=1SV249 (SMD-Marking)		35 (2mm)	SOT-323			›1SV249
GV		PIN-Di	=1SV251 (SMD-Marking)		35	SOT-23			›1SV251
GV		Z-Di	=SM 6T 220 (SMD-Marking)		71a(6x4mm)	SOD-6			›SM 6T....
GW		Z-Di	=SM 6T 220A (SMD-Marking)		71a(6x4mm)	SOD-6			›SM 6T....
GX		Si-N	=2SD2403-GX (SMD-Marking)		39	SOT-89			›2SD2403
GXB 10147 A	Sie	ECL-RAM-IC	128x1 Bit, <12ns, Ucc=-5,2V		16-DIC				-
GXB 10149	Sie	ECL-PROM-IC	256x4 Bit, <20ns, Ucc=-5,2V		16-DIC				-
GXB 100473	Sie	ECL-RAM-IC	64x4 Bit, <8ns, Ucc=-4,5V		24-FLP				-
GXB 100474	Sie	ECL-RAM-IC	1024x4 Bit, <25ns, Ucc=-4,5V		24-FLP				-
GY		Si-P	=2SA2883-Y (SMD-Marking)		39	SOT-89			›2SA2883
GY		Si-N	=2SC2996-Y (SMD-Marking)		35	SOT-23			›2SC2996
GY		Si-N	=2SC3689 (SMD-Marking)		35	SOT-23			›2SC3689
GY		Si-N	=2SC4413 (SMD-Marking)		35(2mm)	SOT-323			›2SC4413
GY		Si-N	=2SD2403-GY (SMD-Marking)		39	SOT-89			›2SD2403
GY		Si-N	=KTC4375-Y (SMD-Marking)		39	SOT-89			›KTC 4375
GZ		Si-N	=2SD2403-GZ (SMD-Marking)		39	SOT-89			›2SD2403
GZ		Si-N	=BFR 35AR (SMD-Marking)		35	SOT-23			›BFR 35AR
GZA 2.0...51(X,Y,Z)	Say	Z-Di	2,0...51V, 0,5W, X=-6...-1%, Y=±2,5%, Z=+1...+6%		31a	DO-35	Z-Diode V	31a	BZW 22/..., BZX 55/..., BZX 85/..., ZPD...,+
GZB 2.0....36(B,C)	Say	Z-Di	2....36V, 1W, B=6%, C=0...+12%		31a	DO-41	Z-Diode V	31a	BZV 85/..., BZW 22/..., BZX 61/..., ZPY...,+
GZB 1500 S1	Phi	LIN-IC	US FB Sender/Transmitter		24-DIP				-
GZB 1504	Phi	LIN-IC	US FB Sender/Transmitter						-
GZS 2.0...39(R...Z)	Say	Z-Di	2,0...39V, 0,4W,R=-1...+2,X=-8...-4,Y=-5...0,Z=-2...+3%		31a	=DO-35	Z-Diode V	31a	BZW 22/..., BZX 55/..., BZX 85/..., ZPD...,+
H									
H 0		Si-N	=2SC4252 (SMD-Marking)		35(2mm)	SOT-323			›2SC4252
H 0		Si-N	=2SC4255 (SMD-Marking)		35	SOT-23			›2SC4255
H		Si-N	=2SC4446 (SMD-Marking)		35(2mm)	SOT-323			›2SC4446
H		GaAs-N-FET	=2SK1100 (Marking)		51	SOT-173			›2SK1100
H		GaAs-N-FET	=2SK1229 (Marking)		51	SOT-173			›2SK1229
H		C-Di	=HVU 354 (SMD-Marking)		71(1,7mm)	SOT-323			›HVU 354
H 1(p)		Si-P	=BCW 69 (SMD-Marking)		35	SOT-23			›BCW 69
H 1		Si-N	=BFS 46 (SMD-Marking)		35	SOT-23			›BFS 42

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
H 1		Si-P	=D71Y1.5T1 (SMD-Marking)		39	SOT-89			›D71Y1.5T1
H 1		Si-Di	=HVM 187WK (SMD-Marking)		35	SOT-23			›HVM 187WK
H1O		Si-P	=KSA 2755-O (SMD-Marking)		35	SOT-23			›KSA 2755
H1O		Si-P	=KSA 2859-O (SMD-Marking)		35	SOT-23			›KSA 2859
H1R		Si-P	=KSA 2755-R (SMD-Marking)		35	SOT-23			›KSA 2755
H1Y		Si-P	=KSA 2755-Y (SMD-Marking)		35	SOT-23			›KSA 2755
H1Y		Si-P	=KSA 2859-Y (SMD-Marking)		35	SOT-23			›KSA 2859
H 2(p)		Si-P	=BCW 70 (SMD-Marking)		35	SOT-23			›BCW 70
H 2		Si-N	=BFS 46A (SMD-Marking)		35	SOT-23			›BFS 42A
H 2		Si-Di	=HVM 13 (SMD-Marking)		35	SOT-23			›HVM 13
H2O		Si-N	=KSC 2756-Y (SMD-Marking)		35	SOT-23			›KSC 2756
H2R		Si-N	=KSC 2756-R (SMD-Marking)		35	SOT-23			›KSC 2756
H2Y		Si-N	=KSC 2756-Y (SMD-Marking)		35	SOT-23			›KSC 2756
H 3		Si-P	=2SA956-H3 (SMD-Marking)		35	SOT-23			›2SA956
H 3(p)		Si-P	=BCW 89 (SMD-Marking)		35	SOT-23			›BCW 89
H 3		Si-Di	=HVM 187S (SMD-Marking)		35	SOT-23			›HVM 187S
H3O		Si-N	=KSC 2757-O (SMD-Marking)		35	SOT-23			›KSC 2757
H3R		Si-N	=KSC 2757-R (SMD-Marking)		35	SOT-23			›KSC 2757
H3Y		Si-N	=KSC 2757-Y (SMD-Marking)		35	SOT-23			›KSC 2757
H 4		Si-P	=2SA956-H4 (SMD-Marking)		35	SOT-23			›2SA956
H 4		Si-N	=2SC3134-4 (SMD-Marking)		35	SOT-23			›2SC3134
H 4		Si-P	=BCW 69R (SMD-Marking)		35	SOT-23			›BCW 69R
H4Z		Si-N	=KSC 2758 (SMD-Marking)		35	SOT-23			›KSC 2758
H 5		Si-P	=2SA956-H5 (SMD-Marking)		35	SOT-23			›2SA956
H 5		Si-N	=2SC3134-5 (SMD-Marking)		35	SOT-23			›2SC3134
H 5		Si-P	=BCW 70R (SMD-Marking)		35	SOT-23			›BCW 70R
H 5		Si-Di	=HVM 14 (SMD-Marking)		35	SOT-23			›HVM 14
H5O		Si-N	=KSC 2223-O (SMD-Marking)		35	SOT-23			›KSC 2223
H5R		Si-N	=KSC 2223-R (SMD-Marking)		35	SOT-23			›KSC 2223
H5Y		Si-N	=KSC 2223-Y (SMD-Marking)		35	SOT-23			›KSC 2223
H 6		Si-P	=2SA956-H6 (SMD-Marking)		35	SOT-23			›2SA956
H 6		Si-N	=2SC3134-6 (SMD-Marking)		35	SOT-23			›2SC3134
H 6		Si-P	=BCW 89R (SMD-Marking)		35	SOT-23			›BCW 89R
H 6		Si-Di	=HVM 14S (SMD-Marking)		35	SOT-23			›HVM 14S
H6O		Si-N	=KSC 2759-O (SMD-Marking)		35	SOT-23			›KSC 2759
H6R		Si-N	=KSC 2759-R (SMD-Marking)		35	SOT-23			›KSC 2759
H6Y		Si-N	=KSC 2759-Y (SMD-Marking)		35	SOT-23			›KSC 2759
H 7		Si-N	=2SC3134-7 (SMD-Marking)		35	SOT-23			›2SC3134
H 7		Si-P	=BCF 70 (SMD-Marking)		35	SOT-23			›BCF 70
H 6		Si-Di	=HVM 14SR (SMD-Marking)		35	SOT-23			›HVM 14SR
H 8 D1010		Hybrid-IC	Vorverstärker/Pre-amplifier						-
H 8 D1011		Hybrid-IC	Vorverstärker/Pre-amplifier						-
H 8 D1029		Hybrid-IC	Vorverstärker/Pre-amplifier						-
H 8 D1044		Hybrid-IC	Vorverstärker/Pre-amplifier						-
H 8 D1063		Hybrid-IC	Vorverstärker/Pre-amplifier						-
H 8 D1153		Hybrid-IC	Vorverstärker/Pre-amplifier						-
H 8 Z		Si-N	=KSC 2734: (SMD-Marking)		35	SOT-23			›2SC2734
H 9		Si-Di	=1SS344 (SMD-Marking)		35	SOT-23			›1SS344
H 9 Z		Si-N	=KSC 3120: (SMD-Marking)		35	SOT-23			›2SC3120
H 11		MOS-P-FET-e	=2SJ166 (SMD-Marking)		35	SOT-23			›2SJ166
H 11		Si-P	=BCX 71G (SMD-Marking)		35	SOT-23			›BCX 71G
H 12		MOS-P-FET-e	=2SJ185 (SMD-Marking)		35	SOT-23			›2SJ185
H 12		Si-P	=BCX 71H (SMD-Marking)		35	SOT-23			›BCX 71H
H 13		MOS-P-FET-e	=2SJ202 (SMD-Marking)		35(2mm)	SOT-323			›2SJ202
H 13		Si-P	=BCX 71J (SMD-Marking)		35	SOT-23			›BCX 71J
H 14		MOS-P-FET-e	=2SJ203 (SMD-Marking)		35	SOT-23			›2SJ203
H 14		Si-P	=BCX 71K (SMD-Marking)		35	SOT-23			›BCX 71K
H 15		MOS-P-FET-e	=2SJ204 (SMD-Marking)		35	SOT-23			›2SJ204
H 16		MOS-P-FET-e	=2SJ210 (SMD-Marking)		35	SOT-23			›2SJ210
H 17		MOS-P-FET-e	=2SJ209 (SMD-Marking)		35	SOT-23			›2SJ209
H 18		MOS-P-FET-e	=2SJ211 (SMD-Marking)		35	SOT-23			›2SJ211
H 31		Si-P	=BCW 89R (SMD-Marking)		35	SOT-23			›BCW 89R
H 32		Si-Di	=1N4148		31a		1N4148	31a	›1N4148
H 71		Si-P	=BCF 70R (SMD-Marking)		35	SOT-23			›BCF 70R
H 580	Sgs	LIN-IC	›SAS 580		18-DIP		SAS 580	18-DIP	SAS 580
H 590	Sgs	LIN-IC	›SAS 590		18-DIP		SAS 590	18-DIP	SAS 590
H 629	Sgs	MOS-IC	Orgelgatter, Gates f. Electronic Organ, 1x12		14-DIP				-
H 770	Sgs	LIN-IC	›SN 29770		16-DIP				SN 29770
H 771	Sgs	LIN-IC	›SN 29771		16-DIP				SN 29771
H 772	Sgs	LIN-IC	›SN 29772		16-DIP				SN 29772
H 773	Sgs	LIN-IC	›SN 29773		16-DIP				SN 29773
H 4249		Si-N			17j	TO-220	BUT 56 A	17j	
HA									
HA		Si-N	=2SC2804 (Marking)		25	SOT-103			›2SC2804
HA		Si-N	=2SC3119 (SMD-Marking)		35	SOT-23			›2SC3119
HA		Si-N	=2SD1464-HA (SMD-Marking)		39	SOT-89			›2SD1464
HA		Si-P	=BSS 25 (SMD-Marking)		35	SOT-23			›BSS 25
HA		GaAs-N-FET-d	=CFY 65-12 (Marking)		51				›CFY 55
HA		Si-P	=µPA601T (SMD-Marking)		46	SOT-163			›µPA601T
HA 1-2650	Has	OP-IC	Dual, Serie 158, ±20V, -55…+125°		14-DIC				… 158…, … 1558…, … 2904…
HA 1-2655	Has	OP-IC	Dual, Serie 158, ±20V, 0…+75°		14-DIC				… 158…, … 258…, … 358…, …1458…
HA 3-4741-5	Ray	OP-IC	Quad, ±20V, 0…+75°		14-DIP				-
HA 178L02(P),A(PA)	Hit	Z-IC	+2V, 0.15A, ±8%, A=±5%		7b	TO-92L			… 78L02(TO-92)
HA 178L05(P),A(PA)	Hit	Z-IC	+5V, 0,15A, ±8%, A=±5%		7b	TO-92L	78L05/TO-92	7b	… 78L05(TO-92)
HA 178L06(P),A(PA)	Hit	Z-IC	+6V, 0.15A, ±8%, A=±5%		7b	TO-92L			… 78L06(TO-92)
HA 178L08(P),A(PA)	Hit	Z-IC	+8V, 0,15A, ±8%, A=±5%		7b	TO-92L	78L08/TO-92	7b	… 78L08(TO-92)
HA 178L09(P),A(PA)	Hit	Z-IC	+9V, 0,15A, ±8%, A=±5%		7b	TO-92L			… 78L09(TO-92)
HA 178L10(P),A(PA)	Hit	Z-IC	+10V, 0,15A, ±8%, A=±5%		7b	TO-92L			… 78L10(TO-92)
HA 178L12(P),A(PA)	Hit	Z-IC	+12V, 0,15A, ±8%, A=±5%		7b	TO-92L	78L12/TO-92	7b	… 78L12(TO-92)
HA 178L15(P),A(PA)	Hit	Z-IC	+15V, 0,15A, ±8%, A=±5%		7b	TO-92L	78L15/TO-92	7b	… 78L15(TO-92)
HA 178L56(P),A(PA)	Hit	Z-IC	+5,6V, 0,15A, ±8%, A=±5%		7b	TO-92L			… 78L56(TO-92)
HA 178 L02…L15UA	Hit	Z-IC	=HA 178L02…L15: SMD		39b	SOT-89			M 5278LxxM, TA 78LxxF, …78Lxx…(SOT-89)

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
HA 178 M05(P,PJ)...	Hit	Z-IC	+5V, 0,5A, ±4%, A=±2%, B=±3%, C=+2/-4%		17b	TO-220	7805/TO-220	17b	... 78M05... (TO-220)
HA 178 M06(P,PJ)...	Hit	Z-IC	+6V, 0,5A, ±4%, A=±2%, B=±3%, C=+2/-4%		17b	TO-220	7806/TO-220	17b	... 78M06... (TO-220)
HA 178 M07(P,PJ)...	Hit	Z-IC	+7V, 0,5A, ±4%, A=±2%, B=±3%, C=+2/-4%		17b	TO-220			... 78M07... (TO-220)
HA 178 M08(P,PJ)...	Hit	Z-IC	+8V, 0,5A, ±4%, A=±2%, B=±3%, C=+2/-4%		17b	TO-220	7808/TO-220	17b	... 78M08... (TO-220)
HA 178 M09(P,PJ)...	Hit	Z-IC	+9V, 0,5A, ±4%, A=±2%, B=±3%, C=+2/-4%		17b	TO-220	7809/TO-220	17b	... 78M09... (TO-220)
HA 178 M12(P,PJ)...	Hit	Z-IC	+12V, 0,5A, ±4%, A=±2%, B=±3%, C=+2/-4%		17b	TO-220	7812/TO-220	17b	... 78M12... (TO-220)
HA 178 M15(P,PJ)...	Hit	Z-IC	+15V, 0,5A, ±4%, A=±2%, B=±3%, C=+2/-4%		17b	TO-220	7815/TO-220	17b	... 78M15... (TO-220)
HA 178 M18(P,PJ)...	Hit	Z-IC	+18V, 0,5A, ±4%, A=±2%, B=±3%, C=+2/-4%		17b	TO-220	7818/TO-220	17b	... 78M18... (TO-220)
HA 178 M20(P,PJ)...	Hit	Z-IC	+20V, 0,5A, ±4%, A=±2%, B=±3%, C=+2/-4%		17b	TO-220	7820/TO-220	17b	... 78M20... (TO-220)
HA 178 M24(P,PJ)...	Hit	Z-IC	+24V, 0,5A, ±4%, A=±2%, B=±3%, C=+2/-4%		17b	TO-220	7824/TO-220	17b	... 78M24... (TO-220)
HA 178 MxxFM,FMP	Hit	Z-IC	=HA 178 M05...M24(P,PJ): Iso		17b	TO-220 Iso			... 78Mxx... (TO-220 Iso)
HA 179L05(P).A(PA)	Hit	Z-IC	-5V, 0,15A, ±4%, A=±2%		7a	TO-92L	79L05/TO-92	7a	... 79L05(TO-92)
HA 179L06(P).A(PA)	Hit	Z-IC	-6V, 0,15A, ±4%, A=±2%		7a	TO-92L			... 79L06(TO-92)
HA 179L08(P).A(PA)	Hit	Z-IC	-8V, 0,15A, ±4%, A=±2%		7a	TO-92L			... 79L08(TO-92)
HA 179L09(P).A(PA)	Hit	Z-IC	-9V, 0,15A, ±4%, A=±2%		7a	TO-92L			... 79L09(TO-92)
HA 179L10(P).A(PA)	Hit	Z-IC	-10V, 0,15A, ±4%, A=±2%		7a	TO-92L			... 79L10(TO-92)
HA 179L12(P).A(PA)	Hit	Z-IC	-12V, 0,15A, ±4%, A=±2%		7a	TO-92L	79L12/TO-92	7a	... 79L12(TO-92)
HA 179L15(P).A(PA)	Hit	Z-IC	-15V, 0,15A, ±4%, A=±2%		7a	TO-92L			... 79L15(TO-92)
HA 179 L05...L15UA	Hit	Z-IC	=HA 179L05...L15: Min		39a	SOT-89			... 79Lxx (SOT-89)
HA 179 M05 FM,FMP	Hit	Z-IC	Iso, -5V, 0,5A		17c	TO-220 Iso	(7905/TO-220)[3]	17c	... 79M05...(TO-220 Iso)
HA 179 M06 FM,FMP	Hit	Z-IC	Iso, -6V, 0,5A		17c	TO-220 Iso			... 79M06...(TO-220 Iso)
HA 179 M06 FM,FMP	Hit	Z-IC	Iso, -12V, 0,5A		17c	TO-220 Iso	(7912/TO-220)[3]	17c	... 79M12...(TO-220 Iso)
HA 179 M15 FM,FMP	Hit	Z-IC	Iso, -15V, 0,5A		17c	TO-220 Iso	(7915/TO-220)[3]	17c	... 79M15...(TO-220 Iso)
HA 1107	Hit	LIN-IC	VC, Sound IF						-
HA 1108	Hit	LIN-IC	TV, AFT		14-DIP				-
HA 1110	Hit	LIN-IC	Video-Verstärker/Amplifier		TO-101				CA 3001
HA 1115	Hit	LIN-IC	Stereo-Decoder		14-DIP				HA 1120
HA 1120	Hit	LIN-IC	Stereo-Decoder		14-DIP				HA 1115
HA 1124	Hit	LIN-IC	TV, Sound IF		14-DIP				>HA 1125
HA 1125	Hit	LIN-IC	TV, Sound IF		14-DIP				AN 241, CA 3065, KA 2101, LA 1365, LM 3065, MC 1358, TA 7176, ULN 2165
HA 1126	Hit	LIN-IC	TV, AFT		14-DIP				LA 1364, M 5135, TA 7070
HA 1127(P)	Hit	LIN-IC	TV, 5x Trans.-Array, 20/15V, 50mA, 460MHz		14-DIC,DIP				CA 3045
HA 1127 FP	Hit	LIN-IC	=HA 1127(P): SMD		14-MDIP				-
HA 1137(W)	Hit	LIN-IC	FM IF, LF Inp, AFC		16-DIP				-
HA 1138	Hit	LIN-IC	AM Inp,Mx,Os,IF, Demodulator		16-DIP				-
HA 1142	Hit	LIN-IC	Stereo-Decoder		14-DIP				-
HA 1144	Hit	LIN-IC	TV, Video IF		14-DIP				-
HA 1148	Hit	LIN-IC	CTV, VA Korrektur/Correction		14-DIP				-
HA 1149	Hit	LIN-IC	FM Muting		14-DIP				-
HA 1150	Hit	LIN-IC	FM IF		16-DIP				-
HA 1151	Hit	LIN-IC	AM HF, IF		14-DIP				-
HA 1152	Hit	LIN-IC	CTV, Video IF		14-DIP				-
HA 1154	Hit	LIN-IC	VC, Sound IF						-
HA 1156(W)	Hit	LIN-IC	Stereo-Decoder		14-DIP				-
HA 1160	Hit	LIN-IC	TV, HA Sync, HA Os		7-SIP				-
HA 1166(W)	Hit	LIN-IC							-
HA 1167	Hit	LIN-IC							-
HA 1173	Hit	LIN-IC	FM Demodulator		14-DIP				-
HA 1190	Hit	LIN-IC	Sensor f. 4 Tasten/Touch Switches		16-DIP		SAS 560 S	16-DIP	SAS 560S
HA 1194	Hit	LIN-IC	Sensor f. 4 Tasten/Touch Switches		16-DIP		SAS 570 S	16-DIP	SAS 570S
HA 1196	Hit	LIN-IC	Stereo-Decoder		16-DIP				-
HA 1197	Hit	LIN-IC	AM Tuner, IF		16-DIP		HA 1197*	16-DIP	-
HA 1199	Hit	LIN-IC	AM Tuner		16-DIP		HA 1199*	16-DIP	-
HA 1201	Hit	LIN-IC	FM IF		8-DIP				(=HA 1211)[10]
HA 1202	Hit	LIN-IC	FM IF		8-DIP				-
HA 1203	Hit	LIN-IC	FM IF		8-DIP				-
HA 1211	Hit	LIN-IC	FM IF		8-SIP		HA 1211*	8-SIP	(=HA 1201)[10]
HA 1303	Hit	OP-IC			TO-100				-
HA 1306(W)	Hit	LIN-IC	Audio Out, 18V, 2,25A, 3,5W(13V/4Ω)		10-QIP+f				-
HA 1314	Hit	LIN-IC							
HA 1317(V,W,VU,WU)	Hit	LIN-IC	Audio Out, 36V, 8W(26V/8Ω)		10-DIP+g				-
HA 1319	Hit	LIN-IC	Audio Inp,Out, 12V, 1W(6V/4Ω)		14-DIP				-
HA 1322(W)	Hit	LIN-IC	Audio Out, 18V, 2,25A, 5,5W(13V/4Ω)		10-DIP+f				-
HA 1324	Hit	LIN-IC	Audio Out, 18V, 2,25A, 4,5W(13V/4Ω)		10-DIP+g				-
HA 1325	Hit	LIN-IC	Audio Out, 20V, 1,25A, 2W(13V/8Ω)		12-DIP+a				-
HA 1327	Hit	LIN-IC	4-Kanal-/Channel Decoder		16-DIP				-
HA 1328	Hit	LIN-IC	Matrix f. 4-Kanal-/Channel Decoder		16-DIP				-
HA 1329	Hit	LIN-IC	Audio Out, 9V, 1,4A, 2,5W(6V/8Ω)		12-DIP+a				-
HA 1333	Hit	LIN-IC	CD-4 Demodulator		16-DIP				-
HA 1334	Hit	LIN-IC	CD-4 Demodulator		16-DIP				-
HA 1338	Hit	LIN-IC	Audio Out, 33V, 4,1A, 6W(24V/8Ω)		10-QIP+f				-
HA 1339(A)	Hit	LIN-IC	Audio Out, 18V, 4,5A, 5,5W(13V)		10-SILP+a				-
HA 1339(A)R	Hit	LIN-IC	=HA1339: spiegelb. Pinbelegung/Reverse Pinning		10-SILP+a				-
HA 1342(A)	Hit	LIN-IC	Audio Out, 18V, 4,5A, 5,5W(13V)		10-SILP+a				-
HA 1342(A)R	Hit	LIN-IC	=HA1342: spiegelb. Pinbelegung/Reverse Pinning		10-SILP+a				-
HA 1345 V	Hit	LIN-IC	Audio Out, 36V, 8W(26V/8Ω)		10-SILP				-
HA 1350	Hit	LIN-IC	Audio Out, ±30V, 7,5A, 18W(±25V/8Ω)		10-SILP				HA 1370
HA 1361	Hit	LIN-IC	Audio Out, 9V, 2,25A, 1W(6V/4Ω)		12-DIP+b				-
HA 1364	Hit	LIN-IC	TV, Sound IF, LF Out, 1,5W(24V/16Ω)		12-QIP+b				-
HA 1366 W	Hit	LIN-IC	Audio Out, 18V, 4,5A, 5,5W(13V/4Ω)		10-SILP+a				-
HA 1366 WR	Hit	LIN-IC	=HA1366W: spiegelb. Pinbelegung/Reverse Pinning		10-SILP+a				-
HA 1367(A)	Hit	LIN-IC	Recorder, Audio Inp,Out, 9V, 2,25A, 2,2W(6V/4Ω)		20-DIP+b				-
HA 1368	Hit	LIN-IC	Audio Out, 18V, 4,5A, 5,3W(13V/4Ω)		10-SILP+a		HA 1368*	10-SILP+a	-
HA 1368 R	Hit	LIN-IC	=HA1368: spiegelb. Pinbelegung/Reverse Pinning		10-SILP+a				-
HA 1370	Hit	LIN-IC	Audio Out, ±30V, 7,5A, 18W(±25V/4...8Ω)		10-SILP				-
HA 1371	Hit	LIN-IC	Audio Out, 15V, 3A, 7,3W(9V/4Ω)		12-QIP+b				-
HA 1372	Hit	LIN-IC	Audio Out, 18V, 4,5A, 5,5W(13V/4Ω)		10-DIP+f				-
HA 1374	Hit	LIN-IC	Dual Audio Out, 22V, 2,8A, 2x3W(15V/8Ω)		10-SILP+a				-
HA 1374 A	Hit	LIN-IC	=HA 1374: 25V, 3,2A, 2x4W(17V/8Ω)		10-SILP+a				-
HA 1377(A)	Hit	LIN-IC	Dual Audio Out, 18V, 4,5A, 2x5,8W(13V/4Ω)		12-SIL		HA 1377	12-SIL	-
HA 1384(A)	Hit	LIN-IC	Audio Out, 18V, 4A, 20W(13,2V/4Ω, BTL)		12-SIL				-
HA 1385	Hit	LIN-IC	CTV, VA Out, Ucc=110V		17/5Pin	TO-220/5			-

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
HA 1388	Hit	LIN-IC	Audio Out, 18V, 4A, 18W(13,2V/4Ω)		12-SIL		HA 1388	12-SIL	-
HA 1389	Hit	LIN-IC	Audio Out, 30V, 3,73A, 7W(22V/8Ω)		10-SILP+a				-
HA 1389 R	Hit	LIN-IC	=HA1389: spiegelb. Pinbelegung/Reverse Pinning		10-SILP+a				-
HA 1392	Hit	LIN-IC	Dual Audio Out, 20V, 4A, 2x4,3W(12V/4Ω)		12-SIL		HA 1392	12-SIL	-
HA 1393	Hit	LIN-IC	Audio Out, 18V, 4A, 19W(13,2V/4Ω, BTL)		12-SIL				-
HA 1394	Hit	LIN-IC	Dual Audio Out, 35V, 4,5A, 2x8,2W(25V/8Ω)		12-SIL		HA 1394	12-SIL	-
HA 1396	Hit	LIN-IC	Audio Out, 18V, 4A, 20W(13V/4Ω)		12-SIL		HA 1396*	12-SIL	-
HA 1397	Hit	LIN-IC	Audio Out, ±30V, 7,5A, 20W(±22V/8Ω)		12-SIL				-
HA 1398	Hit	LIN-IC	Audio Out		12-SIL		HA 1398	12-SIL	-
HA 1403	Hit	Z-IC	Tuner Stabi, 33V, 10mA		2d	TO-18	TAA 550	2g	=TAA 550
HA 1406	Hit	LIN-IC	Audio Inp		8-SIP		HA 1406*	8-SIP	-
HA 1451	Hit	LIN-IC	Dual Audio Inp		14-DIP				-
HA 1452(W)	Hit	LIN-IC	Dual Audio Inp		14-DIP				-
HA 1457(W)	Hit	LIN-IC	Audio Inp In, Ucc=±25V		8-SIP				-
HA 1607	Hit	LIN-IC	Monostab. Multivibrator		8-DIP				-
HA 1806 M	Hit	KOP-IC	Dual, 18V, -30...+80°		TO-100				-
HA 1807	Hit	KOP-IC	Dual, 18V, -30...+80°		14-DIP				-
HA 1807 M	Hit	KOP-IC	=HA 1807: Fig. ›		TO-101				-
HA 1812(GS,PS)	Hit	KOP-IC	20V, 200mA, -20...+75°		8-DIC,DIP				-
HA 1813(PS)	Hit	KOP-IC	18V, -20...+75°		8-DIP				-
HA 1835 P	Hit	Z-IC	5V, Watch Dog Timer, Reset		14-DIP				-
HA 1848 P	Hit	Z-IC	5V, Watch Dog Timer, Reset		14-DIP				-
HA 1902	Hit	LIN-IC	Dual Sensor-Verstärker/Amplifier		16-DIP				-
HA 11107	Hit	IC							
HA 11120	Hit	LIN-IC	AM Tuner, AM/FM IF		16/20-DIP				-
HA 11122	Hit	LIN-IC	Recorder, 2x Rec/Play Amp.		16-DIP				-
HA 11123(W)	Hit	LIN-IC	AM/FM IF, AFC, AGC		16/20-DIP				-
HA 11211	Hit	LIN-IC	AM Tuner, AM/FM IF		16/20-DIP				-
HA 11215(A)	Hit	LIN-IC	CTV, IF, Video Signal, AGC		24-DIP		HA 11215(A)*	24-DIP	-
HA 11218	Hit	LIN-IC	TV, HA/VA Sync., Os		16/20-DIP				-
HA 11219	Hit	LIN-IC	FM Noise Suppression		16-DIP				-
HA 11220	Hit	LIN-IC	CTV, Video IF		22-DIP				-
HA 11221	Hit	LIN-IC	TV, Video IF		16-DIP				-
HA 11222	Hit	LIN-IC	CTV, NTSC Chroma Signal		28-DIP				-
HA 11223(W)	Hit	LIN-IC	Stereo-Decoder		16-DIP				-
HA 11225	Hit	LIN-IC	FM IF		16-DIP		HA 11225	16-DIP	-
HA 11226	Hit	LIN-IC	Dual Dolby B System		16/20-DIP				-
HA 11226 MP	Hit	LIN-IC	=HA 11226: SMD		18-FLP				-
HA 11227	Hit	LIN-IC	Stereo-Decoder		16-DIP		BA 1330	16-DIP	AN7410, BA1330, KA2261, LA3361, TA7604
HA 11229	Hit	LIN-IC	TV, Sound IF		14-DIP		HA 11229*	14-DIP	-
HA 11235	Hit	LIN-IC	CTV, HA/VA Sync., Os, 60/15734Hz		16/20-DIP				-
HA 11236		LIN-IC							-
HA 11238	Hit	LIN-IC	CTV, Video IF		22-DIP				-
HA 11244	Hit	LIN-IC	TV, Sync. Signal		16-DIP		HA 11244*	16-DIP	-
HA 11247	Hit	LIN-IC	CTV, NTSC Chroma Signal		16/20-DIP				-
HA 11247 MP	Hit	LIN-IC	=HA 11247: SMD		18-MP				-
HA 11251	Hit	LIN-IC	AM/FM IF, Demodulator		16-DIP				-
HA 11401	Hit	LIN-IC	TV, Video Signal		16-DIP		HA 11401*	16-DIP	-
HA 11405	Hit	LIN-IC	CTV, Video IF		16-DIP				-
HA 11408 A	Hit	LIN-IC	TV, Video Signal		28-DIP				-
HA 11409	Hit	LIN-IC	CTV, NTSC VIR		16-DIP				-
HA 11410	Hit	LIN-IC	TV		28-DIP				-
HA 11412 A	Hit	LIN-IC	CTV, NTSC Chroma Signal		28-DIP				-
HA 11414	Hit	LIN-IC	TV, Sync. Signal		16-DIP				-
HA 11417	Hit	LIN-IC	CTV, NTSC Chroma Signal, Demodulator		24-DIP				-
HA 11423	Hit	LIN-IC	TV, Sync., VA Os, Blanking		16/20-DIP		HA 11423	16/20-DIP	-
HA 11423 MP	Hit	LIN-IC	=HA 11423: SMD		18-MP				-
HA 11431	Hit	LIN-IC	CTV, Einstellkombi/DC Control (NTSC)		28-DIP				-
HA 11431 NT	Hit	LIN-IC	=HA 11431:Fig. ›		30-SDIP				-
HA 11433	Hit	LIN-IC	TV Stereo Sound System		16-DIP				-
HA 11436 A	Hit	LIN-IC	CTV, Chroma System (NTSC)		28-DIP				-
HA 11440(A)	Hit	LIN-IC	CTV, Video IF System, Iagc<0,5mA		16-DIP				-
HA 11441	Hit	LIN-IC	TV, HA/VA Os, Sync., Blanking		16/20-DIP				-
HA 11441 MP	Hit	LIN-IC	=HA 11441: SMD		18-MP				-
HA 11442	Hit	LIN-IC	=HA11440(A): Iagc<1,5mA		16-DIP				-
HA 11443	Hit	LIN-IC	TV, Video/Sound IF		28-DIP				-
HA 11445	Hit	LIN-IC	TV, Video/Sound IF		28-DIP				-
HA 11465 A	Hit	LIN-IC	CTV, Video System, Sync. Signal		16/20-DIP				-
HA 11466 S	Hit	LIN-IC	HF-Modulator f. VC, µComp, Ucc=5V		16-DIP				-
HA 11476 NT	Hit	LIN-IC	TV/VC, Video/Sound IF, Video Signal		30-SDIP				-
HA 11477 NT	Hit	LIN-IC	Video-/Audio-Umschalter/Switch		30-SDIP				-
HA 11485 BNT	Hit	LIN-IC	TV,VC, Video/Sound IF, FM Demodulator		30-SDIP				-
HA 11498	Hit	LIN-IC	Digital Video Processor		42-DIP				-
HA 11505	Hit	LIN-IC	Video-Verst./Amplifier, 100MHz, Ucc=5V		24-SDIP+b				-
HA 11508	Hit	LIN-IC	CTV, Video-/Audio-Umschalter/Switch, Ucc=8...13,2V		20-DIP				-
HA 11510 NT	Hit	LIN-IC	CTV,VC, FB Interface		30-SDIP				-
HA 11511 CNT	Hit	LIN-IC	CTV, Video-/Chroma Processor (NTSC)		42-SDIP				-
HA 11513	Hit	LIN-IC	5-Kanal/Channel Video-Umschalter/Switch, Ucc=12V		16-DIP				-
HA 11517 BNT	Hit	LIN-IC	TV, HA/VA Os, Sync., Blanking		30-SDIP				-
HA 11525 MP	Hit	LIN-IC	VC, Digital Signal Processor (NTSC)		28-MP				-
HA 11530 MP	Hit	LIN-IC	VC, Digital Signal Processor (NTSC)		28-MP				-
HA 11531 NT	Hit	LIN-IC	VC, Video-/Chroma Processor (NTSC)		42-SDIP				-
HA 11532 MP	Hit	LIN-IC	VC, Digital Chroma Processor (NTSC)		28-MP				-
HA 11533 NT	Hit	LIN-IC	RGB Video-Verst./Amplifier		24-SDIP+b				-
HA 11535 MP	Hit	LIN-IC	VC, HA/VA-Sync., Killer Detector (PAL)		28-MP				-
HA 11536 MP	Hit	LIN-IC	=HA 11535: R-Y, B-Y Signal (PAL)		28-MP				-
HA 11539 NT	Hit	LIN-IC	CTV,VC, Tuning-System Interface		22-SDIP				-
HA 11544	Hit	LIN-IC	Multiplex Video Switch		16-DIP				-
HA 11545 A	Hit	LIN-IC	FM, Video HF Modulator, Ucc=5V		16-DIP				-
HA 11556 NT	Hit	LIN-IC	CTV/VC, Video IF System		22-SDIP				-
HA 11559 NT	Hit	LIN-IC	CTV, Verzögerungsleitung/Delay Line		30-SDIP				-
HA 11560 FP	Hit	LIN-IC	SMD, VC, HF Modulator, Ucc=5V		16-MDIP				-
HA 11561	Hit	LIN-IC	CTV, Color Signal Matrix		16-DIP				-

Original	Fabric.	Constr.	Info	{Compl. Fig.		JAEGER	Fig.	International
HA 11566 NT	Hit	LIN-IC	CTV,VC, Split Video & Sound IF f. SAW Filter	22-DIP				-
HA 11569 FS	Hit	LIN-IC	CTV,VC, PIP Processor (NTSC)	80-MP				-
HA 11571 AF,BF	Hit	LIN-IC	CTV,VC, BS Tuner PLL, AGC, AFC, IF, Video	28-MP/4TAB				-
HA 11575 F	Hit	LIN-IC	CTV,VC, BS Tuner PLL, AGC, AFC, IF, Video	28-MP/4TAB				-
HA 11579	Hit	LIN-IC	CTV,VC, PIP Processor (NTSC)	56-MP				-
HA 11580	Hit	LIN-IC	CTV, Chroma Signal	24-DIP				-
HA 11701	Hit	LIN-IC	VC, FM Signal	16/20-DIP				-
HA 11702	Hit	LIN-IC	VC, Kopfvorverst./Head Preamp.	16/20-DIP		HA 11702*	16/20-DIP	-
HA 11703	Hit	LIN-IC	VC, FM Signal	20-DIP				-
HA 11704	Hit	LIN-IC	VC, Color Signal	16/20-DIP				-
HA 11705	Hit	LIN-IC	VC, Color AFC	16/20-DIP				-
HA 11706	Hit	LIN-IC	VC, Color APC	16/20-DIP		HA 11706*	16/20-DIP	-
HA 11707	Hit	LIN-IC	VC, Servo	28-DIP				-
HA 11710	Hit	LIN-IC	VC, Chroma	16/20-DIP		HA 11710*	16/20-DIP	-
HA 11711	Hit	LIN-IC	VC, Servo	28-DIP				-
HA 11712 A	Hit	LIN-IC	VC, NTSC, VIR	16-DIP				-
HA 11713	Hit	LIN-IC	VC, Servo	16-DIP				-
HA 11714	Hit	LIN-IC	VC, Servo	16/20-DIP				-
HA 11715	Hit	LIN-IC	VC, Servo	12-QIP+a				-
HA 11716	Hit	LIN-IC	VC, Luminance Signal	20-DIP		HA 11716*	20-DIP	-
HA 11717	Hit	LIN-IC	VC, Color AFC	16/20-DIP		HA 11717*	16/20-DIP	-
HA 11718	Hit	LIN-IC	VC, Luminance Signal	16-DIP		HA 11718*	16-DIP	-
HA 11719	Hit	LIN-IC	Video Camera Signal	16/20-DIP				-
HA 11720	Hit	LIN-IC	Video Camera Signal	16/20-DIP				-
HA 11722	Hit	LIN-IC	VC, Servo	14-DIP				-
HA 11724	Hit	LIN-IC	VC, Rec/Play Amp.	28-DIP				KA 2984
HA 11725	Hit	LIN-IC	VC, Video Signal	28-DIP				KA 2985
HA 11726	Hit	LIN-IC	VC, Chroma Signal	28-DIP				KA 2986
HA 11727	Hit	LIN-IC	VC, Chroma Signal	28-DIP				KA 2987
HA 11732	Hit	LIN-IC	Video Camera Signal	16-DIP				-
HA 11738	Hit	LIN-IC						
HA 11741	Hit	LIN-IC	VC, Servo Controller	28-DIP				KA 2988, µPC 1536C
HA 11744	Hit	LIN-IC	VC, Video Rec/Play Amp.	28-DIP				KA 2944, µPC 1534C
HA 11744 NT	Hit	LIN-IC	=HA 11744: Fig. ›	30-SDIP				-
HA 11745	Hit	LIN-IC	VC, Video Signal System	28-DIP				KA 2945, µPC 1524A
HA 11745 NT	Hit	LIN-IC	=HA 11745: Fig. ›	30-SDIP				-
HA 11752	Hit	LIN-IC	=HA 11772: FM AGC	16-DIP				-
HA 11770 AMP	Hit	LIN-IC	Camera, PAL/SECAM Signal Processor	44-MP				-
HA 11772	Hit	LIN-IC	VC, 2-Kanal/Channel Vorverst./Pre-Amp.	16-DIP				HA 11752
HA 11776 AMP	Hit	LIN-IC	Camera, Encoder	28-MP				-
HA 11787	Hit	LIN-IC	VC, Drop Out Compensator	16-DIP				-
HA 11844 BMP	Hit	LIN-IC	Camera, Weiss/White-Balance	28-MP				-
HA 11856 ANT	Hit	LIN-IC	VC, Color Signal Processor (NTSC)	42-SDIP				-
HA 11864 MP	Hit	LIN-IC	VC, VHS-C, FM Signal Processor	44-MP				-
HA 11870 ANT	Hit	LIN-IC	VC, 4-Kanal/Channel Vorverst./Pre-Amp.	30-SDIP				-
HA 11876 MP	Hit	LIN-IC	=HA 11876NT: SMD	44-MP				-
HA 11876 NT	Hit	LIN-IC	VC, VHS-C, 4-Kanal/Channel Vorverst./Pre-Amp.	42-SDIP				-
HA 11882 AMP	Hit	LIN-IC	Camera, 4-Kanal/Channel Processor	44-MP				-
HA 11883 MP	Hit	LIN-IC	Camera, NTSC/PAL Chroma Encoder	18-MP				-
HA 12001 W	Hit	LIN-IC	Recorder, Funktionsstrg./Mechanic Control	22-DIP				-
HA 12002(W)	Hit	LIN-IC	Lautspr.-Schutz/Speaker Protection, Ucc=45V	8-SIP				-
HA 12003	Hit	IC						
HA 12005	Hit	LIN-IC	LF Inp In, Dolby	16-DIP				-
HA 12006	Hit	LIN-IC	Recorder Rec/Play Amp.	16/20-DIP				-
HA 12009	Hit	LIN-IC	7-Segment Decoder f. Digital Tuning	42-DIP				-
HA 12010	Hit	LIN-IC	FLT-Treiber/Driver	16-DIP				-
HA 12016	Hit	LIN-IC	PLL FM MPX Stereo-Decoder, Ucc=13V	16-DIP				-
HA 12017	Hit	LIN-IC	Audio Vorverst./Preamp., In, Ucc=±24V	8-SIP	(no Pin2)			-
HA 12018	Hit	LIN-IC	Stereo-Decoder	16-SQP				-
HA 12019	Hit	LIN-IC	Recorder, Pegelanzeige/Level Meter, log.	16-DIP				-
HA 12020	Hit	LIN-IC	Recorder, Equalizer	28-DIP				-
HA 12022	Hit	LIN-IC		16/20-DIP				
HA 12024	Hit	LIN-IC	Recorder	16/20-DIP				-
HA 12026	Hit	LIN-IC	Stereo-Decoder	16-DIP				-
HA 12027	Hit	LIN-IC	Recorder, Dolby B System	16/20-DIP				-
HA 12028	Hit	LIN-IC	Recorder, Verstärker/Amplifier	22-DIP				-
HA 12029	Hit	LIN-IC	8-Bit µComp Interface	18-FLP				-
HA 12030	Hit	LIN-IC	8-Bit µComp Interface	16-DIP				-
HA 12031	Hit	LIN-IC	Stereo-Decoder	28-DIP				-
HA 12032	Hit	LIN-IC	Anzeigetreiber/Meter Driver	18-DIP				-
HA 12075 MP	Hit	LIN-IC	8mm-VC, FM Processor	44-MP				-
HA 12093 MP	Hit	LIN-IC	=HA 12093NT: SMD	44-MP				-
HA 12093 NT	Hit	LIN-IC	VC, VHS HiFi FM Signal	42-SDIP				-
HA 12095 NT	Hit	LIN-IC	CD, Vorverst./Preamp., Servo Amp., Ucc=±5V	42-SDIP				-
HA 12096 NT	Hit	D/A-IC	16 Bit, Digital Audio, Ucc=±5V	22-SDIP				-
HA 12108 MP	Hit	D/A-IC	=HA 12108NT: SMD	44-MP				-
HA 12108 NT	Hit	D/A-IC	CD/DAT, 16 Bit, Stereo, Digital Audio, S/H, Ucc=5V	22-SDIP				-
HA 12127 ANT	Hit	LIN-IC	Stereo FM Demodulation, CX NR System, Ucc=±5V	56-SDIP				-
HA 12132 MP	Hit	A/D-D/A-IC	SMD, Dual, 16 Bit, Dig. Audio (R-DAT), Sample/Hold	44-MP				-
HA 12133 MP	Hit	LIN-IC	SMD, R-DAT, Dual, Rec/Play Amp, Equal., Ucc=5V	44-MP				-
HA 12134 A	Hit	LIN-IC	Dual Dolby-B NR System, Ucc=6,5…16V, Level=300mV	16-DIP				-
HA 12135 A	Hit	LIN-IC	Dual Dolby-B NR System, Ucc=8…16V, Level=450mV	16-DIP				-
HA 12136 A	Hit	LIN-IC	Dual Dolby-B NR System, Ucc=9,5…16V, Level=580mV	16-DIP				-
HA 12136 AF	Hit	LIN-IC	=HA 12134…12136: SMD	16-MDIP				-
HA 12141 NT	Hit	LIN-IC	Dual Dolby-B/C NR System, Ucc=7,5…16V	30-SDIP				-
HA 12142 NT	Hit	LIN-IC	Dual Dolby-B/C NR System, Ucc=9,5…16V	30-SDIP				-
HA 12144 FP	Hit	LIN-IC	SMD,FM Front End, AGC, f. Auto-/Car Radio, Ucc=12V	16-MDIP				-
HA 12151 MA	Hit	LIN-IC	SMD, Dual Dolby-B/C NR System, Ucc=7,5…16V	44-MP				-
HA 12153 MA	Hit	LIN-IC	SMD, Dual Dolby-B/C NR System, Ucc=9,5…16V	44-MP				-
HA 12154 MA	Hit	LIN-IC	DAT Recorder, Rec/Play Amp, Equalizer, Ucc=5V	56-MP				-
HA 12155 NT	Hit	LIN-IC	Recorder, Dual Audio Signal Processor, Dolby-B/C	64-SDIP				-
HA 12156 MA	Hit	LIN-IC	CD, Vorverst./Preamp., Tracking f. Portable	44-MP				-
HA 12157 NT	Hit	LIN-IC	Recorder, Audio Signal Processor, Dolby-B/C	64-SDIP				-

Original	Fabric.	Constr.	Info	{Compl.	Fig.	JAEGER	Fig.	International
HA 12158	Hit	LIN-IC	=HA 12158NT: SMD		56-MP			-
HA 12158 NT	Hit	LIN-IC	CD, Servo System, Ucc=5V		56-SDIP			-
HA 12160	Hit	LIN-IC	Recorder, Audio Processor, Dolby-B, Ucc=8,2...16V		56-MP			-
HA 12161 FP	Hit	LIN-IC	SMD, Dual Dolby-B/C NR System, Ucc=7,5...16V		28-MDIP			-
HA 12162 FP	Hit	LIN-IC	SMD, Dual Dolby-B/C NR System, Ucc=9,5...16V		28-MDIP			-
HA 12163	Hit	LIN-IC	Recorder, Audio Processor, Dolby-B, Ucc=6,5...16V		56-MP			-
HA 12164	Hit	LIN-IC	Recorder, Audio Processor, Dolby-B, Ucc=7,2...16V		56-MP			-
HA 12165	Hit	LIN-IC	Recorder, Audio Processor, Dolby-B, Ucc=8,5...16V		56-MP			-
HA 12166 F	Hit	LIN-IC	Recorder, Audio Processor, Dolby-B, Ucc=6,5...16V		48-MP			-
HA 12167 FB	Hit	LIN-IC	Recorder, Audio Processor, Dolby-B/C, Ucc=12...15V		80-MP			-
HA 12168 NT	Hit	LIN-IC	SMD, CD, Servo System, Ucc=5V, =HA 12158(Pin9)		56-MP			-
HA 12169 FB	Hit	LIN-IC	Recorder, Audio Processor, Dolby-B/C, Ucc=11...15V		80-MP			-
HA 12170 NT	Hit	LIN-IC	Dual Dolby-B/C NR System, Ucc=12...16V		30-SDIP			-
HA 12171 NT	Hit	LIN-IC	Recorder, Audio Processor, Dolby-B, Ucc=9,5...16V		56-SDIP			-
HA 12172 NT	Hit	LIN-IC	Recorder, Audio Processor, Dolby-B, Ucc=9,5...16V		56-SDIP			-
HA 12173	Hit	LIN-IC	Recorder, Audio Processor, Dolby-B/C, Ucc=7...16V		56-MP			-
HA 12174	Hit	LIN-IC	Recorder, Audio Processor, Dolby-B/C, Ucc=8...16V		56-MP			-
HA 12175	Hit	LIN-IC	Recorder, Audio Processor, Dolby-B/C, Ucc=9,5...16V		56-MP			-
HA 12177	Hit	LIN-IC	Recorder, Audio Processor, Dolby-B/C, Ucc=12...16V		56-MP			-
HA 12178 F	Hit	LIN-IC	CD, Servo System, Ucc=5V		56-MP			-
HA 12179 F	Hit	LIN-IC	Recorder, Audio Processor, Dolby-B, Ucc=6,8...16V		56-MP			-
HA 12180 F	Hit	LIN-IC	FM IF (H.U.C. GmbH DYNAS System), Mute, Ucc<16V		56-MP			-
HA 12181 FP	Hit	LIN-IC	SMD, AM Störunterdr./Noise Reduction, Ucc7...10V		16-MDIP			-
HA 12182 F	Hit	LIN-IC	=HA 12182NT: SMD		56-MP			-
HA 12182 NT	Hit	LIN-IC	Recorder, Audio Processor, Dolby-B, Ucc=12...16V		56-SDIP			-
HA 12402	Hit	LIN-IC	AM Inp, AM/FM IF, Audio Out, 0,45W(6V/8Ω)		16-DIP	TDA 1083	16-DIP	A 283D, KA 22424, TA 7613AP, TDA 1083, ULN 2204
HA 12404	Hit	LIN-IC	AM/FM Frequ.-Zähler/Counter, 7-Segment Decoder		22-DIP			-
HA 12405	Hit	LIN-IC	AM/FM Frequ.-Zähler/Counter, 7-Segment Decoder		22-DIP			-
HA 12411	Hit	LIN-IC	FM IF, AGC, AFC		16-DIP			-
HA 12412	Hit	LIN-IC	FM IF, Dem, Mute, AFC, Ucc=13V		16-DIP			-
HA 12413	Hit	LIN-IC	AM/FM IF, Dem, Signal Meter, Ucc=3...14V		16-DIP			BA 4220, KA 2243
HA 12417	Hit	LIN-IC	AM Tuner, IF		16-SQP			-
HA 12418	Hit	LIN-IC	FM IF		16-SQP			-
HA 12419	Hit	LIN-IC	FM Impulszähler/Pulse Count		16-DIP			-
HA 12427	Hit	LIN-IC	AM Tuner, IF		16-DIP			-
HA 12428	Hit	LIN-IC	AM Tuner, IF, AGC, Ucc=7,5...16V		16+4-DIP			-
HA 12428 V	Hit	LIN-IC	=HA 12428: Fig. •		21-SQP			-
HA 12430	Hit	LIN-IC	AM Tuner, AM/FM IF, AGC, Signal Meter, Ucc=3...12V		20-DIP			-
HA 12438 CFP	Hit	LIN-IC	SMD, FM Tuner, FM IF, AGC, f. Car R., Ucc=6,5...10V		16-MDIP			-
HA 13001	Hit	LIN-IC	Dual LF Out, 18V, 4,5A, 2x5,5W(13V/4Ω), 17,5W(BTL)		12-SIL	HA 13001	12-SIL	-
HA 13002	Hit	LIN-IC	Schaltregler/Switching Regulator		16-DIP			-
HA 13006	Hit	LIN-IC	Video Disk, Motorregler/Motor Control		20-DIP+b			-
HA 13007	Hit	LIN-IC	Quad Relais, Solenoid, Motor Drv, Ucc=5V, 0,7A		16-DIP			-
HA 13108	Hit	LIN-IC	Dual Audio Out, 18V, 4A, 2x5,5W(13,2V/4Ω)		12-SIL			-
HA 13116	Hit	LIN-IC	Audio Out, 18V, 4A, 20W(13,2V/4Ω, BTL)		15-SQL			-
HA 13117	Hit	LIN-IC	Audio Out, 18V, 4A, 14W(13,2V/4Ω, BTL)		15-SQL			-
HA 13118	Hit	LIN-IC	Audio Out, 26V, 4A, 18W(13,2V/4Ω, BTL)		15-SQL	HA 13118	15-SQL	-
HA 13119	Hit	LIN-IC	Dual, Audio Out, 18V, 4A, 2x5,5W(13,2V/4Ω)		15-SQL	HA 13119	15-SQL	-
HA 13127	Hit	LIN-IC	Dual BTL LF Out, 18V, 4A, 2x17W(14,4V/4Ω), Gv=50dB		16-SQL			HA 13128
HA 13128	Hit	LIN-IC	Dual BTL LF Out, 18V, 4A, 2x22W(14,4V/4Ω), Gv=50dB		16-SQL			-
HA 13130	Hit	LIN-IC	=HA 13127: Voltage Gain=40dB		16-SQL			HA 13135
HA 13135	Hit	LIN-IC	=HA 13128: Voltage Gain=40dB		16-SQL			-
HA 13143	Hit	LIN-IC	CD, 4x BTL Treiber/Driver f. Servo, Ucc=7...10V		26-SMDIP+b			-
HA 13150 A	Hit	LIN-IC	Quad BTL Audio Out, 18V, 4A, 4x18W(13,2V/4Ω)		23-SQL			-
HA 13151	Hit	LIN-IC	Quad BTL Audio Out, 18V, 3A, 4x14W(13,2V/4Ω)		23-SQL			-
HA 13152	Hit	LIN-IC	Quad BTL Audio Out, 18V, 3A, 4x14W(13,2V/4Ω)		23-SQL			HA 13151
HA 13403(V)	Hit	LIN-IC	VC,3-Phase Brushless Motor Drv, Ucc=4,5...13V, 1,5A		23-SQL			-
HA 13403 MP	Hit	LIN-IC	=HA 13403: SMD, Ucc=4,5...5,5V, 1A		28-MP			-
HA 13406 W	Hit	LIN-IC	5,25" HDD, 3-Ph. Brushless Motor Drv		23-SQL			-
HA 13408	Hit	LIN-IC	9-Channel Power Driver, Ucc=5V, 1,5A		23-SQL			-
HA 13412	Hit	LIN-IC	3-Phase Brushless Motor Drv, Ucc=6...15/5...30V, 1A		23-SQL			-
HA 13415	Hit	LIN-IC	4x Solenoid Driver, Ucc=5V, 0,6A		16-DIP			-
HA 13421 A	Hit	LIN-IC	3...5,25" FDD, 2-Phase Stepping Motor Drv, 0,33A		16-DIP			-
HA 13421 AMP	Hit	LIN-IC	=HA 13421A: SMD		18-MP			-
HA 13426	Hit	LIN-IC	5,25" HDD, Spindle Motor Drv, Ucc=12V, 3A		23-SQL			-
HA 13431	Hit	LIN-IC	5,25" FDD, Spindle Motor Drv, Ucc=12V, 1A		23-SQL			-
HA 13432	Hit	LIN-IC	3...3,5" FDD, Spindle Motor Drv, Ucc=12V, 0,5A		24-SDIP+b			-
HA 13432 MP	Hit	LIN-IC	=HA 13432: SMD		28-MP			-
HA 13439 AMP	Hit	LIN-IC	SMD,2-Ph. Brushl. DC Fan Motor Drv, 7,5...30V, 1,5A		18-MP			-
HA 13440 MP	Hit	LIN-IC	SMD, FDD, 3-Ph. Brushless DC Motor Drv, 12V, 0,7A		28-MP			-
HA 13441(V)	Hit	LIN-IC	HDD, 3-Ph. Brushless DC Motor Drv, 12V, 2A		23-SQL			-
HA 13442(V)	Hit	LIN-IC	=HA 13441(V): 4A		23-SQL			-
HA 13444	Hit	LIN-IC	4x Solenoid Driver, Ucc=5V, 0,6A		16-DIP			-
HA 13447	Hit	LIN-IC	HDD, Voice Coil Motor Drv, Ucc=12V, 2,8A		23-SQL			-
HA 13449 MP	Hit	LIN-IC	S-Reg., 4 Outputs, 200kHz, Ucc=12V, Uref=5V		28-MP			-
HA 13455	Hit	LIN-IC	VC, 3-Phase Brushless Motor Drv(1A), S-Reg(1,8A)		24-SDIP+b			-
HA 13456 A	Hit	LIN-IC	FDD, 3-Phase Brushless DC Motor Drv, Ucc=12V, 0,7A		24-SDIP+b			-
HA 13456 AMP	Hit	LIN-IC	=HA 13456A: SMD		28-MP			-
HA 13457 NT	Hit	LIN-IC	VC, 3-Phase Motor Drv, 1A		24-SDIP+b			-
HA 13460 FP	Hit	LIN-IC	SMD, Brushless DC Fan Motor Drv, 7,5...28V, 2x 1,5A		16-MDIP			-
HA 13464 MP	Hit	LIN-IC	SMD, 3-Phase Brushless DC Motor Drv, 0,4A		28-MP			-
HA 13467 NT	Hit	LIN-IC	VC, 3-Phase Brushless Motor Drv, 1A		24-SDIP+b			-
HA 13468 MP	Hit	LIN-IC	SMD, 3-Ph. Brushl. DC Motor Drv, 0,7A,Speed Diskr.		28-MP			-
HA 13470	Hit	LIN-IC	HDD, Voice Coil Motor Drv, Ucc=12V, 1,67A		15-SQL			-
HA 13471(A)	Hit	LIN-IC	HDD, 3-Ph. Brushless Motor Drv, 12V, 2A		23-SQL			-
HA 13472(A)	Hit	LIN-IC	=HA 13471(A): 4A		23-SQL			-
HA 13473 MP	Hit	LIN-IC	=HA 13473NT: SMD		28-MP			-
HA 13473 NT	Hit	LIN-IC	FDD, 3-Phase Brushless Motor Drv, Ucc=12V, 0,7A		24-SDIP+b			-
HA 13475 FP	Hit	LIN-IC	=HA 13475MP: Fig. •		16-MDIP			-
HA 13475 MP	Hit	LIN-IC	SMD, 2-Phase Stepping Motor Drv, 12V, 0,33A		18-MP			-
HA 13476 S	Hit	LIN-IC	SMD, 3-Ph. HDD, Brushl.Motor Drv, 1A, Speed Diskr.		26-MDIP+b			-
HA 13480 AS-02	Hit	LIN-IC	SMD, 3-Ph. Motor Drv, 24V, 0,7A, Speed Diskr.		26-MDIP+b			-

Original	Fabric.	Constr.	Info	{Compl. Fig.	JAEGER	Fig.	International
HA 13480 S	Hit	LIN-IC	SMD, 3-Ph. Motor Drv, 24V, 0,7A, Speed Diskr.	26-MDIP+b			-
HA 13481 AFP	Hit	LIN-IC	SMD, HDD, 3-Ph. DC Motor Drv, 12V, 2A, Speed Diskr	26-MDIP+b			-
HA 13481 S	Hit	LIN-IC	SMD, HDD, 3-Ph. DC Motor Drv, 12V, 2A, Speed Diskr	26-MDIP+b			-
HA 13482	Hit	LIN-IC	HDD, 3-Ph. Brushl.Motor Drv, 12V, 4A, Speed Diskr.	23-SQL			-
HA 13483 ANT	Hit	LIN-IC	=HA 13483NT: 0,8A	24-SDIP+b			-
HA 13483 (A)MP	Hit	LIN-IC	=HA 13483NT: SMD	28-MP			-
HA 13483 NT	Hit	LIN-IC	FDD, 3-Phase Brushless Motor Drv, Ucc=12V, 0,7A	24-SDIP+b			-
HA 13488	Hit	LIN-IC	HDD, 3-Ph. Brushl.Motor Drv, 12V, 4A, Speed Diskr.	23-SQL			-
HA 13490	Hit	LIN-IC	HDD, Voice Coil Motor Drv, Ucc=12V, 0,8A	16-DIP			-
HA 13490 FP	Hit	LIN-IC	=HA 13490: SMD	16-MDIP			-
HA 13490 MP	Hit	LIN-IC	=HA 13490: SMD	18-MP			-
HA 13491 S	Hit	LIN-IC	SMD, HDD, 3-Phase DC Motor Drv, 5V, 12V, 1A	26-MDIP+b			-
HA 13492	Hit	LIN-IC	Quad Solenoid Driver, Ucc=7…25V, 0,8A	15-SIL			-
HA 13493 MP	Hit	LIN-IC	SMD,FDD, 3-Phase Brushless Motor Drv, Ucc=5V, 0,7A	28-MP			-
HA 13499 AMP,MP	Hit	LIN-IC	SMD,FDD, 3-Phase Brushless Motor Drv, Ucc=5V, 0,7A	28-MP			-
HA 13501 F		LIN-IC	=HA 13501S: Fig. •	56-MP			-
HA 13501 S	Hit	LIN-IC	HDD, 3-Phase Brushless Motor Drv, Ucc=5V, 1,2A	26-MDIP+b			-
HA 13509 F	Hit	LIN-IC	HDD, Voice Coil Motor Drv, Ucc=5V, 0,4A	28-MP/4TAB			-
HA 13511 F	Hit	LIN-IC	FDD, 3-Phase Brushless Motor Drv, Ucc=5V, 0,7A	28-MP/4TAB			-
HA 13513 F,NF	Hit	LIN-IC	FDD, 3-Phase Brushless Motor Drv, Ucc=5V, 0,7A	28-MP/4TAB			-
HA 13518 FP	Hit	LIN-IC	HDD, 3-Phase Brushless Motor Drv, Ucc=5V, 1,2A	26-MDIP+b			-
HA 13520 F	Hit	LIN-IC	HDD, Spindel(1A) & Voice Coil(0,4A) Motor Drv, 5V	28-MP/4TAB			-
HA 13524(S)	Hit	LIN-IC	HDD, Voice Coil Motor Drv, Ucc=12V, 2,8A	23-SQL/SIL			-
HA 13524 FP		LIN-IC	=HA 13524(S): SMD	26-MDIP+b			-
HA 13525 FP	Hit	LIN-IC	HDD, Spindel(1,5A) & Voice Coil(1A) Motor Drv, 12V	26-MDIP+b			-
HA 13529 FP	Hit	LIN-IC	HDD, Voice Coil Motor Drv, Ucc=12V, 0,8A	26-MDIP+b			-
HA 13532 NT	Hit	LIN-IC	3-Phase Stepping Motor Drv, Ucc=24V	24-SDIP			-
HA 13534 FP	Hit	LIN-IC	3-Ph. Brushless Motor Drv, Ucc=24V, 0,7A, >3500rpm	26-MDIP+b			-
HA 13535 FP	Hit	LIN-IC	=HA 13534FP: 7000…18000rpm	26-MDIP+b			-
HA 13536 F	Hit	LIN-IC	FDD, 3-Phase Brushless Motor Drv, Ucc=5V, 0,7A	28-MP/4TAB			-
HA 13537 F	Hit	LIN-IC	FDD, 3-Phase Brushless Motor Drv, Ucc=12V, 0,8A	28-MP/4TAB			-
HA 13537 NT	Hit	LIN-IC	=HA 13537F: Fig. •	24-SDIP+b			-
HA 13539 FP	Hit	LIN-IC	HDD, Voice Coil Motor Drv, Ucc=12V, 1A	26-MDIP+b			-
HA 13540 F	Hit	LIN-IC	HDD, Voice Coil Motor Drv, Ucc=12V, 1,5A	80-MP			-
HA 13542 FP	Hit	LIN-IC	HDD, 3-Phase Brushless Motor Drv, Ucc=12V, 2A	26-MDIP+b			-
HA 13544 F	Hit	LIN-IC	HDD, Spindel(1A) & Voice Coil(0,4A) Motor Drv, 5V	28-MP/4TAB			-
HA 13549 FP	Hit	LIN-IC	HDD, Voice Coil Motor Drv, Ucc=12V, 1A	26-MDIP+b			-
HA 13605	Hit	LIN-IC	3-Phase Brushless Motor Drv, Ucc=20…35V, 1,5A	23-SQP			-
HA 13606(S)	Hit	LIN-IC	HDD, 3-Phase Brushless Motor Drv, Ucc=12V, 4,5A	23-SQP/SIL			-
HA 13705	Hit	LIN-IC	Hi-Side Solenoid Driver, Udd=7…25V	17/5Pin	TO-220/5		-
HA 16103 FPJ	Hit	Z-IC	=HA 16103PJ: SMD	20-MDIP			-
HA 16103 PJ	Hit	Z-IC	5V, Watch Dog Timer, Reset	18-DIP			-
HA 16107 FP	Hit	LIN-IC	=HA 16107P: SMD	16-MDIP			-
HA 16107 P	Hit	LIN-IC	PWM Schaltregler/Switching Regulator, …600kHz	16-DIP			-
HA 16108 FP	Hit	LIN-IC	=HA 16108P: SMD	16-MDIP			-
HA 16108 P	Hit	LIN-IC	PWM Schaltregler/Switching Regulator, …600kHz	16-DIP			-
HA 16109 FP	Hit	LIN-IC	=HA 16109P: SMD	16-MDIP			-
HA 16109 P	Hit	LIN-IC	PWM Schaltregler/Switching Regulator, …600kHz	16-DIP			-
HA 16111 FP	Hit	LIN-IC	=HA 16111P: SMD	16-MDIP			-
HA 16111 P	Hit	LIN-IC	PWM Schaltregler/Switching Regulator, …600kHz	16-DIP			-
HA 16112 F	Hit	CMOS-IC	Spg.-Teiler/Volt. Divider, 10V •1,25+2,5+7,5+8,75V	8-MDIP			-
HA 16113 FPJ	Hit	Z-IC	SMD, Dual, 5V, Watch Dog Timer, Reset	24-MDIP			-
HA 16114 FP	Hit	LIN-IC	=HA 16114P: SMD	16-MDIP			-
HA 16114 P	Hit	LIN-IC	PWM Schaltregler/Switching Regulator, …600kHz	16-DIP			-
HA 16115 F	Hit	CMOS-IC	Spg.-Teiler/Volt. Divider, 10V •1,25+2,5+7,5+8,75V	8-MDIP			-
HA 16116 FP	Hit	LIN-IC	SMD, Dual, PWM Schaltreg./Switch. Reg., …600kHz	20-MDIP			-
HA 16117 FA(J)	Hit	CMOS-IC	SMD, Watch Dog Timer, Reset, Threshold Volt.=4,4V	8-MDIP			-
HA 16117 FB(J)	Hit	CMOS-IC	=HA 16117FA: Threshold Volt.=4,2V	8-MDIP			-
HA 16117 FC(J)	Hit	CMOS-IC	=HA 16117FA: Threshold Volt.=4,0V	8-MDIP			-
HA 16118 FP	Hit	CMOS-OP-IC	SMD, Dual, 15V, Iout=±5mA, 0,82V/µs, -20…+75°	8-MDIP			-
HA 16118 FPJ	Hit	CMOS-OP-IC	=HA 16118FP: -40…+85°	8-MDIP			-
HA 16119 FP	Hit	CMOS-OP-IC	SMD, Dual, 15V, Iout=±5mA, 0,08V/µs, -20…+75°	8-MDIP			-
HA 16120 FP	Hit	LIN-IC	SMD,PWM Schaltregler/Switching Regulator, …600kHz	16-MDIP			-
HA 16121 FP	Hit	LIN-IC	SMD, Dual, PWM Schaltreg./Switch. Reg., …600kHz	20-MDIP			-
HA 16503(P)	Hit	LIN-IC	Motorsteuerung/Motor Control	14-DIP			-
HA 16603 FP	Hit	LIN-IC	=HA 16603P: SMD	16-MDIP			-
HA 16603 P	Hit	LIN-IC	Münz-Sensor/Coin Sensor, Contactless Switch	16-DIP			-
HA 16605 W	Hit	LIN-IC	Burner Controller	20-DIP			-
HA 16613 A	Hit	A/D-IC	8 Bit, Dual Slope, Ucc=+5V	28-DIP			-
HA 16617 P	Hit	LIN-IC	FLT Display Drv, 8 Segm., CMOS/TLL compatible	18-DIP			-
HA 16619 P	Hit	LIN-IC	FLT Display Drv, 8 Segm., CMOS/TLL compatible	18-DIP			-
HA 16628 P	Hit	LIN+D/A-IC	5 Bit, Position Amp. (f. DC Motor), Ucc=12V	16-DIP			-
HA 16629 P	Hit	LIN-IC	Tachometer F/V-Converter (f. DC Motor), Ucc=12V	16-DIP			-
HA 16631 MP	Hit	LIN-IC	=HA 16631P: SMD	18-MP			-
HA 16631 P	Hit	LIN-IC	FDD, Leseverst./Read Amp., Ucc=5/12V	18-DIP			KA 6201
HA 16632 AP	Hit	LIN-IC	FDD, VCO, Data Separate, Ucc=5V	28-DIP			-
HA 16636 AP	Hit	LIN-IC	Fehlstrom-/Ground Fault Interrupter	8-SIP			-
HA 16640 NT	Hit	BiMOS-IC	FDD, Schreib-/Write/Mechanism Controller,UDD=5/12V	42-SDIP			-
HA 16642 MP	Hit	LIN-IC	=HA 16642NT: SMD	44-MP			-
HA 16642 NT	Hit	LIN-IC	FDD, Schreib-Lese/Read-Write Processor, Ucc=5/12V	42-SDIP			-
HA 16643 MP	Hit	BiMOS-IC	SMD, FDD, Mechanik-/Mechanism Controller, Ucc=5V	44-MP			-
HA 16650 MP	Hit	BiMOS-IC	SMD, FDD, Mechanik-/Mechanism Controller, Ucc=5V	44-MP			-
HA 16651 MP	Hit	LIN-IC	SMD, FDD, Schreib-Lese/Read-Write Proc., Ucc=5/12V	44-MP			-
HA 16652 MP	Hit	LIN-IC	SMD, HDD, Schreib-Lese/Read-Write Prozessor, 5/12V	28-MP			-
HA 16652 P4	Hit	LIN-IC	HDD, Schreib-Lese/Read-Write Prozessor, Ucc=5/12V	22-DIP			-
HA 16652 P6	Hit	LIN-IC	HDD, Schreib-Lese/Read-Write Prozessor, Ucc=5/12V	28-DIP			-
HA 16654 AFP	Hit	LIN-IC	=HA 16654APS: SMD	14-MDIP			-
HA 16654 APS	Hit	LIN-IC	PWM Schaltregler/Switching Regulator, 100…500kHz	8-DIP			-
HA 16656 MP	Hit	LIN-IC	SMD, HDD, Lese-/Read Pulse Generator, Ucc=5/12V	44-MP			-
HA 16658 MA,MP	Hit	LIN-IC	=HA 16658NT: SMD	44-MP			-
HA 16658 NT	Hit	LIN-IC	HDD, VCO, Read Data (MFM, RLL), Ucc=5V	42-SDIP			-
HA 16662 MP	Hit	LIN-IC	SMD, HDD, Interface(ST-506), Ucc=5V	44-MP			-
HA 16663 MP	Hit	LIN-IC	SMD, HDD, Lese-/Read Pulse Generator, Ucc=5/12V	18-MP			-

Original	Fabric.	Constr.	Info	Compl.	Fig.		JAEGER	Fig.	International
HA 16664 AFP	Hit	LIN-IC	=HA 16664APS: SMD		14-MDIP				-
HA 16664 APS	Hit	LIN-IC	PWM Schaltregler/Switching Regulator, 100...200kHz		8-DIP				-
HA 16666 FP	Hit	LIN-IC	=HA 16666P: SMD		16-MDIP				-
HA 16666 P	Hit	LIN-IC	PWM Schaltregler/Switching Regulator, ...600kHz		8-DIP				-
HA 16670 MP	Hit	LIN-IC	SMD, HDD, Position Signal Generator, Ucc=5/12V		44-MP				-
HA 16671 MP	Hit	LIN-IC	SMD, HDD, VCM Servo Controller, 8Bit DAC,Ucc=5/12V		44-MP				-
HA 16672 MP	Hit	LIN-IC	SMD, HDD, VCM Servo Controller, 8Bit DAC,Ucc=5/12V		44-MP				-
HA 16676 MP	Hit	LIN-IC	SMD, HDD, Lese-/Read Pulse Generator, Ucc=5/12V		44-MP				-
HA 16681 MA,MP	Hit	LIN-IC	SMD, FDD, Schreib-Lese/Read-Write Proc., Ucc=5/12V		44-MP				-
HA 16682 MP	Hit	LIN-IC	SMD, HDD, Interface(ST-506), Ucc=5V		44-MP				-
HA 16686 MA,MP	Hit	LIN-IC	SMD, HDD, Lese-/Read Pulse Generator, Ucc=5/12V		44-MP				-
HA 16688 MP	Hit	LIN-IC	SMD, HDD, Schreib-Lese/Read-Write Proc., Ucc=5/12V		44-MP				-
HA 16689 MP	Hit	LIN-IC	SMD, HDD, Schreib-Lese/Read-Write Proc., Ucc=5/12V		44-MP				-
HA 16697 MP	Hit	LIN-IC	SMD, FDD, Schreib-Lese/Read-Write Proc., Ucc=5/12V		44-MP				-
HA 16721 MP	Hit	LIN-IC	SMD, FLT Display Drv, 32 Segm., TTL compatible		44-MP				-
HA 16722 MP	Hit	LIN-IC	SMD, FLT Display Drv, 32 Segm., TTL compatible		44-MP				-
HA 17008 RFP	Hit	D/A-IC	=HA 17008RG,RP: SMD		16-MDIP				-
HA 17008 RG,RP	Hit	D/A-IC	8 Bit, Multiplying, Ucc=15V, 85ns		16-DIC,DIP				-
HA 17012 G,P(B,C)	Hit	D/A-IC	12 Bit, Multiplying, Ucc=±15V, 250ns		20-DIC,DIP				-
HA 17080(A)GS	Hit	OP-IC	=HA 17080(A)PS: -40...+85°		8-DIC				TL 080...
HA 17080(A)PS	Hit	OP-IC	J-FET, Serie 080, ±18V, 13V/µs, -20...+75°, A=>CMR		8-DIP				TL 080...
HA 17082(A)GS,PS	Hit	OP-IC	=HA 17080...: Dual		8-DIP,DIC				TL 082...
HA 17083(A)G,P	Hit	OP-IC	=HA 17080...: Dual		14-DIP,DIC				TL 083...
HA 17084(A)G,P	Hit	OP-IC	=HA 17080...: Quad		14-DIP,DIC				TL 084...
HA 17301 G	Hit	OP-IC	=HA 17301P: -40...+85°		14-DIC				
HA 17301 G,P	Hit	OP-IC	Quad, +28V, 50mA, 2,6MHz, 0,2V/µs, -20...+75°		14-DIP				MC 3301
HA 17324 F,FP	Hit	OP-IC	=HA 17324(G,P): SMD		14-MDIP				... 124..., ... 224..., ... 324..., ... 2902...
HA 17324(G,P)	Hit	OP-IC	Quad, Serie 124, ±16V, 50mA, 0,19V/µs, -20...+75°		14-DIC,DIP		(LM 324 N)[16]	14-DIP	... 124..., ... 224..., ... 324..., ... 2902...
HA 17339	Hit	KOP-IC	Quad, Serie 139, ±18V, 20mA, -20...+75°		14-DIP		(LM 339 N)[16]	14-DIP	... 139..., ... 239..., ... 339..., ... 2901...
HA 17339 F	Hit	KOP-IC	=HA 17339: SMD		14-MDIP				... 139..., ... 239..., ... 339..., ... 2901...
HA 17358	Hit	OP-IC	Dual, Serie 158, ±16V, 50mA, 0,2V/µs, -20...+75°		8-DIP		(4558/8-D)[16]	8-DIP	... 158..., ... 258..., ... 358..., ... 1458...
HA 17358 F	Hit	OP-IC	=HA 17358: SMD		8-MDIP				... 158..., ... 258..., ... 358..., ... 1458...
HA 17384 (B)FP	Hit	LIN-IC	=HA 17384PS: SMD		14-MDIP				-
HA 17384(A,B)PS	Hit	LIN-IC	PWM Schaltreg./Sw. Reg., Current Mode, ...300kHz		8-DIP				-
HA 17385(B)FP	Hit	LIN-IC	=HA 17384PS: SMD		14-MDIP				-
HA 17385 PS	Hit	LIN-IC	PWM Schaltreg./Sw. Reg., Current Mode, ...300kHz		8-DIP				-
HA 17393	Hit	KOP-IC	Dual, Serie 193, ±18V, -20...+75°		8-DIP		(LM 393/8-D)[16]	8-DIP	... 193..., ... 293..., ... 393..., ... 2903...
HA 17393 F	Hit	KOP-IC	=HA 17393: SMD		8-MDIP				... 193..., ... 293..., ... 393..., ... 2903...
HA 17408 G,P	Hit	D/A-IC	8 Bit, Multiplying, Ucc=5V, 250ns		16-DIC,DIP				-
HA 17431 FP,FPA(J)	Hit	Ref-Z-IC	=HA 17431P...: Fig. ›		8-MDIP				µPC 1093G
HA 17431 P,PA,PJ	Hit	Ref-Z-IC	+2,5...40V, 1...100mA, Uref=2,495V(±0,1V), A=±0,055V		7(KARef)	TO-92L			TA 76431S, µPC 1093J
HA 17431PS,PSA,PSJ	Hit	Ref-Z-IC	=HA 17431P...: Fig. ›		8-DIP				-
HA 17431 UA,UPA	Hit	Ref-Z-IC	=HA 17431P...: Fig. ›		39(KARef)	SOT-89			TA 76431F, µPC 1093T
HA 17451 AP	Hit	LIN-IC	=HA 17451P: ohne/without Latch Circuits		16-DIP				-
HA 17451 FP,AFP	Hit	LIN-IC	=HA 17451(A)P: SMD		16-MDIP				-
HA 17451 P	Hit	LIN-IC	Dual, PWM Schaltreg./Sw. Reg., 3,3...40V, ...300kHz		16-DIP				-
HA 17458 F,FP,FPJ	Hit	OP-IC	=HA 17458GS,PS: SMD		8-MDIP				... 1458, ... 1558..., ... 4558...
HA 17458 GS,PS	Hit	OP-IC	Dual, Serie 158, ±18V, 0,6V/µs, -25...+75°		8-DIC/DIP		(4558/8-D)	8-DIP	... 1458..., ... 1558..., ... 4558...
HA 17458 M	Hit	OP-IC	=HA 17458GS,PS: Fig. ›		TO-99				... 1458..., ...1558..., ... 4558...
HA 17458 PSJ	Hit	OP-IC	=HA 17458GS,PS: -40...+85°		8-DIP		(4558/8-D)[16]	8-DIP	... 1558...
HA 17474(G,P,RP)	Hit	OP-IC	Quad, ±20V, 1,9V/µs, -20...+75°		14-DIC,DIP				(... 124..., ... 224..., ... 324..., ... 2902.)
HA 17524 FP	Hit	LIN-IC	=HA 17524G,P: SMD		16-MDIP				SG 3524CD
HA 17524 G,P	Hit	LIN-IC	PWM Schaltregler/Switching Regulator, 450kHz		16-DIC,DIP				KA 3524, LM 3524, SG 3524, UC 3524A
HA 17555(GS,PS)(J)	Hit	LIN-IC	=NE 555, 0...+70°, GS,PS=-20...+75°, PSJ=-40...+85°		8-DIC,DIP		NE 555 N	8-DIP	›NE 555
HA 17558(GS,PS)	Hit	OP-IC	Dual, ±18V, 1V/µs, -20...+75°		8-DIC,DIP				(... 1458..., ... 1558..., ... 4558...)
HA 17558 F,FP,FPJ	Hit	OP-IC	=HA 17558...: SMD		8-MDIP				(... 1458..., ... 1558..., ... 4558...)
HA 17558 PSJ	Hit	OP-IC	=HA 17558(GS,PS): -40...+85°		8-DIP				(... 1558...)
HA 17592(G,P)	Hit	LIN-IC	Differential Video-Verst./Amp., ...90MHz, Ucc=6V		14-DIC,DIP				-
HA 17711	Hit	KOP-IC	Dual		14-DIP				-
HA 17715 G	Hit	OP-IC	=HA 17715M: Fig. ›		14-DIC				µA 715
HA 17715 M	Hit	OP-IC	hi-speed, Serie 115, ±18V, 6V/µs, 65MHz, -25...+75°		TO-100				µA 715
HA 17723 F	Hit	Z-IC	=HA 17723M: SMD, 0...+70°		14-MDIP				... 723...
HA 17723(G,P)	Hit	Z-IC	=HA 17723M: 0...+70°, G=-25...+75°		14-DIC,DIP		723/14-D	14-DIP	... 723...
HA 17723 M	Hit	Z-IC	+2....37V, 0,15A, -25...+70		TO-100		723/TO	TO-100	... 723...
HA 17733 M	Hit	LIN-IC	Differential Video-Verst./Ampl., ...120MHz, Ucc=6V		TO-100				LM 733..., µA 733...
HA 17733(G,P)	Hit	LIN-IC	=HA 17733M: Fig. ›		14-DIP				KA 733..., LM 733..., µA 733...
HA 17741 G	Hit	OP-IC	Uni, Serie 741, ±18, 1V/µs, -20...+75°		14-DIC				... 741...
HA 17741(GS,PS)	Hit	OP-IC	=HA 17741G: Fig. ›		8-DIC,DIP		(741/8-D)[16]	8-DIP	... 741...
HA 17741 M	Hit	OP-IC	=HA 17741G:Fig. ›		TO-99		(741/TO)[16]	TO-99	... 741...
HA 17741 PSJ	Hit	OP-IC	=HA 17741G: -40...+85°		8-DIP				... 741...
HA 17747(G,P)	Hit	OP-IC	Dual, Serie 747, ±18V, 1V/µs, -20...+75°		14-DIC,DIP		(747/14-D)[16]	14-DIP	... 747...
HA 17747 M	Hit	OP-IC	=HA 17747G: Fig. ›		TO-100				... 747...
HA 17805P,V,VP,VPJ	Hit	Z-IC	+5V, 1A		17b	TO-220	7805/TO-220	17b	... 7805... (TO-220)
HA 17806P,V,VP,VPJ	Hit	Z-IC	+6V, 1A		17b	TO-220	7806/TO-220	17b	... 7806... (TO-220)
HA 17807P,V,VP,VPJ	Hit	Z-IC	+7V, 1A		17b	TO-220			... 7807... (TO-220)
HA 17808P,V,VP,VPJ	Hit	Z-IC	+8V, 1A		17b	TO-220	7808/TO-220	17b	... 7808... (TO-220)
HA 17809P,V,VP,VPJ	Hit	Z-IC	+9V, 1A		17b	TO-220	7809/TO-220	17b	... 7809... (TO-220)
HA 17810P,V,VP,VPJ	Hit	Z-IC	+10V, 1A		17b	TO-220	7810/TO-220	17b	... 7810... (TO-220)
HA 17812P,V,VP,VPJ	Hit	Z-IC	+12V, 1A		17b	TO-220	7812/TO-220	17b	... 7812... (TO-220)
HA 17815P,V,VP,VPJ	Hit	Z-IC	+15V, 1A		17b	TO-220	7815/TO-220	17b	... 7815... (TO-220)
HA 17818P,V,VP,VPJ	Hit	Z-IC	+18V, 1A		17b	TO-220	7818/TO-220	17b	... 7818... (TO-220)
HA 17824P,V,VP,VPJ	Hit	Z-IC	+24V, 1A		17b	TO-220	7824/TO-220	17b	... 7824... (TO-220)
HA 17885P,V,VP,VPJ	Hit	Z-IC	+8,5V, 1A		17b	TO-220			... 7885... (TO-220)
HA 178xx FM,FMP	Hit	Z-IC	=HA 17805...17885: Iso		17b	TO-220 Iso			... 78xx... (TO-220 Iso)
HA 17901(P)	Hit	KOP-IC	Quad, Serie 139, ±18V, 20mA, -20...+75°		14-DIP		(LM 339 N)[16]	14-DIP	... 139..., ... 239..., ... 339..., ... 2901...
HA 17901 FP,FPJ,RP	Hit	KOP-IC	=HA 17901(P,PJ): SMD		14-MDIP				... 139..., ... 239..., ... 339..., ... 2901...
HA 17901 G,PJ	Hit	KOP-IC	=HA 17901(P): -40...+85°		14-DIC,DIP				... 139..., ... 239..., ... 2901...
HA 17902(P)	Hit	OP-IC	Quad, Serie 124, 28V, 50mA, 0,19V/µs, -20...+75°		14-DIP		(LM 324 N)[16]	14-DIP	... 124..., ... 224..., ... 2902...
HA 17902 FP,FPJ	Hit	OP-IC	=HA 17902(P,PJ): SMD		14-MDIP				... 124..., ... 224..., ... 2902...
HA 17902 G,PJ	Hit	OP-IC	=HA 17902(P): -40...+85°		14-DIC,DIP				... 124..., ... 224..., ... 2902...
HA 17903(PS)	Hit	KOP-IC	Dual, Serie 193, ±18V, -20...+75°		8-DIP		(LM 393/8-D)[16]	8-DIP	... 193..., ...293..., ... 393..., ... 2903...
HA 17903 FP,FPJ	Hit	KOP-IC	=HA 17903(PS,PSJ): SMD		8-MDIP				... 193..., ...293..., ... 393..., ... 2903...
HA 17903 G,PSJ	Hit	KOP-IC	=HA 17903(PS): -40...+85°		8-DIC,DIP				... 193..., ...293..., ... 2903...

Original	Fabric.	Constr.	Info	{Compl. Fig.		JAEGER	Fig.	International
HA 17904 FP,FPJ	Hit	OP-IC	=HA 17904PS,PSJ: SMD	8-MDIP				... 158..., ... 258..., ... 358..., ... 2904...
HA 17904 GS	Hit	OP-IC	=HA 17904PS,PSJ: -40...+85°	8-DIC				... 158..., ... 258..., ... 2904...
HA 17904(PS)	Hit	OP-IC	Dual, Serie 158, ±16V, 50mA, 0,2V/µs, -20...+75°	8-DIP				... 158..., ... 258..., ... 358..., ... 2904...
HA 17904 PSJ	Hit	OP-IC	=HA 17904PS: -40...+85°	8-DIP				... 158..., ... 258..., ... 2904...
HA 17905 FM,FMP	Hit	Z-IC	Iso, -5V, 1A	17c	TO-220 Iso	(7905/TO-220)[3]	17c	... 7905... (TO-220 Iso)
HA 17906 FM,FMP	Hit	Z-IC	Iso, -6V, 1A	17c	TO-220 Iso			... 7906... (TO-220 Iso)
HA 17908 FM,FMP	Hit	Z-IC	Iso, -8V, 1A	17c	TO-220 Iso			... 7908... (TO-220 Iso)
HA 17909 FM,FMP	Hit	Z-IC	Iso, -9V, 1A	17c	TO-220 Iso			... 7909... (TO-220 Iso)
HA 17910 FM,FMP	Hit	Z-IC	Iso, -10V, 1A	17c	TO-220 Iso			... 7910... (TO-220 Iso)
HA 17912 FM,FMP	Hit	Z-IC	Iso, -12V, 1A	17c	TO-220 Iso	(7912/TO-220)[3]	17c	... 7912... (TO-220 Iso)
HA 17915 FM,FMP	Hit	Z-IC	Iso, -15V, 1A	17c	TO-220 Iso	(7915/TO-220)[3]	17c	... 7915... (TO-220 Iso)
HA 17952 FM,FMP	Hit	Z-IC	Iso, -5,2V, 1A	17c	TO-220 Iso			... 7952... (TO-220 Iso)
HA 19202	Hit	A/D-IC	4 Bit, Ucc=5V, 10MHz	22-DIP				-
HA 19203 MP	Hit	A/D-IC	4 Bit, Ucc=5V, 10MHz	18-MP				-
HA 19209 C,TP	Hit	A/D-IC	8 Bit Flash, VC, hi-speed, lo-power, Ucc=+5V,30MHz	28-DIC,DIP				-
HA 19209 MP	Hit	A/D-IC	=HA 19209C,TP: SMD	44-MP				-
HA 19210 C,TP	Hit	A/D-IC	8 Bit Flash, VC, hi-speed, lo-power, Ucc=+5V,30MHz	28-DIC,DIP				-
HA 19210 MP	Hit	A/D-IC	=HA 19210C,TP: SMD	44-MP				-
HA 19211(B)MP	Hit	A/D-IC	=HA 19211(B)P: SMD	44-MP				-
HA 19211(B)NT	Hit	A/D-IC	=HA 19211(B)P:	30-SDIP				-
HA 19211 P	Hit	A/D-IC	8 Bit Flash, VC, hi-speed, lo-power, Ucc=+5V,30MHz	28-DIP				-
HA 19212 MP	Hit	A/D-IC	=HA 19212P: SMD	44-MP				-
HA 19212 NT	Hit	A/D-IC	=HA 19212P:	30-SDIP				-
HA 19212 P	Hit	A/D-IC	8 Bit Flash, VC, hi-speed, lo-power, Ucc=+5V,30MHz	28-DIP				-
HA 19213 MP	Hit	A/D-IC	=HA 19213NT: SMD	28-MP				-
HA 19213 NT	Hit	A/D-IC	7 Bit Flash, hi-speed, lo-power, Ucc=+5V, 30MHz	30-SDIP				-
HA 19214 NT	Hit	A/D-IC	10 Bit Flash, VC,hi-speed, lo-power, Ucc=±5V,20MHz	42-SDIP				-
HA 19216(C)	Hit	A/D-IC	6 Bit Flash, hi-speed, Ucc=+5V, 30MHz	18-DIP,DIC				-
HA 19216 MP	Hit	A/D-IC	=HA 19216(C): SMD	28-MP				-
HA 19503 ANT	Hit	D/A-IC	6 Bit, Clock Generator, Ucc=+5V	30-SDIP				-
HA 19505	Hit	D/A-IC	10 Bit, Ucc=+5V, 50MHz	20-DIP				-
HA 19507 MP	Hit	D/A-IC	=HA 19507NT: SMD	28-MP				-
HA 19507 NT	Hit	D/A-IC	6 Bit, Clock Generator, Ucc=+5V	30-SDIP				-
HA 19508 A	Hit	D/A-IC	6 Bit, Ucc=+5V, 30MHz	16-DIP				-
HA 19508 AMP	Hit	D/A-IC	=HA 19508A: SMD	18-MP				-
HA 19510 A	Hit	D/A-IC	8 Bit Flash, hi-speed, lo-power, Ucc=+5V, 50MHz	18-DIP				-
HA 19510 AMP	Hit	D/A-IC	=HA 19510A: SMD	18-MP				-
HA 21001 MS	Hit	GaAs-IC	VHF/UHF Tuner, Ucc=8...10V	18-MP				-
HA 21008	Hit	GaAs-IC	BS Tuner, 0,95...2,05GHz, Ucc=4,5...5,5V	44	SOT-143			-
HA 21009 MS	Hit	GaAs-IC	BS Tuner, 0,95...2,05GHz, Ucc=4,5...5,5V	18-MP				-
HA 21010 MS	Hit	GaAs-IC	BS Tuner, 0,95...1,35GHz, Ucc=4,5...5,5V	18-MP				-
HA 118001 MP	Hit	LIN-IC	VC, FM Signal Processor	44-MP				-
HA 118002 FP	Hit	LIN-IC	Camera, Vorverst./Pre-Amp.	16-MDIP				-
HA 118003 MP	Hit	LIN-IC	=HA 118003NT: SMD	28-MP				-
HA 118003 NT	Hit	LIN-IC	Camera, Matrix-Verstärker/Amplifier	22-SDIP				-
HA 118010 MP	Hit	LIN-IC	Camera, 4-Kanal/Channel Processor	44-MP				-
HA 118019 NT	Hit	LIN-IC	VC, 4 Kopf-Vorverst./4-Head Pre-Amplifier	30-SDIP				-
HA 118041 NT	Hit	LIN-IC	VC, 2 Kopf-Vorverst./2-Head Pre-Amplifier	22-SDIP				-
HA 118058	Hit	LIN-IC	VC, Digital-Schalter/Switch	16-DIP				-
HA 118059	Hit	LIN-IC	VC(S-VHS), 3x Video-Schalter/Switch, Ucc=5V	16-DIP				-
HA 118059 FP	Hit	LIN-IC	=HA 118059: SMD	16-MDIP				-
HA 118070	Hit	LIN-IC	VC, Video-Schalter/Switch, Ucc=5V	8-DIP				-
HA 118070 FP	Hit	LIN-IC	=HA 118070: SMD	8-MDIP				-
HA 118082 MA	Hit	LIN-IC	Camera, 4-Kanal/Channel Processor	44-MP				-
HA 118084	Hit	LIN-IC	VC(VHS, S-VHS), Signal Processor, FM AGC	18-DIP				-
HA 118084 MP	Hit	LIN-IC	=HA 118084: SMD	18-MP				-
HA 118088	Hit	LIN-IC	VC, PIP Processor	22-SDIP				-
HA 118088 MP	Hit	LIN-IC	=HA 118088: SMD	28-MP				-
HA 118099	Hit	LIN-IC	VC(S-VHS), 3x Video-Schalter/Switch, Ucc=5V	16-DIP				-
HA 118099 FP	Hit	LIN-IC	=HA 118099: SMD	16-MDIP				-
HA 118104	Hit	LIN-IC	VC, 3x Video-Schalter/Switch, Ucc=5V	16-DIP				-
HA 118104 FP	Hit	LIN-IC	=HA 118104: SMD	16-MDIP				-
HA 118105 MA	Hit	LIN-IC	=HA 118105NT: SMD	56-MP				-
HA 118105(D)NT	Hit	LIN-IC	VC, 1-Chip VHS Processor	56-SDIP				-
HA 118118 MA	Hit	LIN-IC	Camera, Weissbalance/White Balance	44-MP				-
HA 118120 AMA	Hit	LIN-IC	Camera, Signal Processor	44-MP				-
HA 118121 FP,VFP	Hit	LIN-IC	SMD, Camera, EVF (Electronic View Finder)	16-MDIP				-
HA 118124 MA	Hit	LIN-IC	VC(VHS, S-VHS), Signal Processor	56-MP				-
HA 118129 MP	Hit	LIN-IC	FM IF, AGC, AFC, 430MHz	28-MP				-
HA 118142 AMA	Hit	LIN-IC	Camera, 4-Kanal/Channel Processor	44-MP				-
HA 118144 AF	Hit	LIN-IC	Camera, Signal Processor	48-MP				-
HA 118162 NT	Hit	LIN-IC	VC(S-VHS), 4 Kopf-Vorverst./4-Head Pre-Amplifier	30-SDIP				-
HA 118191 NT	Hit	LIN-IC	VC(VHS), 4 Kopf-Vorverst./4-Head Pre-Amplifier	30-SDIP				-
HA 118285 BF	Hit	LIN-IC	=HA 118285BNT: SMD	56-MP				-
HA 118285 BNT	Hit	LIN-IC	VC(VHS), Multistandard Processor	56-SDIP				-
HA 166008 FP	Hit	LIN-IC	=HA 166008MP:	24-MDIP				-
HA 166008 MP	Hit	LIN-IC	SMD, HDD, Schreib-Lese/Read-Write Proc., Ucc=5/12V	28-MP				-
HA 166009 MP	Hit	LIN-IC	SMD, HDD, Schreib-Lese/Read-Write Proc., Ucc=5/12V	28-MP				-
HA 166010 MP	Hit	LIN-IC	SMD, HDD, Schreib-Lese/Read-Write Proc., Ucc=5/12V	44-MP				-
HA 166024 FP	Hit	LIN-IC	SMD, HDD, Schreib-Lese/Read-Write Proc., Ucc=5V	16-MDIP				-
HA 166025 FP	Hit	LIN-IC	SMD, HDD, Schreib-Lese/Read-Write Proc., Ucc=5V	20-MDIP				-
HB....HZ								
HB		Si-N	=2SC3120 (SMD-Marking)	35	SOT-23			›2SC3120
HB		Si-N	=2SC3137 (Marking)	25	SOT-103			›2SC3137
HB		Si-N	=2SC4245 (SMD-Marking)	35(2mm)	SOT-323			›2SC4245
HB		Si-N	=2SD1464-HB (SMD-Marking)	39	SOT-89			›2SD1464
HB(s)		Si-N	=BFN 22 (SMD-Marking)	35	SOT-23			›BFN 22
HB		GaAs-FET	=CFY 75-13 (SMD-Marking)	44	SOT-143			-
HB		GaAs-N-FET-d	=CFY 65-14 (Marking)	51	SOT-173			›CFY 55
HBF 4000....4xxx	Sgs	CMOS-Logic	=HEF					
HC		Si-N	=2SC2733 (SMD-Marking)	35	SOT-23			›2SC2733
HC		Si-N	=2SC3121 (SMD-Marking)	35	SOT-23			›2SC3121

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
HC		Si-N	=2SC4246 (SMD-Marking)		35(2mm)	SOT-323			›2SC4246
HC		Si-N	=2SC4463 (SMD-Marking)		35(2mm)	SOT-323			›2SC4463
HC(s)		Si-P	=BFN 23 (SMD-Marking)		35	SOT-23			›BFN 23
HC		GaAs-FET	=CFY 75-15 (SMD-Marking)		44	SOT-143			-
HC 1 A3M…L2Q	Nec	Si-N+R	=AC 1A3M…L2Q: SMD		39b	SOT-89			-
HC 2000 H	Rca	Hybrid-IC	Op-Amp., 75V, 7A, PQ=100W(eff)						-
HC 2500	Rca	Hybrid-IC	Op-Amp., 75V, 7A, PQ=100W(eff)						-
HC 16701	Hit	LIN-IC	Thermal Head Driver, Ucc=5V, 0,1A		Chip				-
HD		Si-N	=2SC3122 (SMD-Marking)		35	SOT-23			›2SC3122
HD		Si-N	=2SC4249 (SMD-Marking)		35(2mm)	SOT-323			›2SC4249
HD 1 A3M…L3N	Nec	Si-N+R	=AD 1A3M…L3N: SMD		39b	SOT-89			-
HD 2 A3M…L3N	Nec	Si-N+R	=AD 2A3M…L3N: SMD		39b	SOT-89			-
HD 74 LSxx…	Hit	TTL-Logic	Standard TTL-Logic 74LS-Serie						… 74LSxx… (TTL)
HD 102		Si-N					BC 546	7a	
HD 105		Si-N			22a	TO-66	BD 243 C	17j	
HD 106		Si-N					BC 141	2a	
HD 107		Si-P					BC 161	2a	
HD 110		Si-P					BC 556	7a	
HD 140		Si-P					BC 556	7a	
HD 6350	Hit	I/O-IC	›KS 5824		24-DIP				KS 5824, MC 6850
HD 10551	Hit	LIN-IC	FM Frequ.-Teiler/Divider, 1:10…1:44		8-SIP				-
HD 14000….14xxx	Hit	CMOS-Logic	Standard CMOS-Logic 4000-Serie						… 4000… …4xxx (CMOS)
HD 17903 GS/PS	Hit	KOP-IC	Dual		8-DIC/DIP				›LM 2903
HD 38980 C	Hit	MOS-IC	Alarmuhr/Digital Clock, FLT Drv		40-DIP				-
HD 38991 A	Hit	MOS-IC	Alarmuhr/Digital Clock, LED Drv		40-DIP				-
HD 42851	Hit	MOS-IC	CB PLL Synthesizer		24-DIP				-
HD 42853	Hit	MOS-IC	CB PLL Synthesizer		22-DIP				-
HD 42854	Hit	MOS-IC	CB Scanner f.Kanalwahl/Channel Select		16/20-DIP				-
HD 42855	Hit	MOS-IC	CB Scanner f.Kanalwahl/Channel Select		16/20-DIP				-
HD 43880	Hit	MOS-IC	Analoguhr/Analog Clock (4MHz)		8-DIP				-
HD 43890	Hit	CMOS-IC	Tischuhr/Desk-top Clock		8-DIP				-
HD 44007(A)	Hit	CMOS-IC	Camera, Color Signal Processor (NTSC/PAL/SECAM)		28-DIP				-
HD 44015	Hit	LIN-IC	PLL Frequ. Synthesizer f. Digital Tuning		22-DIP				-
HD 44231 P	Hit	CMOS-IC	Telecom, A-Law Codec, Filter (Sync)		16-DIP				MB 6026A
HD 44232 P	Hit	CMOS-IC	Telecom, µ-Law Codec, Filter (Sync)		16-DIP				MB 6025A
HD 44235 C	Hit	CMOS-IC	Telecom, A-Law Codec, Filter (Sync)		16-DIP				MB 6056A
HD 44236 C	Hit	CMOS-IC	Telecom, µ-Law Codec, Filter (Sync)		16-DIP				MB 6055A
HD 44273 P	Hit	CMOS-IC	Telecom, A-Law Codec, Filter (Sync/Async)		16-DIP				MB 6022A
HD 44274 P	Hit	CMOS-IC	Telecom, µ-Law Codec, Filter (Sync/Async)		16-DIP				MB 6021A
HD 44277 P	Hit	CMOS-IC	Telecom, A-Law Codec, Filter (Sync/Async)		16-DIP				MB 6052A
HD 44278 P	Hit	CMOS-IC	Telecom, µ-Law Codec, Filter (Sync/Async)		16-DIP				MB 6051A
HD 44752	Hit	LIN-IC	PLL Frequ. Synthesizer Controller (AM/FM)		42-DIP				-
HD 44840		LIN-IC							-
HD 49201 A	Hit	MOS-IC	CD, Signal Processor, Udd=5V		80-MP				-
HD 49202 NT	Hit	CMOS-IC	CD, Digital Audio-Filter, Udd=5V		30-SDIP				-
HD 49211 BFS	Hit	CMOS-IC	R-DAT, Signal Prozessor, RAM/Converter Ctrl.		100-MP				-
HD 49212	Hit	CMOS-IC	R-DAT, Digital Servo, µComp. Interface		80-MP				-
HD 49215	Hit	MOS-IC	CD, Signal Processor, µComp. Interface, D/A Ctrl.		80-MP				-
HD 49217 AFS	Hit	MOS-IC	CD-ROM, Signal Processor, Double Speed Support		100-MP				-
HD 49226 AFS	Hit	CMOS-IC	R-DAT, Signal Processor, µComp.Interface, RAM Ctrl		100-MP				-
HD 49228 FS	Hit	CMOS-IC	R-DAT, Digital Servo, µComp. Interface		80-MP				-
HD 49229	Hit	CMOS-IC	R-DAT, Data Extractor, Clock Generator		56-MP				-
HD 49232 FS	Hit	MOS-IC	CD, Digital Signal Processor, µComp. Interface		80-MP				-
HD 49233 AFS	Hit	MOS-IC	CD, Signal Processor, µComp. Interface, RAM, DAC		80-MP				-
HD 49303	Hit	CMOS-A/D-IC	8 Bit, TV/VC, hi-speed, lo-power, Udd=+5V, 20MHz		30-DIP				-
HD 49304(ANT)	Hit	CMOS-D/A-IC	TV, 8 Bit, 3 Channel, Udd=+5V, 50MHz		42-SDIP				-
HD 49306 AF	Hit	CMOS-A/D-IC	TV, 9 Bit, Udd=+5V		48-MP				-
HD 49307	Hit	CMOS-D/A-IC	TV, 8 Bit, 3 Channel, Udd=+5V, >30MHz		56-MP				-
HD 49315 F	Hit	CMOS-A/D-IC	VC,Camera, 10 Bit, Digital Video		48-MP				-
HD 49409 FS	Hit	LIN-IC	TV,VC, PIP Control, A/D-D/A Converter		100-MP				-
HD 49412 FS	Hit	LIN-IC	TV,VC, PIP Control (NTSC), A/D-D/A Converter		100-MP				-
HD 49417 AFS	Hit	LIN-IC	TV,VC, MUSE Decoder		100-MP				-
HD 49420 FS	Hit	LIN-IC	TV,VC, PIP Control (NTSC), A/D-D/A Converter		80-MP				-
HD 49421 FS	Hit	LIN-IC	TV,VC, PIP Control (NTSC), A/D-D/A Converter		80-MP				-
HD 49704 FP	Hit	CMOS-IC	VC, VHS-C, Servo-Controller		80-MP				-
HD 49723	Hit	LIN-IC							KA 8307
HD 49733 NT	Hit	CMOS-IC	VC, Servo-Controller		56-SDIP				-
HD 49740 NT	Hit	MOS-IC	VC, ON-Screen Display		42-SDIP				-
HD 49741 NT	Hit	CMOS-IC	VC, Servo-Controller		56-SDIP				-
HD 49748	Hit	CMOS-IC	›KA 8316		56-SDIP				KA 8316
HD 49781 F	Hit	CMOS-IC	=HD 49781NT: SMD		56-MP				-
HD 49781 NT	Hit	CMOS-IC	VC, Servo-Controller		56-SDIP				-
HD 49783 FP	Hit	CMOS-IC	=HD 49783NT: SMD		16-MDIP				-
HD 49783 NT	Hit	CMOS-IC	VC, Synchronized Serial Bus		16-DIP				-
HD 49801 FB	Hit	CMOS-IC	Camera, Digital Signal Processor		100-MP				-
HD 61927	Hit	MOS-IC	Camera, Color Signal (NTSC)		22-DIP				-
HD 64951	Hit	BiMOS-I/O-IC	µComp., SCSI Interface		68-MP				-
HD 64961	Hit	CMOS-I/O-IC	µComp., SCSI Controller						-
HD 153007	Hit	MOS-IC	Min, HDD, 2-7 Code Encoder/Decoder		44-MP				-
HD 153009	Hit	MOS-IC	Min, HDD, 2-7 Code Encoder/Decoder		44-MP				-
HD 153011	Hit	MOS-IC	Min, HDD, 2-7 RLL Encoder/Decoder		44-MP				-
HD 153013	Hit	MOS-IC	Min, HDD, 2-7 Code Encoder/Decoder		44-MP				-
HD 153510 F50,F135	Hit	D/A-IC	8 Bit, 3 Kanal/Channel, 50/135MHz		56-MP				-
HD 431115	Hit	MOS-IC	Analoguhr/analog clock (4MHz)		8-DIP				-
HD 440072	Hit	CMOS-IC	Camera, Color Signal Processor (NTSC/PAL/SECAM)		28-DIP				-
HDA-0505…-2415	Shi	Hybrid-IC	DC-DC Converter		≈7-SIP	(22x40mm)			-
HDB-0505…-2415	Shi	Hybrid-IC	DC-DC Converter		≈7-SIP	(25x45mm)			-
HDF-0515…-4815	Shi	Hybrid-IC	DC-DC Converter		≈7-SIP	(45x21mm)			-
HE		Si-N	=2SC3123 (SMD-Marking)		35	SOT-23			›2SC3123
HE		Si-N	=2SC4250 (SMD-Marking)		35(2mm)	SOT-323			›2SC4250
HEF 4000….4xxx	Phi	CMOS-Logic	Standard CMOS-Logic 4000-Serie						… 4000… …4xxx (CMOS)

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
HEF 4750 VD	Phi	MOS-IC	VHF/UHF Frequ.-Synthesizer, >1GHz		28-DIC				-
HEF 4751 VD	Phi	MOS-IC	=HEF 4751VP: Keramik		28-DIC				-
HEF 4751 VP	Phi	MOS-IC	Frequ.-Teiler/Divider f. HEF 4750		28-DIP				-
HEF 4751 VT	Phi	MOS-IC	=HEF 4751VP: SMD		28-MDIP				-
HF		Si-N	=2SC2805 (Marking)		25	SOT-103			›2SC2805
HF		Si-N	=2SC3124 (SMD-Marking)		35	SOT-23			›2SC4251
HF		Si-N	=2SC4251 (SMD-Marking)		35(2mm)	SOT-323			›2SC4251
HF		Si-P	=BFN 23 (SMD-Marking)		35	SOT-23			›BFN 23
HF		Si-N	=KTC 3882 (SMD-Marking)		35	SOT-23			›KTC 3882
HFSD-1 A....Z	Sak	Si-Di	FRr, 200...1000V, 0,3A, Uf<1,2V(0,5A), <800ns HFSD-1=400V, A=600V, B=800V, C=1000C, Z=200V		31a	(6x11mmØ)	BA 159	31a	BA 157...159, BY 204/..., BY 208/..., ++
HG		Si-N	=2SC2806 (Marking)		25	SOT-103			›2SC2806
HG		Si-N	=2SC3439-G (SMD-Marking)		39	SOT-89			›2SC3439
HGE 122...24005	Shi	Hybrid-IC	DC-DC Converter		Module				-
HGF 051...12001	Shi	Hybrid-IC	DC-DC Converter		Module				-
HGG 122...24005	Shi	Hybrid-IC	DC-DC Converter		Module				-
HH		Si-N	=2SC4253 (SMD-Marking)		35(2mm)	SOT-323			›2SC4253
HH		Si-N	=2SC3125 (SMD-Marking)		35	SOT-23			›2SC3125
HH		Si-N	=2SC3439-H (SMD-Marking)		39	SOT-89			›2SC3439
HH		Si-N	=KTC 3881 (SMD-Marking)		35	SOT-23			›KTC 3881
HH 8090 B	Mat	Hybrid-IC	Schaltregler/Switching Regulator		≈10-SIP				-
HH 8360	Mat	Hybrid-IC	8-Bit D/A-Converter		≈13-SIL				-
HI		Si-N	=2SC4247 (SMD-Marking)		35(2mm)	SOT-323			›2SC4247
HI		MOS-N-FET-d	=3SK188 (SMD-Marking)		44	SOT-143			›3SK188
HIT 5609....5610		Si-N/P	›CS 5609...5610				›CS 5609-5610		
HIT 9010....9022		Si-N/P	›CS 9010...9022				›CS 9010-9022		
HJ		Si-N	=2SC3439-J (SMD-Marking)		39	SOT-89			›2SC3439
HJ		Si-N	=2SC3602 (Marking)		25	SOT-103			›2SC3602
HK		Si-N	=2SC3828 (SMD-Marking)		44	SOT-143			›2SC3828
HK		Si-N	=2SD1006-HK (SMD-Marking)		39	SOT-89			›2SD1006
HKZ 101(S)	Sie	LIN-IC	Hall-IC, Magnet-Gabelschranke/Vane Switch						-
HKZ 121	Sie	LIN-IC	Hall-IC, Magnet-Gabelschranke/Vane Switch						-
HL		Si-P	=2SA1502 (SMD-Marking)		35	SOT-23			›2SA1502
HL		Si-P	=2SA1722 (SMD-Marking)		35(2mm)	SOT-323			›2SA1722
HL		Si-N	=2SC3862 (SMD-Marking)		35	SOT-23			›2SC3862
HL		Si-N	=2SD1006-HL (SMD-Marking)		39	SOT-89			›2SD1006
HLD 00006...05003	Shi	Hybrid-IC	DC-DC Converter		Module				-
HLE 00006...12003	Shi	Hybrid-IC	DC-DC Converter		Module				-
HM		Si-N	=2SC3547B (SMD-Marking)		35	SOT-23			›2SC3547B
HM		Si-N	=2SC4248 (SMD-Marking)		35(2mm)	SOT-323			›2SC4248
HM		Si-N	=2SD1006-HM (SMD-Marking)		39	SOT-89			›2SD1006
HM 6514		sRAM-IC	1k x 4 Bit						US 224D20
HM 53051 FP-...	Hit	CMOS-RAM-IC	=HM 53051P: SMD		28-MDIP				-
HM 53051 P-...	Hit	CMOS-RAM-IC	TV,VC, 262144x4 Bit, Frame Memory, 34, 45, 60ns		18-DIP				-
HM 53461 JP-...	Hit	CMOS-VRAM-IC	=HN 53461P: SMD			24-MDIP			-
HM 53461 P-...	Hit	CMOS-VRAM-IC	TV,VC, 65536x4 Bit, Multiport Video RAM,100...150ns			24-DIP			-
HM 53461 ZP-...	Hit	CMOS-VRAM-IC	=HN 53461P: Fig. ›			24-SQP			-
HM 53462 JP-...	Hit	CMOS-VRAM-IC	=HN 53462P: SMD			24-MDIP			-
HM 53462 P-...	Hit	CMOS-VRAM-IC	TV,VC, 65536x4 Bit, Multiport Video RAM,100...150ns			24-DIP			-
HM 53462 ZP-...	Hit	CMOS-VRAM-IC	=HN 53462P: Fig. ›			24-SQP			-
HM 63021 FP-...	Hit	RAM-IC	=HM 63021P: SMD		28-MDIP				-
HM 63021 P-...	Hit	RAM-IC	TV,VC, 2048x8 Bit, Line Memory, 28, 34, 45ns		28-DIP				-
HM 530281 TT-...	Hit	CMOS-RAM-IC	TV,VC, 331776x8 Bit, Frame Memory,20, 25, 34, 45ns		44-SMDIP				-
HM 530283 FP-...	Hit	CMOS-RAM-IC	TV,VC, 331776x8 Bit, Frame Memory,20, 25, 34, 45ns		32-MDIP				-
HN		Si-N	=2SC4214 (SMD-Marking)		44	SOT-143			›2SC4214
HN		Si-N	=2SC4244 (SMD-Marking)		35(2mm)	SOT-323			›2SC4244
HN 1 AO1F	Tos	Si-P	SMD, Dual, 50/50V, 0,15A, >80MHz		46	SOT-163			-
HN 1 AO1FU	Tos	Si-P	=HN 1 AO1F:		46(2mm)	SOT-363			-
HN 1 BO1F	Tos	Si-N/P	SMD, NPN+PNP, 60/50+50/50V, 0,15A, 150+120MHz		46	SOT-163			-
HN 1 BO1FU	Tos	Si-N/P	=HN 1 BO1F:		46(2mm)	SOT-363			-
HN 1 CO1F	Tos	Si-N	SMD, Dual, 60/50V, 0,15A, >80MHz		46	SOT-163			-
HN 1 CO1FU	Tos	Si-N	=HN 1 CO1F:		46(2mm)	SOT-363			-
HN 1 CO3F	Tos	Si-N	SMD, Dual, 50/20V, hi-Ueb=25V, 0,3A, 30MHz		46	SOT-163			-
HN 1 CO3FU	Tos	Si-N	=HN 1 CO3F:		46(2mm)	SOT-363			-
HN 2 AO1FU	Tos	Si-P	SMD, Dual, 50/50V, 0,15A, >80MHz		46(2mm)	SOT-363			-
HN 2 CO1FU	Tos	Si-N	SMD, Dual, 60/50V, 0,15A, >80MHz		46(2mm)	SOT-363			-
HN 3 BO1F	Tos	Si-P/N	SMD, PNP+NPN, 60/50+50/50V, 0,15A, 150+120MHz		46	SOT-163			-
HN 3 CO1F	Tos	Si-N	SMD, Dual, VHF, 30/20V, 50mA, 1400MHz		46	SOT-163			-
HN 3 CO2F	Tos	Si-N	SMD, Dual, UHF, 30/15V, 50mA, 2400MHz		46	SOT-163			-
HN 3 CO3F	Tos	Si-N	SMD, Dual, UHF, 20/12V, 30mA, 4000MHz		46	SOT-163			-
HN 3 CO6F	Tos	Si-N	SMD, Dual, UHF, 20/12V, 80mA, 7000MHz, F<2dB(1GHz)		46	SOT-163			-
HN 3 CO7F	Tos	Si-N	SMD, Dual, UHF, 20/10V, 40mA, 10GHz, F=1,7dB(2GHz)		46	SOT-163			-
HN 3 CO8F	Tos	Si-N	SMD, Dual, UHF, 20/10V, 15mA, 10GHz, F=1,8dB(2GHz)		46	SOT-163			-
HN 3 G01J	Tos	N-FET+Si-N	SMD, N-FET(20V)+NPN-Trans(60/50V, 0,15A)		45	SOT-153			-
HO		Si-P	=2SA1203-O (SMD-Marking)		39	SOT-89			›2SA1203
HO		Si-P	=KTA1663-O (SMD-Marking)		39	SOT-89			›KTA 1663
HP		Si-P	=2SA1036-HP (SMD-Marking)		≈35	(MMT)			›2SA1036
HP		Si-P	=2SA1036K-P (SMD-Marking)		35	SOT-23			›2SA1036K
HP		Si-P	=2SA1577-P (SMD-Marking)		35(2mm)	SOT-323			›2SA1577
HP		Si-N	=2SC4527 (SMD-Marking)		35	SOT-23			›2SC4527
HP		Si-N	=2SD1007-HP (SMD-Marking)		39	SOT-89			›2SD1007
HP 5082-4657		Opto							
HPA 72 R	Say	Si-N+Di	HA, 1500/800, 7/16A, 60W, sat<5V(4A)		18c	TO-3P Iso	BU 508DF	16c	BU 508DF, 2SC3892A, 2SC4123...24, 2SD2251
HPA 100 R	Say	Si-N	HA, hi-def, 1500/800V, 10/25A, 150W, sat<5V(6A)		77j	TOP-3L			2SC3995, 2SC4288A
HPA 150 R	Say	Si-N	HA, hi-def, 1500/800V, 15/35A, 150W, sat<5V(10A)		77j	TOP-3L			2SC3996, 2SC4289A
HPG 8	Gie	Si-Di	kV-Rr, 8kV, 0,05A		31a	(47x5x6)			1N5184
HPG 10	Gie	Si-Di	=HPG 8: 10kV, 0,04A		31a	(47x5x6)			1N5184
HPG 15	Gie	Si-Di	=HPG 8: 15kV, 0,03A		31a	(47x5x6)			1N3054
HPG 20	Gie	Si-Di	=HPG 8: 20kV, 0,02A		31a	(47x5x6)			1N3056
HQ		Si-P	=2SA1036-HQ (SMD-Marking)		≈35	(MMT)			›2SA1036
HQ		Si-P	=2SA1036K-Q (SMD-Marking)		35	SOT-23			›2SA1036K
HQ		Si-P	=2SA1577-Q (SMD-Marking)		35(2mm)	SOT-323			›2SA1577

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
HQ		Si-P	=2SB956-Q (SMD-Marking)		39	SOT-89			›2SB956
HQ		Si-N	=2SC3928-Q (SMD-Marking)		35	SOT-23			›2SC3928
HQ		Si-N	=2SC4155-Q (SMD-Marking)		35(2mm)	SOT-323			›2SC4155
HQ		Si-N	=2SD1007-HQ (SMD-Marking)		39	SOT-89			›2SD1007
HQ 1 A3M…L3N	Nec	Si-P+R	=AQ 1A3M…L3N: SMD		39b	SOT-89			-
HR		Si-P	=2SA1035-R (SMD-Marking)		35	SOT-23			›2SA1035
HR		Si-P	=2SA1036-HR (SMD-Marking)		=35	(MMT)			›2SA1036
HR		Si-P	=2SA1036K-R (SMD-Marking)		35	SOT-23			›2SA1036K
HR		Si-P	=2SA1531A-R (SMD-Marking)		35(2mm)	SOT-323			›2SA1531A
HR		Si-P	=2SA1577-R (SMD-Marking)		35(2mm)	SOT-323			›2SA1577
HR		Si-P	=2SB956-R (SMD-Marking)		39	SOT-89			›2SB956
HR		Si-N	=2SC3928-R (SMD-Marking)		35	SOT-23			›2SC3928
HR		Si-N	=2SC4155-R (SMD-Marking)		35(2mm)	SOT-323			›2SC4155
HR		Si-N	=2SD1007-HR (SMD-Marking)		39	SOT-89			›2SD1007
HR 1 A3M…L3N	Nec	Si-P+R	=AR 1A3M…L3N: SMD		39b	SOT-89			-
HR 5 A,B	Hit	Si-Di	Rr, Uni, A=100, B=200V, 0,4/3A, Uf<1,1V(0,4A)		31a	DO-39	BA 159	31a	BA 157…159, BY 204/…, BY 208/…, ++
HR 51….		Si-Di	=1N4001…4007				1N4007	31a	›1N4001…4007
HR 100(R)	Tho	Si-Di	Rr, Uni, 100V, 3A, Uf<1V(3A), R: <3µs		31a	DO-27A	RGP 30 M	31a	BY 251…255, GP 30B…M, 1N5401…08, ++
HR 200(R)	Tho	Si-Di	=HR 100: 200V		31a	DO-27A	RGP 30 M	31a	BY 251…255, GP 30D…M, 1N5402…08, ++
HR 400(R)	Tho	Si-Di	=HR 100: 400V		31a	DO-27A	RGP 30 M	31a	BY 252…255, GP 30G…M, 1N5404…08, ++
HR 400(R)		Si-Di	=BYX 71/350		26	SOD-38	BY 329/1200[4]	17k	›BYX 71/350
HR 600(R)	Tho	Si-Di	=HR 100: 600V		31a	DO-27A	RGP 30 M	31a	BY 253…255, GP 30J…M, 1N5406…08, ++
HR 800(R)	Tho	Si-Di	=HR 100: 800V		31a	DO-27A	RGP 30 M	31a	BY 254…255, GP 30K…M, 1N5407…08, ++
HR 1000(R)	Tho	Si-Di	=HR 100: 1000V		31a	DO-27A	RGP 30 M	31a	BY 255, GP 30M, MR 510, 1N5408, ++
HS		Si-P	=2SA1035-S (SMD-Marking)		35	SOT-23			›2SA1035
HS		Si-P	=2SA1531A-S (SMD-Marking)		35(2mm)	SOT-323			›2SA1531A
HS		Si-P	=2SB956-S (SMD-Marking)		39	SOT-89			›2SB956
HS		Si-N	=2SC3928-S (SMD-Marking)		35	SOT-23			›2SC3928
HS		Si-N	=2SC4155-S (SMD-Marking)		35(2mm)	SOT-323			›2SC4155
HS		Si-N	=2SD2540 (SMD-Marking)		39	SOT-89			›2SC2540
HS 15		Se-Di	=TV 11						TV 11
HS 5305….5308(A)	Gen	Si-N	=2N5305…5308(A): 0,9W		7c°	TO-92+Clip			›2N5305…5308(A)
HS 5810….5823	Gen	Si-N/P	=2N5810…5823: 0,7W		7a°	TO-92+Clip			›2N5810…5823
HS 6010….6017	Gen	Si-N/P	=2N6010…6017: 0,7W		7a°	TO-92+Clip			›2N6010…6017
HS 6018….6021	Gen	Si-N	=2N6018…6021: 0,7W		7a°	TO-92+Clip			›2N6018…6021
HSG 3020…3250	Sgs	CMOS-IC	HCMOS Gate Arrays						-
HSG 5080…5600	Sgs	CMOS-IC	HCMOS Gate Arrays						-
HT		Si-P	=2SA1035-T (SMD-Marking)		35	SOT-23			›2SA1035
HT		Si-P	=2SA1531A-T (SMD-Marking)		35(2mm)	SOT-323			›2SA1531A
HT		Si-P	=2SB956-T (SMD-Marking)		39	SOT-89			›2SB956
HT		Si-N	=2SC3928-T (SMD-Marking)		35	SOT-23			›2SC3928
HT		Si-N	=2SC4155-T (SMD-Marking)		35(2mm)	SOT-323			›2SC4155
HT 2	Fer	Si-N	SMD, Uni, 90V, 0,1A, 0,3W, <500/2000ns		35a	SOT-23			2SC4050
HT 3	Fer	Si-P	SMD, Uni, 90V, 0,1A, 0,3W, <500/1000ns		35a	SOT-23			2SA1566
HV 10		Si-Di	=BA 127		31a		1N4148	31a	›BA 127
HV 13		Si-Di	=BA 127		31a		1N4148	31a	›BA 127
HV 15	Hit	Ge-St	10mA, 0,15W, Uf=0,145V(1,5mA)		2	TO-1			-
HV 16	Hit	Ge-St	10mA, 0,25W, Uf=0,145V(2,3mA)		2	TO-1			-
HV 17(C)	Hit	Ge-St	20mA, 0,5W, Uf=0,145V(3,5mA)		2	TO-1			-
HV 18	Hit	Ge-St	10mA, 0,1W, Uf=0,145V(1mA)		2	TO-1			-
HV 23 D,E,F	Hit	Si-St	20V, 50mA, Uf=0,66…0,8V(3mA) D=0,66…0,75V, E=0,73…0,9V, F=0,66…0,8V		9c	(6x6x3,5)	(1N4148)	31a	BA 216, BA 314
HV 23 G	Hit	Si-St	3V, 10mA, Uf=0,58…0,69V(3mA)		31a	DO-35	(1N4148)	31a	BA 216, BA 314
HV 25		Si-Di	=BA 127		31a		1N4148	31a	›BA 127
HV 26	Hit	Si-St	200mA, Uf=0,68…0,75V(30mA)		31a		(1N4148)	31a	BA 220, BZ 102/0V7, BZX 55/C0V8
HV 46		C-Di	=BA 102		31a				›BA 102
HV 46(RD)	Hit	Si-St	3V, 10mA, Uf=1,17…1,4V(3mA)		31a		Z-Diode 1,4V	31a	BZV 86/1V4, BZX 75/C1V4, ZTE 1,5
HV 70	Hit	Si-St	5V, 50mA, 0,25W, Uf=0,61…0,81V(0,5mA)		31a	DO-35	(1N4148)	31a	BA 216, BA 314
HV 75	Hit	Si-St	2,5V, 1A, Uf=0,77…0,87V(100mA)		31a	DO-41			BZW 22/C1, ZPY 1, ZY 1
HV 80	Hit	Si-St	10V, 50mA, 0,25W, Uf=0,55…0,75V(3mA)		31a	DO-35	(1N4148)	31a	BA 216, BA 314…315
HV 100	Hit	Si-St	100V, 0,38W, Uf=70…115V(1mA)		31a	(6x14mmØ)			-
HVG 1	Gie	Si-Di	kV-Rr, 1kV, 0,3A, Uf<3V(1A), 2µs		31a	SOD-57			GP 02-20, MR 250-2, 1N1732(A)
HVG 2	Gie	Si-Di	=HVG 1: 2kV, 0,3A		31a	SOD-57			GP 02-20, MR 250-2, 1N1732(A)
HVG 3	Gie	Si-Di	=HVG 1: 3kV, 0,25A, Uf<4V(1A)		31a	SOD-57			GP 02-30, MR 250-3, 1N1733(A)
HVG 4	Gie	Si-Di	=HVG 1: 4kV, 0,2A, Uf<6V(1A)		31a	SOD-57			GP 02-40, MR 250-4, 1N1734(A)
HVG 5	Gie	Si-Di	=HVG 1: 5kV, 0,15A, Uf<8V(1A)		31a	SOD-57			MR 250-5, 1N1734(A)
HVT 15(SS)	Sak	Si-Di	kV-Rr, 11kV, 15mA, Uf<32V(10mA)		31a	(12x4mmØ)	(BY 713)	31a	HS 10
HVT 18	Sak	Si-Di	kV-Rr, 12kV, 15mA		31a	(16x5,5Ø)	(BY 713)	31a	HS 10
HVT 20(SS)	Sak	Si-Di	kV-Rr, 14kV, 15mA, Uf<42V(10mA)		31a	(12x4mmØ)	(BY 713)	31a	HS 13
HVT 22	Sak	Si-Di	kV-Rr, 14kV, 15mA, Uf<25V(10mA)		31a	(16x5,5Ø)	(BY 713)	31a	HS 13
HVT 25(SS)	Sak	Si-Di	kV-Rr, 17kV, 15mA, Uf<52V(10mA)		31a	(12x4mmØ)	BY 713	31a	HS 13
HVT 30(E,S,SS)	Sak	Si-Di	kV-Rr, 18…24kV, 10mA, Uf<75V(10mA)		31a	(15x4mmØ)	(BY 713)	31a	-
HX		Si-P	=2SB1572-HX (SMD-Marking)		39	SOT-89			›2SB1572
HY		Si-P	=2SA1203-Y (SMD-Marking)		39	SOT-89			›2SA1203
HY		Si-P	=2SB1572-HY (SMD-Marking)		39	SOT-89			›2SB1572
HY		Si-P	=KTA1663-Y (SMD-Marking)		39	SOT-89			›KTA 1663
HYB 4116 A-3	Sie	dRAM-IC	16384x1 Bit, 200ns		16-DIP				….4116-….
HYB 4116 A-4	Sie	dRAM-IC	=HYB 4116A-3: 250ns		16-DIP				….4116-….
HYB 4116-P2	Sie	dRAM-IC	16384x1 Bit, 150ns		16-DIP				….4116-….
HYB 4116-P3	Sie	dRAM-IC	=HYB 4116-P2: 200ns		16-DIP				….4116-….
HYB 4116 -P4,P-4	Sie	dRAM-IC	=HYB 4116-P2: 250ns		16-DIP				….4116-….
HYB 4164-P1	Sie	dRAM-IC	65536x1 Bit, 120ns		16-DIP				….4164-….
HYB 4164-P2	Sie	dRAM-IC	=HYB 4164-P1: 150ns		16-DIP				….4164-….
HYB 4164-P3	Sie	dRAM-IC	=HYB 4164-P1: 200ns		16-DIP				….4164-….
HYB 41256-12	Sie	dRAM-IC	262144x1 Bit, 120ns		16-DIP				….41256-….
HYB 41256-15	Sie	dRAM-IC	=HYB 41256-12: 150ns		16-DIP				….41256-….
HYB 41256-20	Sie	dRAM-IC	=HYB 41256-12: 200ns		16-DIP				….41256-….
HYB 511000-12	Sie	dRAM-IC	=HYB 511000-10: 120ns		18-DIP				…41024-…
HYB 511000-10	Sie	dRAM-IC	1048576x1 Bit, 100ns, page mode		18-DIP				…41024-…
HZ		Si-P	=2SB1572-HZ (SMD-Marking)		39	SOT-89			›2SB1572
HZ 1 C3	Hit	Z-Di	1,5…1,7V(5mA), 0,5W		31a	DO-35			-

Original	Fabric.	Constr.	Info	{Compl.	Fig.		JAEGER	Fig.	International
HZ 2…36(H) ….	Hit	Z-Di	2…36V, 0,5W, A≈-15…-7%, B≈-10…0%, C≈-2…+8%, (A,B,C)1,2,3: engere Toleranzen/tighter tolerances		31a	DO-35	Z-Diode ….V	31a	BZV 85/…, BZX 55/…, BZX 83/…, ZPD…,+
HZ 2.7…39E(B1…4)	Hit	Z-Di	2,7…39V, 0,5W, B1≈-8…-4%, B2≈-5…-1%, B3≈-2…+3% B4≈-1…+3%		31a	DO-35	Z-Diode ….V	31a	BZV 85/…, BZX 55/…, BZX 83/…, ZPD…,+
HZ 6…36(….)L	Hit	Z-Di	In, 6…36V, 0,4W, A≈-12…-6%, B≈-8…0%, C≈0…+8% (A,B,C)1,2,3L: engere Toleranzen/tighter toleranc.		31a	DO-35	(Z-Diode ….V)	31a	BZV 39/…, 1N4099…4122
HZ 2…5(A,B,C)LL	Hit	Z-Di	In, 2…5V, 0,25W, A≈-10…0%, B≈±5%, C≈0…+10%		31a	DO-35	(Z-Diode ….V)	31a	BZV 39/…, 1N4615…25
HZ 2.0…36(B,C)P	Hit	Z-Di	2,0…36V, 0,8W, BP≈-6…+6%, CP≈0…+12%		31a	DO-41	Z-Diode ….V	31a	BZV 85/…, BZW 22/…, BZX 61/…, ZPY…,+
HZF 2.0…36(B,C)P	Hit	Z-Di	=HZ 2.0…36(B,C)P: SMD, 0,9W		71a(5mm)				BZG 03-…, MA 1Z…, PTZ…, RD…FM
HZK 2…36 A,B,C	Hit	Z-Di	=HZ 2…36(H)A,B,C: SMD, 0,5W		72a(3,4mm)	SOD-80	Z-Di …V(SMD)	72a(3,4mm)	BZD 27/…, BZV 55/…, RLZ …(J)
HZK 6…36(A,B,C)L	Hit	Z-Di	=HZ 6…36(A,B,C)L: SMD, 0,4W		72a(3,4mm)	SOD-80	Z-Di …V(SMD)	72A(3,4mm)	-
HZK 2…5(A,B,C)LL	Hit	Z-Di	=HZ 2…5(A,B,C)LL: SMD, 0,25W		72a(3,4mm)	SOD-80			-
HZM 2.0…36N(B…)	Hit	Z-Di	SMD, 2,0…36V, B≈-5…+5%, B1≈-5…-1%, B2≈-3…-2% B3≈+1…+5%		35p	SOT-23			BZX 84/…, RD …M
HZS 2…36 ….	Hit	Z-Di	=HZ 2…36(H)…: 0,4W		31a	DO-34	›HZ 2…36(H)		›HZ 2…36(H)…
HZS 2.7…39E….	Hit	Z-Di	=HZ 2.7…39E…: 0,4W		31a	DO-34	›HZ2.7…39E…		›HZ 2.7…39E…
HZS 5.6…36J(B…)	Hit	Z-Di	5,6…36V, 0,4W, B1≈-6…-1%, B2≈±2,5%, B3≈0…+5%		31a	DO-34	Z-Diode ….V	31a	BZV 85/…, BZX 55/…, BZX 83/…, ZPD…,+
HZS 6…36 L…	Hit	Z-Di	=HZ 6…36L…: 0,4W		31a	DO-34	›HZ 6…36L…		›HZ 6…36L…
HZS 2…5 LL…	Hit	Z-Di	=HZ 2…5LL…: 0,25W		31a	DO-34	›HZ 2…5LL…		›HZ 2…5LL…
HZS 2.0…39N(B…)	Hit	Z-Di	2,0…39V, 0,4W, B1≈-8…-4%, B2≈-5…0%, B3≈-2…+3% B4≈-2…+1%		31a	DO-35	Z-Diode ….V	31a	BZV 85/…, BZX 55/…, BZX 83/…, ZPD…,+
HZS 5.6…36S….	Hit	Z-Di	=HZS 5.6…36J…: 0,4W		31a	DO-34	›HZS 5.6…36J		›HZS 5.6…36J…
HZT 33	Hit	Z-IC, Ref-Di	Tuner Stabi, 31…35V, 20mA, 0,4W, ±1mV/°C(≈ZTK 33)		31h		ZTK 33	31h	›ZTK 33
HZU 2.0…36….	Hit	Z-Di	=HZM 2.0…36N…:		71a(1,7mm)	SOD-323			DTZ …, RD …S
I									
I		GaAs-N-FET	=2SK1196 (Marking)		51	SOT-173			›2SK1196
I C		Si-N+R	=UN 7231 (SMD-Marking)		39	SOT-89			›UN 7231
I 9		Si-Di	=1SS336 (SMD-Marking)		35	SOT-23			›1SS336
i 1103	Int	dRAM-IC	1024 Bit		18-DIP				U 253D
i 1302	Int	ROM-IC	2048 Bit		24-DIP				U 501D
i 1602 A	Int	PROM-IC	256x8 Bit		24-DIP				U 551D
i 1702 A	Int	EPROM-IC	256x8 Bit		24-DIP				U 552C
i 2102 A	Int	sRAM-IC	1024 Bit		16-DIP				U 202D
i 2114	Int	sRAM-IC	1024x4 Bit		18-DIP				… 2114…, U 214D
i 2115	Int	sRAM-IC	1024x1 Bit		16-DIP				U 215D
i 2124	Int	sRAM-IC	1024x4 Bit		18-DIP				U 224D, UL 224D, US 224D, VL 224D
i 2125	Int	sRAM-IC	1024x1 Bit		16-DIP				U 225D
i 2147 H	Int	sRAM-IC	4096x1 Bit		18-DIP				… 2147…
i 2148	Int	sRAM-IC	1024x4 Bit		18-DIP				… 2148…, U 2148C
i 2308	Int	ROM-IC	8192-Bit, mask.-progr.		24-DIP				U 505D
i 2364	Int	ROM-IC	8192x8 Bit		28-DIP				MN 2364, U 2364D
i 2616	Int	PROM-IC	2048x8 Bit		24-DIP				U 2616D
i 2708	Int	EPROM-IC	1024x8 Bit		24-DIP				U 555C
i 2716	Int	EPROM-IC	2048x8 Bit		24-DIP				… 2716…, U 2716C
i 2764	Int	EPROM-IC	8192x8 Bit, 200ns		28-DIP				… 2764…
i 3245	Int	I/O-IC	=µA 9645						›µA 9645
i 4016	Int	sRAM-IC	2048x8 Bit		24-DIP				MN 4216, MN 4316
i 8008	Int	µP-IC	8-Bit-CPU		18-DIP				U 808D
i 8205	Int	TTL-IC	Schottky, 1/8-Binärdecoder/Binary Decoder		16-DIP				DS 8205D
i 8212	Int	TTL-IC	Schottky, 8-Bit Bustreiber/Bus Driver		24-DIP				DS 8212D
i 8216	Int	TTL-IC	Schottky, 4-Bit Bustreiber/Bus Driver		16-DIP				DS 8216D
i 8272	Int	I/O-IC	Floppy Disk Controller		40-DIP				U 8272D
i 8282	Int	TTL-IC	Schottky, 8-Bit Bustreiber/Bus Driver		20-DIP				DS 8282D
i 8283	Int	TTL-IC	Schottky, 8-Bit Bustreiber/Bus Driver		20-DIP				DS 8283D
i 8286	Int	TTL-IC	Schottky, 8-Bit Bustreiber/Bus Driver		20-DIP				DS 8286D
i 8287	Int	TTL-IC	Schottky, 8-Bit Bustreiber/Bus Driver		20-DIP				DS 8287D
i 23128	Int	ROM-IC	16384x8 Bit, 250ns		28-DIP				MN 23128
i 82720	Int	MOS-IC	Grafic Display Controller						U 82720D
IA		MOS-N-FET-e	=µPA602T (SMD-Marking)		46	SOT-163			›µPA602T
IBB 1488 B		OP-IC	Dual, Serie 158		8-DIP		4558/8-D	8-DIP	›MC 1458
IC		Si-N	=2SC3016 (SMD-Marking)		35	SOT-23			›2SC3016
ICL 108…	Isi	OP-IC	›µA 108…						›µA 108…
ICL 741…	Isi	OP-IC	›µA 741…						›µA 741…
ICL 7106	Tsc	A/D-IC	A/D-Converter, 3,5 digit						TSC 7106A
ICL 7136	Sie	A/D-IC	3,5-Digit A/D-Converter		40-DIP				C 7136D
ICL 7650 CPD	Isi	CMOS-OP-IC	Chopperstabilisiert, ±9V		14-DIP				U 7650 DD
ICL 7660 CAP	Isi	CMOS-IC	Spannungswandler/volt. conv., 0…+70°		8-DIP				U 7660 DC
ICL 7660 CSA	Isi	CMOS-IC	=ICL 7660CAP: -25…+85°		8-DIP				U 7660 DG
ICM 7555 CD	Phi	LIN-IC	=NE 555: CMOS-Version, SMD, 0…+70°		8-MDIP				-
ICM 7555 CFE,CN	Phi	CMOS-IC	=NE 555: CMOS-Version, 0…+70°		8-DIC/DIP				KS 555N
ICM 7555 ID	Phi	LIN-IC	=NE 555: CMOS-Version, SMD, -40…+85°		8-MDIP				-
ICM 7555 IFE,IN	Phi	LIN-IC	=NE 555: CMOS-Version, -40…+85°		8-DIP				-
ICM 7555 MFE,MN	Phi	LIN-IC	=NE 555: CMOS-Version, -55…+125°		8-DIC/DIP				-
ICM 7556		CMOS-IC	=KS 556N		14-DIP				KS 556N
ID		Si-N	=2SC3127 (SMD-Marking)		35	SOT-23			›2SC3127
IE		Si-N	=2SC3722K-E (SMD-Marking)		35	SOT-23			›2SC3722K
IFB		Si-P	=2SB973-B (SMD-Marking)		35	SOT-23			›2SB973
IFC		Si-P	=2SB973-C (SMD-Marking)		35	SOT-23			›2SB973
IGD		MOS-N-FET-d	=2SK1215-D (SMD-Marking)		35(2mm)	SOT-323			›2SK1215
IGD		MOS-N-FET-d	=2SK360-D (SMD-Marking)		35	SOT-23			›2SK360
IGE		MOS-N-FET-d	=2SK1215-E (SMD-Marking)		35(2mm)	SOT-323			›2SK1215
IGE		MOS-N-FET-d	=2SK360-E (SMD-Marking)		35	SOT-23			›2SK360
IGF		MOS-N-FET-d	=2SK1215-F (SMD-Marking)		35(2mm)	SOT-323			›2SK1215
IGF		MOS-N-FET-d	=2SK360-F (SMD-Marking)		35	SOT-23			›2SK360
IGT 4 D/E10…11	Gen	MOS-N-IGBT	Iso-Gate, bipolar Tr., 400…500/25V, 18/40A, 75W		17(GCEC)	TO-220			-
IGT 6 D/E10…11	Gen	MOS-N-IGBT	=IGT 4 D/E10…11:		23(EGC)	TO-3			GT 25J101
IGT 6 D/E20…21	Gen	MOS-N-IGBT	Iso-Gate, bipolar Tr., 400…500V, 20/32A, 125W		23(EGC)	TO-3			GT 25J101
IGT 8 D/E20…21	Gen	MOS-N-IGBT	=IGT 6 D/E20…21:		16(GCEC)	TO-247			GT 25J101
IHC		N-FET	=2SK431-C (SMD-Marking)		35	SOT-23			›2SK431
IHD		N-FET	=2SK431-D (SMD-Marking)		35	SOT-23			›2SK431
IHE		N-FET	=2SK431-E (SMD-Marking)		35	SOT-23			›2SK431
IHF		N-FET	=2SK431-F (SMD-Marking)		35	SOT-23			›2SK431